ETSI TS 138 101-2 V16.14.0 (2023-01)



5G; NR; User Equipment (UE) radio transmission and reception; Part 2: Range 2 Standalone (3GPP TS 38.101-2 version 16.14.0 Release 16)



Reference RTS/TSGR-0438101-2vge0

Keywords

5G

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cannot	indicates that something is impossible

The constructions "can" and "cannot" are not substitutes for "may" and "need not".

will	indicates that something is certain or expected to happen as a result of action taken by an agency the behaviour of which is outside the scope of the present document
will not	indicates that something is certain or expected not to happen as a result of action taken by an agency the behaviour of which is outside the scope of the present document
might	indicates a likelihood that something will happen as a result of action taken by some agency the behaviour of which is outside the scope of the present document

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might not indicates a likelihood that something will not happen as a result of action taken by some agency the behaviour of which is outside the scope of the present document

In addition:

- is (or any other verb in the indicative mood) indicates a statement of fact
- is not (or any other negative verb in the indicative mood) indicates a statement of fact

The constructions "is" and "is not" do not indicate requirements.

1 Scope

The present document establishes the minimum RF requirements for NR User Equipment (UE) operating on frequency Range 2.

2 References

The following documents contain provisions which, through reference in this text, constitute provisions of the present document.

- References are either specific (identified by date of publication, edition number, version number, etc.) or non-specific.
- For a specific reference, subsequent revisions do not apply.
- For a non-specific reference, the latest version applies. In the case of a reference to a 3GPP document (including a GSM document), a non-specific reference implicitly refers to the latest version of that document *in the same Release as the present document*.
- [1] 3GPP TR 21.905: "Vocabulary for 3GPP Specifications".
- [2] 3GPP TS 38.101-1: "NR; User Equipment (UE) radio transmission and reception; Part 1: Range 1 Standalone"
- [3] 3GPP TS 38.101-3: "NR; User Equipment (UE) radio transmission and reception; Part 3: Range 1 and Range 2 Interworking operation with other radios"
- [4] Void
- [5] 3GPP TS 38.521-2: "NR; User Equipment (UE) conformance specification; Radio transmission and reception; Part 2: Range 2 Standalone"
- [6] Recommendation ITU-R M.1545: "Measurement uncertainty as it applies to test limits for the terrestrial component of International Mobile Telecommunications-2000"
- [7] ITU-R Recommendation SM.329-10, "Unwanted emissions in the spurious domain"
- [8] 47 CFR Part 30, "UPPER MICROWAVE FLEXIBLE USE SERVICE, §30.202 Power limits", FCC.
- [9] 3GPP TS 38.211: "NR; Physical channels and modulation".
- [10] 3GPP TS 38.213: "NR; Physical layer procedures for control".
- [11] 3GPP TS 38.215: "NR; Physical layer measurements".
- [12] 3GPP TS 38.133: "NR; Requirements for support of radio resource management".
- [13] 3GPP TS 38.331: "NR; Radio Resource Control (RRC); Protocol specification".
- [14] 3GPP TS 38.306: "NR; User Equipment (UE) radio access capabilities".
- [15] IEEE Std 149: "IEEE Standard Test Procedures for Antennas", IEEE.

3 Definitions, symbols and abbreviations

3.1 Definitions

For the purposes of the present document, the terms and definitions given in 3GPP TR 21.905 [1] and the following apply. A term defined in the present document takes precedence over the definition of the same term, if any, in 3GPP TR 21.905 [1].

Aggregated Channel Bandwidth: The RF bandwidth in which a UE is configured to transmit and receive multiple contiguously aggregated carriers.

Bidirectional spectrum: UL/DL common spectrum in which the UE supports the configuration of uplink or downlink CCs.

Beam correspondence: the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping.

Carrier aggregation: Aggregation of two or more component carriers in order to support wider transmission bandwidths.

Carrier aggregation band: A set of one or more operating bands across which multiple carriers are aggregated with a specific set of technical requirements.

Carrier aggregation bandwidth class: A class defined by the aggregated transmission bandwidth configuration and maximum number of component carriers supported by a UE.

Carrier aggregation configuration: A combination of CA operating band(s) and CA bandwidth class(es) supported by a UE.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

Cumulative aggregated channel bandwidth: The cumulative aggregated channel bandwidth is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs inside the bidirectional spectrum of the UE.

EIRP(Link=Link angle, Meas=Link angle): measurement of the UE such that the link angle is aligned with the measurement angle. EIRP (indicator to be measured) can be replaced by EIS, Frequency, EVM, carrier Leakage, Inband eission and OBW.

EIRP(Link=TX beam peak direction, Meas=Link angle): measurement of the EIRP of the UE such that the measurement angle is aligned with the beam peak direction within an acceptable measurement error uncertainty. EIRP (indicator to be measured) can be replaced by Frequency, EVM, carrier Leakage, In-band eission and OBW

EIRP(Link=Spherical coverage grid, Meas=Link angle): measurement of the EIRP spherical coverage of the UE such that the EIRP link and measurement angles are aligned with the directions along the spherical coverage grid within an acceptable measurement error uncertainty. Alternatively, the spherical coverage grid can be replaced by the beam peak search grid as the results from the beam peak search can be re-used for spherical coverage.

EIS (effective isotropic sensitivity): sensitivity for an isotropic directivity device equivalent to the sensitivity of the discussed device exposed to an incoming wave from a defined AoA

EIS(Link=RX beam peak direction, Meas=Link angle): measurement of the EIS of the UE such that the measurement angle is aligned with the RX beam peak direction within an acceptable measurement error uncertainty.

NOTE 1: The sensitivity is the minimum received power level at which specific requirement is met.

NOTE 2: Isotropic directivity is equal in all directions (i.e. 0 dBi).

Fallback group: Group of carrier aggregation bandwidth classes for which it is mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration. It is not mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration that belong to a different fallback group.

IBM(Independent Beam Management): A UE that supports inter-band CA with IBM selects its DL Rx beam(s) for all CCs in each configured band based on DL reference signals measurements made in that band.

Inter-band carrier aggregation: Carrier aggregation of component carriers in different operating bands.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

Intra-band contiguous carrier aggregation: Contiguous carriers aggregated in the same operating band.

Intra-band non-contiguous carrier aggregation: Non-contiguous carriers aggregated in the same operating band.

Link angle: a DL-signal AoA from the view point of the UE, as described in Annex J. If the beam lock function is used to lock the UE beam(s), the link angle can become any arbitrary AoA once the beam lock has been activated.

Measurement angle: the angle of measurement of the desired metric from the view point of the UE, as described in Annex J

radiated interface boundary: operating band specific radiated requirements reference point where the radiated requirements apply

radiated requirements reference point: for the RF measurement setup, the radiated requirements reference point is located at the centre of the quiet zone. From the UE perspective the reference point is the input of the UE antenna array

RX beam peak direction: direction where the maximum total component of RSRP and thus best total component of EIS is found

Sub-block: This is one contiguous allocated block of spectrum for transmission and reception by the same UE. There may be multiple instances of sub-blocks within an RF bandwidth.

TX beam peak direction: direction where the maximum total component of EIRP is found

TRP(Link=TX beam peak direction, Meas=TRP grid): measurement of the TRP of the UE such that the measurement angles are aligned with the directions of the TRP grid points within an acceptable measurement uncertainty while the link angle is aligned with the TX beam peak direction

NOTE: For requirements based on EIRP/EIS, the radiated interface boundary is associated to the far-field region

UE transmission bandwidth configuration: Set of resource blocks located within the UE channel bandwidth which may be used for transmitting or receiving by the UE.

Vehicular UE: A UE embedded in a vehicle

3.2 Symbols

For the purposes of the present document, the following symbols apply:

$\Delta \mathrm{EIRP}_\mathrm{BC}$ $\Delta \mathrm{F}_\mathrm{Global}$ $\Delta \mathrm{F}_\mathrm{Raster}$	The beam correspondence tolerance, where $\Delta EIRP_{BC} = EIRP_2 - EIRP_1$ Granularity of the global frequency raster Band dependent channel raster granularity
Δf_{OOB}	Δ Frequency of Out Of Band emission
$\Delta_{\rm RB}$	The starting frequency offset between the allocated RB and the measured non-allocated RB
ΔR_{IB}	Allowed reference sensitivity relaxation due to support for inter-band CA operation
ΔR_{IBC}	Allowed reference sensitivity relaxation due to support for intra-band contiguous CA operation
ΔR_{IBNC}	Allowed reference sensitivity relaxation due to support for intra-band non-contiguous CA operation
$\Delta R_{IB,P,n}$	Allowed relaxation to each, minimum peak EIRP and reference sensitivity due to support for inter- band CA operation, per band in a combination of supported bands
$\Delta R_{IB,S,n}$	Allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to support for inter-band CA operation, per band in a combination of supported bands
$\Delta MB_{P,n}$	Allowed relaxation to minimum peak EIRP and reference sensitivity due to support for multi-band operation, per supported band in a combination.
$\Delta MB_{S,n}$	Allowed relaxation to EIRP spherical coverage and EIS spherical coverage due to support for multi-band operation, per supported band in a combination

$\sum MB_P$	Total allowed relaxation to minimum peak EIRP and reference sensitivity due to support for multi-
	band operation, for all supported bands in a combination
$\sum MB_s$	Total allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to
	support for multi-band operation, for all supported bands in a combination
BW _{Channel}	Channel bandwidth
BW _{Channel_CA}	Aggregated channel bandwidth, expressed in MHz
BW _{GB}	max(BWGB,Channel(k))
BW _{GB,Channel(k)}	Minimum guard band defined in sub-clause 5.3A.2 of carrier k
BWinterferer	Bandwidth of the interferer
Ceil(x)	Rounding upwards; ceil(x) is the smallest integer such that $ceil(x) \ge x$
$EIRP_1$	The measured total EIRP based on the beam the UE chooses autonomously (corresponding beam)
	to transmit in the direction of the incoming DL signal, which is based on beam correspondence
	without relying on UL beam sweeping
EIRP ₂	The measured total EIRP based on the beam yielding highest EIRP in a given direction, which is
	based on beam correspondence with relying on UL beam sweeping
EIRP _{max}	The applicable maximum EIRP as specified in sub-clause 6.2.1
Floor(x)	Rounding downwards; floor(x) is the greatest integer such that $floor(x) \le x$
F_center	The center frequency of an allocated block of PRBs
F _C	<i>RF reference frequency</i> for the carrier center on the channel raster, given in table 5.4.2.2-1
F _{C,block, high}	Fc of the highest transmitted/received carrier in a sub-block.
F _{C,block, low}	Fc of the lowest transmitted/received carrier in a sub-block.
F _{C, low}	The Fc of the lowest carrier, expressed in MHz.
F _{C, high}	The Fc of the highest carrier, expressed in MHz.
F _{DL_low}	The lowest frequency of the downlink <i>operating band</i>
F _{DL_high}	The highest frequency of the downlink <i>operating band</i> The lower sub-block edge, where $F_{edge,block,low} = F_{C,block,low} - F_{offset, low}$.
F _{edge,block,low}	The upper sub-block edge, where $F_{edge,block,ligh} = F_{C,block,ligh} + F_{offset, ligh}$.
F _{edge,block,high}	The lower edge of Aggregated Channel Bandwidth, expressed in MHz. $F_{edge, low} = F_{C, low} - F_{offset, low}$.
F _{edge, low}	The upper edge of Aggregated Channel Bandwidth, expressed in MHz. $F_{edge, low} = F_{C, low} + F_{offset, low}$. The upper edge of Aggregated Channel Bandwidth, expressed in MHz. $F_{edge, high} = F_{C, high} + F_{offset, low}$.
$F_{edge, high}$	
FInterferer	high. Frequency of the interferer
F _{Interferer} (offset)	Frequency of the interferer (between the center frequency of the interferer and the carrier
I Interferer (OIISet)	frequency of the carrier measured)
F _{Ioffset}	Frequency offset of the interferer (between the center frequency of the interferer and the closest
I Ionset	edge of the carrier measured)
Floor(x)	Rounding downwards; floor(x) is the greatest integer such that floor(x) \leq x
FOOB	The boundary between the NR out of band emission and spurious emission domains
F _{REF}	RF reference frequency
F _{REF-Offs}	Offset used for calculating F_{REF}
F _{UL_low}	The lowest frequency of the uplink <i>operating band</i>
F _{UL_high}	The highest frequency of the uplink <i>operating band</i>
F _{UL_Meas}	The sub-carrier frequency for which the equalizer coefficient is evaluated
GB _{Channel}	Minimum guard band defined in sub-clause 5.3.3
L _{CRB}	Transmission bandwidth which represents the length of a contiguous resource block allocation
	expressed in units of resources blocks
L _{CRB,Max}	Maximum number of RB for a given Channel bandwidth and sub-carrier spacing
Max()	The largest of given numbers
Min()	The smallest of given numbers
MPR _{f,c}	Maximum output power reduction for carrier f of serving cell c
MPR _{narrow}	Maximum output power reduction due to narrow PRB allocation
MPR _{WT}	Maximum power reduction due to modulation orders, transmit bandwidth configurations,
	waveform types
$n_{\rm PRB}$	Physical resource block number
NR _{ACLR}	NR ACLR
N _{RB}	Transmission bandwidth configuration, expressed in units of resource blocks
$N_{RB,low}$	Transmission bandwidth configurations according to Table 5.3.2-1 for the lowest assigned
	component carrier in clause 5.3A.1
$N_{RB,high}$	Transmission bandwidth configurations according to Table 5.3.2-1 for the highest assigned
	component carrier in clause 5.3A.1
N _{REF}	NR Absolute Radio Frequency Channel Number (NR-ARFCN)
N _{REF-Offs}	Offset used for calculating N _{REF}
P _{CMAX}	The configured maximum UE output power

The configured maximum UE output power for carrier f of serving cell c
The intermediate power point as defined in table 6.3.4.2-2
Modulated mean power of the interferer
The maximum UE output power as specified in sub-clause 6.2.1
The minimum UE output power as specified in sub-clause 6.3.1
The Power Management UE Maximum Power Reduction for carrier <i>f</i> of serving cell <i>c</i>
Nominal UE power class (i.e., no tolerance) as specified in sub-clause 6.2.1
The transmitted power per allocated RB, measured in dBm
The measured total radiated power for carrier f of serving cell c
The measured configured maximum UE output power
Power of a wanted DL signal
Indicates the lowest RB index of transmitted resource blocks
SCS for the lowest assigned component carrier in clause 5.3A.1
SCS for the highest assigned component carrier in clause 5.3A.1
SS block reference frequency position
The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB)
The maximum TRP for the UE power class as specified in sub-clause 6.2.1

3.3 Abbreviations

For the purposes of the present document, the abbreviations given in 3GPP TR 21.905 [1] and the following apply. An abbreviation defined in the present document takes precedence over the definition of the same abbreviation, if any, in 3GPP TR 21.905 [1].

ACLR	Adjacent Channel Leakage Ratio
ACS	Adjacent Channel Selectivity
A-MPR	Additional Maximum Power Reduction
AoA	Angle of Arrival
BCS	Bandwidth Combination Set
BPSK	Binary Phase-Shift Keying
BS	Base Station
BW	Bandwidth
BWP	Bandwidth Part
CA	Carrier aggregation
CABW	Cumulative Aggregated Channel Bandwidth
CA_nX-nY	Inter-band CA of component carrier(s) in one sub-block within Band X and component carrier(s)
	in one sub-block within Band Y where X and Y are the applicable NR operating band
CC	Component carrier
CDF	Cumulative Distribution Function
CP-OFDM	Cyclic Prefix-OFDM
CW	Continuous Wave
DFT-s-OFDM	Discrete Fourier Transform-spread-OFDM
DM-RS	Demodulation Reference Signal
DTX	Discontinuous Transmission
EIRP	Effective Isotropic Radiated Power
EIS	Effective Isotropic Sensitivity
EVM	Error Vector Magnitude
FR	Frequency Range
FWA	Fixed Wireless Access
GSCN	Global Synchronization Channel Number
IBB	In-band Blocking
IBM	Independent Beam Management
IDFT	Inverse Discrete Fourier Transformation
ITU-R	Radiocommunication Sector of the International Telecommunication Union
MBW	Measurement bandwidth defined for the protected band
MPR	Allowed maximum power reduction
NR	New Radio
NR-ARFCN	NR Absolute Radio Frequency Channel Number
OCNG	OFDMA Channel Noise Generator
OOB	Out-of-band
OTA	Over The Air

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P-MPR	Power Management Maximum Power Reduction
PRB	Physical Resource Block
QAM	Quadrature Amplitude Modulation
RF	Radio Frequency
REFSENS	Reference Sensitivity
RIB	Radiated Interface Boundary
RMS	Root Mean Square (value)
RSRP	Reference Signal Receiving Power
Rx	Receiver
SCS	Subcarrier spacing
SEM	Spectrum Emission Mask
SRS	Sounding Reference Symbol
SS	Synchronization Symbol
TPC	Transimission Power Control
TRP	Total Radiated Power
Tx	Transmitter
UE	User Equipment
UL MIMO	Uplink Multiple Antenna transmission
ULFPTx	Uplink Full Power Transmission

4 General

4.1 Relationship between minimum requirements and test requirements

The present document is a Single-RAT specification for NR UE, covering RF characteristics and minimum performance requirements. Conformance to the present specification is demonstrated by fulfilling the test requirements specified in the conformance specification 3GPP TS 38.521-2 [5].

The Minimum Requirements given in this specification make no allowance for measurement uncertainty. The test specification TS 38.521-2 [5] defines test tolerances. These test tolerances are individually calculated for each test. The test tolerances are used to relax the minimum requirements in this specification to create test requirements. For some requirements, including regulatory requirements, the test tolerance is set to zero.

The measurement results returned by the test system are compared - without any modification - against the test requirements as defined in 3GPP TS 38.521-2 [5].

4.2 Applicability of minimum requirements

- a) In this specification the Minimum Requirements are specified as general requirements and additional requirements. Where the Requirement is specified as a general requirement, the requirement is mandated to be met in all scenarios
- b) For specific scenarios for which an additional requirement is specified, in addition to meeting the general requirement, the UE is mandated to meet the additional requirements.
- c) The spurious emissions power requirements are for the long-term average of the power. For the purpose of reducing measurement uncertainty it is acceptable to average the measured power over a period of time sufficient to reduce the uncertainty due to the statistical nature of the signal
- d) All the requirements for intra-band contiguous and non-contiguous CA apply under the assumption of the same slot format indicated by *TDD-UL-DL-ConfigurationCommon and TDD-UL-DL-ConfigurationDedicated* in the PCell and SCells for NR SA.

For FR2 intra-band CA configurations with multiple FR2 sub-blocks, where at least one of the sub-blocks is a contiguous CA configuration:

- if the field *partialFR2-FallbackRX-Req* is not present, the UE shall meet all applicable UE RF requirements for the highest order CA configuration and all associated fallback CA configurations;
- if the field *partialFR2-FallbackRX-Req* is present, for each FR2 intra-band CA configuration with multiple subblocks that the UE indicates support for explicitly in UE capability signalling: the in-gap UE RF requirements in clauses 7.5A, 7.5D, 7.6A, 7.6D apply as the equivalent requirements for the associated fallback CA configurations with the same number of sub-blocks, where at least one of the sub-blocks consists of a contiguous CA configuration. The UE shall meet all applicable UE RF requirements for fallback CA configurations with a lesser number of sub-blocks;
- regardless of the field *partialFR2-FallbackRX-Req*, the UE shall meet all DL out-of-gap requirements for all lower order fallback CA configurations.

4.3 Specification suffix information

Unless stated otherwise the following suffixes are used for indicating at 2nd level clause, shown in Table 4.3-1.

Clause suffix	Variant	
None	Single Carrier	
A	Carrier Aggregation (CA)	
В	Dual-Connectivity (DC)	
С	Supplement Uplink (SUL)	
D	UL MIMO	
or spatial UL MIMC both kinds of UL M	cification represents either polarized UL MIMO D. RF requirements are same. If UE supports IIMO, then RF requirements only need to be er polarized or spatial UL MIMO.	

Table 4.3-1: Definition of suffixes

5 Operating bands and channel arrangement

5.1 General

The channel arrangements presented in this clause are based on the operating bands and channel bandwidths defined in the present release of specifications.

NOTE: Other operating bands and channel bandwidths may be considered in future releases.

Requirements throughout the RF specifications are in many cases defined separately for different frequency ranges (FR). The frequency ranges in which NR can operate according to this version of the specification are identified as described in Table 5.1-1.

Frequency range designation	Corresponding frequency range
FR1	410 MHz – 7125 MHz
FR2	24250 MHz – 52600 MHz

Table 5.1-1: Definition of frequency ranges

The present specification covers FR2 operating bands.

5.2 Operating bands

NR is designed to operate in the FR2 operating bands defined in Table 5.2-1.

Table 5.2-1: NR operating bands in FR2

Operating Band	Uplink (UL) operating band BS receive UE transmit	Downlink (DL) operating band BS transmit UE receive	Duplex Mode
	Ful_low – Ful_high	F _{DL_low} – F _{DL_high}	
n257	26500 MHz – 29500 MHz	26500 MHz – 29500 MHz	TDD
n258	24250 MHz – 27500 MHz	24250 MHz – 27500 MHz	TDD
n259	39500 MHz – 43500 MHz	39500 MHz – 43500 MHz	TDD
n260	37000 MHz – 40000 MHz	37000 MHz – 40000 MHz	TDD
n261	27500 MHz – 28350 MHz	27500 MHz – 28350 MHz	TDD

5.2A Operating bands for CA

5.2A.1 Intra-band CA

NR intra-band contiguous and non-contiguous carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.1-1, where all operating bands are within FR2.

Table 5.2A.1-1: Intra-band	contiguous and ne	on-contiguous C	A operating	bands in FR2
	J		J	

NR CA Band	NR Band (Table 5.2-1)
CA_n257	n257
CA_n258	n258
CA_n259	n259
CA_n260	n260
CA_n261	n261

5.2A.2 Inter-band CA

NR inter-band carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.2-1, where all operating bands are within FR2.

Beam management type is according to UE capability declaration *IE beamManagementType-r16*. The requirements in the following clauses are only applicable to inter-band CA with IBM type.

Table 5.2A.2-1: Inter-band CA operating bands in FR2

NR CA Band	NR Band (Table 5.2-1)		
CA_n260-n261	n260, n261		
NOTE 1: The minimum requirements apply only when there is non-simultaneous Rx/Tx operation between inter-band NR carriers in the current version of this specification.			

5.2D Operating bands for UL MIMO

NR UL MIMO is designed to operate in the operating bands defined in Table 5.2D-1.

UL MIMO operating band (Table 5.2-1)	
n257	
n258	
n259	
n260	
n261	

Table 5.2D-1: NR UL MIMO operating bands

5.3 UE Channel bandwidth

5.3.1 General

The UE channel bandwidth supports a single NR RF carrier in the uplink or downlink at the UE. From a BS perspective, different UE channel bandwidths may be supported within the same spectrum for transmitting to and receiving from UEs connected to the BS. Transmission of multiple carriers to the same UE (CA) or multiple carriers to different UEs within the BS channel bandwidth can be supported.

From a UE perspective, the UE is configured with one or more BWP / carriers, each with its own UE channel bandwidth. The UE does not need to be aware of the BS channel bandwidth or how the BS allocates bandwidth to different UEs.

The placement of the UE channel bandwidth for each UE carrier is flexible but can only be completely within the BS channel bandwidth.

The relationship between the channel bandwidth, the guardband and the transmission bandwidth configuration is shown in Figure 5.3.1-1.

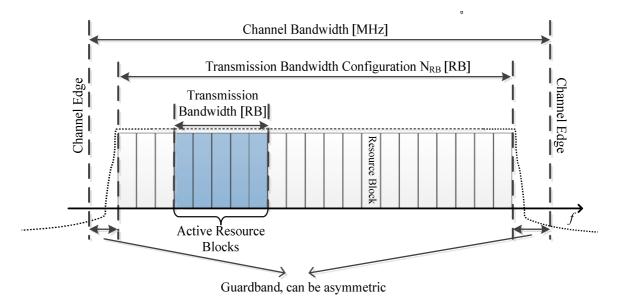


Figure 5.3.1-1: Definition of channel bandwidth and transmission bandwidth configuration for one NR channel

5.3.2 Maximum transmission bandwidth configuration

The maximum transmission bandwidth configuration N_{RB} for each UE channel bandwidth and subcarrier spacing is specified in Table 5.3.2-1

Table 5.3.2-1: Maximum transmission bandwidth configuration N_{RB}

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz
	N _{RB}	Nrb	Nrb	N _{RB}
60	66	132	264	N.A
120	32	66	132	264

5.3.3 Minimum guardband and transmission bandwidth configuration

The minimum guardband for each UE channel bandwidth and SCS is specified in Table 5.3.3-1

Table 5.3.3-1: Minimum guardband for each UE channel bandwidth and SCS (kHz)

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz
60	1210	2450	4930	N. A
120	1900	2420	4900	9860

NOTE: The minimum guardbands have been calculated using the following equation: $(BW_{Channel} \times 1000 \text{ (kHz)} - N_{RB} \times SCS \times 12) / 2 - SCS/2$, where N_{RB} are from Table 5.3.2-1.

The minimum guardband of receiving BS SCS 240 kHz SS/PBCH block for each UE channel bandwidth is specified in table 5.3.3-2 for FR2.

Table: 5.3.3-2: Minimum guardband (kHz) of SCS 240 kHz SS/PBCH block

SCS (kHz)	100 MHz	200 MHz	400 MHz
240	3800	7720	15560

NOTE: The minimum guardband in Table 5.3.3-2 is applicable only when the SCS 240 kHz SS/PBCH block is received adjacent to the edge of the UE channel bandwidth within which the SS/PBCH block is located.

Figure 5.3.3-1: Void

The number of RBs configured in any channel bandwidth shall ensure that the minimum guardband specified in this clause is met.

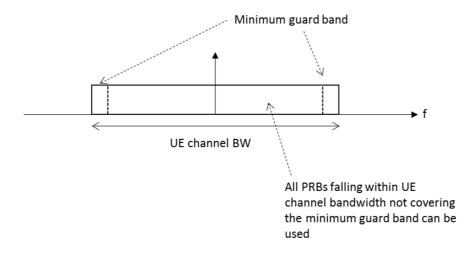
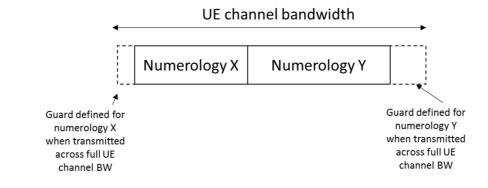
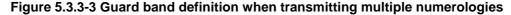


Figure 5.3.3-2 UE PRB utilization

In the case that multiple numerologies are multiplexed in the same symbol due to BS transmission of SSB, the minimum guardband on each side of the carrier is the guardband applied at the configured channel bandwidth for the numerology that is transmitted immediately adjacent to the guard band.

If multiple numerologies are multiplexed in the same symbol and the UE channel bandwidth is > 200 MHz, the minimum guardband applied adjacent to 60 kHz SCS shall be the same as the minimum guardband defined for 120 kHz SCS for the same UE channel bandwidth.





Note: Figure 5.3.3-3 is not intended to imply the size of any guard between the two numerologies. Internumerology guard band within the carrier is implementation dependent.

5.3.4 RB alignment

For each numerology, its common resource blocks are specified in Clause 4.4.4.3 in [9], and the starting point of its transmission bandwidth configuration on the common resource block grid for a given channel bandwidth is indicated by an offset to "Reference point A" in the unit of the numerology. The *UE transmission bandwidth configuration* is indicated by the higher layer parameter *carrierBandwidth* [13] and will fulfil the minimum UE guardband requirement specified in Clause 5.3.3.

5.3.5 Channel bandwidth per operating band

The requirements in this specification apply to the combination of channel bandwidths, SCS and operating bands shown in Table 5.3.5-1. The transmission bandwidth configuration in Table 5.3.2-1 shall be supported for each of the specified channel bandwidths. The channel bandwidths are specified for both the Tx and Rx path.

Operating band / SCS / UE channel bandwidth					
Operating band	SCS kHz	50 MHz	100 MHz	200 MHz	400 ¹ MHz
n257	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n258	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n259	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n260 <u>60 Yes Yes</u> Yes					
	120	Yes	Yes	Yes	Yes
n261	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
NOTE 1: This UE channel bandwidth is optional in this release of the specification.					

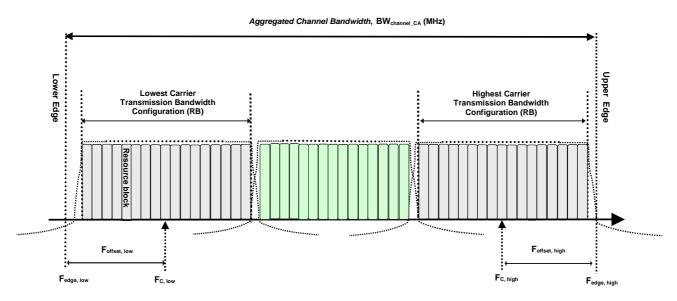
Table 5.3.5-1: Channel bandwidths for each NR band

5.3A UE channel bandwidth for CA

5.3A.1 General

5.3A.2 Minimum guardband and transmission bandwidth configuration for CA

For intra-band contiguous carrier aggregation, *Aggregated Channel Bandwidth* and *Guard Bands* are defined as follows, see Figure 5.3A.2-1.





The aggregated channel bandwidth, BWChannel_CA, is defined as

 $BW_{Channel_CA} = F_{edge,high} - F_{edge,low}$ (MHz).

The lower bandwidth edge $F_{edge, low}$ and the upper bandwidth edge $F_{edge, high}$ of the aggregated channel bandwidth are used as frequency reference points for transmitter and receiver requirements and are defined by

$$F_{edge,low} = F_{C,low} - F_{offset,low}$$

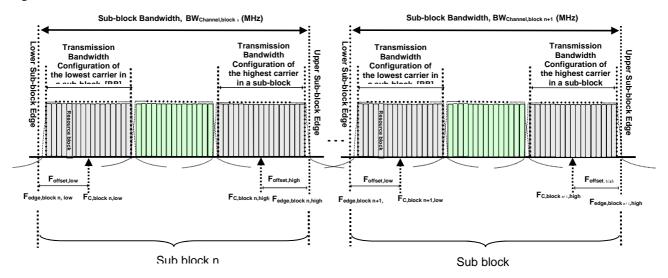
$$F_{edge,high} = F_{C,high} + F_{offset,high}$$

The lower and upper frequency offsets depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carrier and are defined as

$$\begin{split} F_{offset,low} &= (N_{RB,low}*12+1)*SCS_{low}/2 + BW_{GB} (MHz) \\ F_{offset,high} &= (N_{RB,high}*12-1)*SCS_{high}/2 + BW_{GB} (MHz) \\ BW_{GB} &= max(BW_{GB,Channel(k)}) \end{split}$$

N_{RB,low} and N_{RB,high} are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier, SCS_{low} and SCS_{high} are the sub-carrier spacing for the lowest and highest assigned $component\ carrier\ respectively.\ SCS_{low},\ SCS_{high},\ N_{RB,low},\ N_{RB,high},\ and\ BW_{GB,Channel(k)}\ use\ the\ largest\ \mu\ value\ among\ the$ subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1 and BW_{GB,Channel(k)} is the minimum guard band for carrier k according to Table 5.3.3-1 for the said μ value.

For intra-band non-contiguous carrier aggregation Sub-block Bandwidth and Sub-block edges are defined as follows, see Figure 5.3A.2-2.





The lower sub-block edge of the Sub-block Bandwidth (BW_{Channel,block}) is defined as

 $F_{edge,block, low} = F_{C,block,low} - F_{offset, low}$

The upper sub-block edge of the Sub-block Bandwidth is defined as

 $F_{edge,block,high} = F_{C,block,high} + F_{offset,high}$

The Sub-block Bandwidth, BW_{Channel,block}, is defined as follows:

 $BW_{Channel,block} = F_{edge,block,high} - F_{edge,block,low} (MHz)$

The lower and upper frequency offsets Foffset, block, low and Foffset, block, high depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carriers within a sub-block and are defined as

> $F_{\text{offset,block,low}} = (N_{\text{RB,low}}*12 + 1)*SCS_{\text{low}}/2 + BW_{\text{GB}}(\text{MHz})$ $F_{offset,block,high} = (N_{RB,high}*12 - 1)*SCS_{high}/2 + BW_{GB} (MHz)$ $BW_{GB} = max(BW_{GB,Channel(k)})$

where $N_{RB,low}$ and $N_{RB,high}$ are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier within a sub-block, respectively. SCS_{low} and SCS_{high} are the sub-carrier spacing for the lowest and highest assigned component carrier within a sub-block, respectively. SCS_{low}, SCS_{high}, N_{RB,low}, N_{RB,high}, and BW_{GB,Channel(k)} use the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1 and BW_{GB,Channel(k)} is the minimum guard band for carrier k according to Table 5.3.3-1 for the said μ value.

The sub-block gap size between two consecutive sub-blocks W_{gap} is defined as

 $W_{gap} = F_{edge,block n+1,low} - F_{edge,block n,high} (MHz)$

5.3A.3 RB alignment with different numerologies for CA

5.3A.4 UE channel bandwidth per operating band for CA

For intra-band contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting a carrier aggregation bandwidth class with associated bandwidth combination sets specified in clause 5.5A.1. For each carrier aggregation configuration, requirements are specified for all aggregated channel bandwidths contained in a bandwidth combination set, UE can indicate support of several bandwidth combination sets per carrier aggregation configuration. The requirements are applicable only when Uplink CCs are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier.

For intra-band non-contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting two or more sub-blocks, each supporting a carrier aggregation bandwidth class. The requirements are applicable only when Uplink CCs in each UL sub-block are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier of a DL sub-block.

Frequency separation class (Fs) specified in Table 5.3A.4-2 indicates the maximum frequency span between lower edge of lowest component carrier and upper edge of highest component carrier that UE can support per band in downlink or uplink (DL Fs or UL Fs) respectively in non-contiguous intra-band operation within the bidirectional spectrum.

The DL-only frequency spectrum is the width of UE frequency spectrum available to network to configure DL CCs only, and it extends on one-side of the bidirectional spectrum in contiguous manner with no frequency gap between the two. Frequency separation class for DL-only spectrum (Fsd) specified in Table 5.3A.4-3 and is declared per band. The frequency separation class for DL-only spectrum (Fsd) can be equal but not larger than the frequency separation (DL Fs). The combined downlink spectrum (DL Fs + Fsd) cannot exceed 2400 MHz. A UE may configure DL-only spectrum only if the combined downlink spectrum (DL Fs + Fsd) exceeds 1400 MHz. When a UE configures DL-only spectrum, it shall not expect a CC to be configured across the boundary between bidirectional spectrum and DL-only spectrum UE can support respectively.

For inter-band carrier aggregation, a carrier aggregation configuration is a combination of operating bands, each supporting a carrier aggregation bandwidth class.

NR CA bandwidth class	Aggregated channel bandwidth	Number of contiguous CC	Fallback group
А	BW _{Channel} ≤ 400 MHz	1	1,2,3,4
В	400 MHz < BW _{Channel_CA} ≤ 800 MHz	2	1
С	800 MHz < BW _{Channel_CA} ≤ 1200 MHz	3	
D	200 MHz < BW _{Channel_CA} ≤ 400 MHz	2	2
E	400 MHz < BW _{Channel_CA} ≤ 600 MHz	3	
F	600 MHz < BW _{Channel_CA} ≤ 800 MHz	4	
G	100 MHz < BW _{Channel_CA} ≤ 200 MHz	2	3
Н	200 MHz < BW _{Channel_CA} ≤ 300 MHz	3	
	300 MHz < BW _{Channel_CA} ≤ 400 MHz	4	
J	400 MHz < BW _{Channel_CA} ≤ 500 MHz	5	
К	500 MHz < BW _{Channel_CA} ≤ 600 MHz	6	
L	600 MHz < BW _{Channel_CA} ≤ 700 MHz	7	
М	700 MHz < BW _{Channel_CA} ≤ 800 MHz	8	
0	100 MHz ≤ BW _{Channel_CA} ≤ 200 MHz	2	4
Р	150 MHz ≤ BW _{Channel_CA} ≤ 300 MHz	3	
Q	200 MHz ≤ BW _{Channel_CA} ≤ 400 MHz	4	
NOTE 1: Maximum su	pported component carrier bandwidths for fall	lback groups 1, 2, 3 and 4 a	re 400 MHz, 200
	Hz and 100 MHz respectively except for CA b		·
NOTE 2: It is mandate	ory for a UE to be able to fallback to lower ord	er CA bandwidth class confi	guration within a
fallback grou	p. It is not mandatory for a UE to be able to fa	allback to lower order CA ba	ndwidth class
configuration	that belong to a different fallback group.		

Table 5.3A.4-1: CA bandwidth classes

Table 5.3A.4-2: Frequency separation classes for non-contiguous intra-band operation

Frequency separation class	Max. allowed frequency separation (Fs)	
	800 MHz	
II	1200 MHz	
III	1400 MHz	
IV	1000 MHz	
V	1600 MHz	
VI	1800 MHz	
VII	2000 MHz	
VIII	2200 MHz	
IX	2400 MHz	
Х	400 MHz	
XI 600 MHz		
NOTE 1: Fs values larger than 1400 MHz apply only to downlink frequency separation.		

Table 5.3A.4-3: Frequency separation classes for DL-only spectrum

Frequency separation class	Max. allowed frequency separation (Fsd)
Ι	200 MHz
II	400 MHz
III	600 MHz
IV	800 MHz
V	1000 MHz
VI	1200 MHz

5.3D Channel bandwidth for UL MIMO

The requirements specified in clause 5.3 are applicable to UE supporting UL MIMO.

5.4 Channel arrangement

5.4.1 Channel spacing

5.4.1.1 Channel spacing for adjacent NR carriers

The spacing between carriers will depend on the deployment scenario, the size of the frequency block available and the channel bandwidths. The nominal channel spacing between two adjacent NR carriers is defined as following:

For NR operating bands with 60 kHz channel raster,

- Nominal Channel spacing = $(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-20 \text{ kHz}, 0 \text{ kHz}, 20 \text{ kHz}\}$ for ΔF_{Raster} equals to 60 kHz
- Nominal Channel spacing = $(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-40 \text{ kHz}, 0 \text{ kHz}, 40 \text{ kHz}\}$ for ΔF_{Raster} equals to 120 kHz

where $BW_{Channel(1)}$ and $BW_{Channel(2)}$ are the channel bandwidths of the two respective NR carriers. The channel spacing can be adjusted depending on the channel raster to optimize performance in a particular deployment scenario.

5.4.2 Channel raster

5.4.2.1 NR-ARFCN and channel raster

The global frequency raster defines a set of RF reference frequencies F_{REF} . The RF reference frequency is used in signalling to identify the position of RF channels, SS blocks and other elements.

The global frequency raster is defined for all frequencies from 0 to 100 GHz. The granularity of the global frequency raster is ΔF_{Global} .

RF reference frequency is designated by an NR Absolute Radio Frequency Channel Number (NR-ARFCN) in the range [2016667...3279165] on the global frequency raster. The relation between the NR-ARFCN and the RF reference frequency F_{REF} in MHz is given by the following equation, where $F_{REF-Offs}$ and $N_{Ref-Offs}$ are given in table 5.4.2.1-1 and N_{REF} is the NR-ARFCN

 $F_{REF} = F_{REF-Offs} + \Delta F_{Global} (N_{REF} - N_{REF-Offs})$

Table 5.4.2.1-1: NR-ARFCN parameters for the global frequency raster

Frequency range (MHz)	ΔF _{Global} (kHz)	FREF-Offs [MHz]	NREF-Offs	Range of NREF
24250 - 100000	60	24250.08	2016667	2016667 - 3279165

The *channel raster* defines a subset of *RF reference frequencies* that can be used to identify the RF channel position in the uplink and downlink. The *RF reference frequency* for an RF channel maps to a resource element on the carrier. For each operating band, a subset of frequencies from the global frequency raster are applicable for that band and forms a channel raster with a granularity ΔF_{Raster} , which may be equal to or larger than ΔF_{Global} .

The mapping between the channel raster and corresponding resource element is given in Clause 5.4.2.2. The applicable entries for each operating band are defined in clause 5.4.2.3

5.4.2.2 Channel raster to resource element mapping

The mapping between the RF reference frequency on channel raster and the corresponding resource element is given in Table 5.4.2.2-1 and can be used to identify the RF channel position. The mapping depends on the total number of RBs that are allocated in the channel and applies to both UL and DL. The mapping must apply to at least one numerology supported by the UE.

	$N_{RB} \mod 2 = 0$	$N_{RB} \mod 2 = 1$
Resource element index k	0	6
Physical resource block number <i>n_{PRB}</i>	$n_{\rm PRB} = \left\lfloor \frac{N_{\rm RB}}{2} \right\rfloor$	$n_{\rm PRB} = \left\lfloor \frac{N_{\rm RB}}{2} \right\rfloor$

Table 5.4.2.2-1: Channel raster to resource element mapping

k, n_{RB} , N_{RB} are as defined in TS 38.211 [9].

5.4.2.3 Channel raster entries for each operating band

The RF channel positions on the channel raster in each NR operating band are given through the applicable NR-ARFCN in Table 5.4.2.3-1, using the channel raster to resource element mapping in clause 5.4.2.2.

- For NR operating bands with 60 kHz channel raster above 24 GHz, $\Delta F_{Raster} = I \times \Delta F_{Global}$, where $I \in \{1,2\}$. Every I^{th} NR-ARFCN within the operating band are applicable for the channel raster within the operating band and the step size for the channel raster in table 5.4.2.3-1 is given as $\langle I \rangle$.
- In frequency bands with two ΔF_{Raster} , the higher ΔF_{Raster} applies to channels using only the SCS that equals the higher ΔF_{Raster} and the SSB SCS that is equal to or larger than the higher ΔF_{Raster} .

Operating Band	ΔF _{Raster} (kHz)	Uplink and Downlink Range of N _{REF}
	()	(First – <step size=""> – Last)</step>
n257	60	2054166 - <1> - 2104165
	120	2054167 - <2> - 2104165
n258	60	2016667 - <1> - 2070832
	120	2016667 - <2> - 2070831
n259	60	2270833 - <1> - 2337499
	120	2270833- <2> - 2337499
n260	60	2229166 - <1> - 2279165
	120	2229167 - <2> - 2279165
n261	60	2070833 - <1> - 2084999
	120	2070833 - <2> - 2084999

Table 5.4.2.3-1: Applicable NR-ARFCN per operating band

5.4.3 Synchronization raster

5.4.3.1 Synchronization raster and numbering

The synchronization raster indicates the frequency positions of the synchronization block that can be used by the UE for system acquisition when explicit signalling of the synchronization block position is not present.

A global synchronization raster is defined for all frequencies. The frequency position of the SS block is defined as SS_{REF} with corresponding number GSCN. The parameters defining the SS_{REF} and GSCN for all the frequency ranges are in Table 5.4.3.1-1.

The resource element corresponding to the SS block reference frequency SS_{REF} is given in clause 5.4.3.2. The synchronization raster and the subcarrier spacing of the synchronization block is defined separately for each band.

Frequency range	SS block frequency position SSREF	GSCN	Range of GSCN
24250 – 100000 MHz	24250.08 MHz + N * 17.28 MHz,	22256 + N	22256 - 26639
	N = 0:4383		

Table 5.4.3.1-1: GSCN parameters for the global frequency raster

5.4.3.2 Synchronization raster to synchronization block resource element mapping

The mapping between the synchronization raster and the corresponding resource element of the SS block is given in Table 5.4.3.2-1.

Table 5.4.3.2-1: Synchronization raster to SS block resource element mapping

Resource element index k	120

k is the subcarrier number of SS/PBCH block defined in TS 38.211 clause 7.4.3.1 [9].

5.4.3.3 Synchronization raster entries for each operating band

The synchronization raster for each band is give in Table 5.4.3.3-1. The distance between applicable GSCN entries is given by the <Step size> indicated in Table 5.4.3.3-1.

Table 5.4.3.3-1: Applicable SS raster entries per operating band									
ng Band	SS Block SCS	SS Block pattern ¹	Range of						

NR Operating Band	SS Block SCS	SS Block pattern ¹	Range of GSCN			
			(First – <step size=""> – Last)</step>			
n257	120 kHz	Case D	22388 - <1> - 22558			
	240 kHz	Case E	22390 - <2> - 22556			
n258	120 kHz	Case D	22257 - <1> - 22443			
	240 kHz	Case E	22258 - <2> - 22442			
n259	120 kHz	Case D	23140 - <1> - 23369			
	240 kHz	Case E	23142 - <2> - 23368			
n260	120 kHz	Case D	22995 - <1> - 23166			
	240 kHz	Case E	22996 - <2> - 23164			
n261	120 kHz	Case D	22446 - <1> - 22492			
	240 kHz	Case E	22446 - <2> - 22490			
NOTE 1: SS Block pattern	is defined in clause 4.1 in T	S 38,213 [10].				

SS Block pattern is defined in clause 4.1 in TS 38.213 [10]

Channel arrangement for CA 5.4A

5.4A.1 Channel spacing for CA

For intra-band contiguous carrier aggregation with two or more component carriers, the nominal channel spacing between two adjacent NR component carriers is defined as the following unless stated otherwise:

For NR operating bands with 60kHz channel raster:

Nominal channel spacing =
$$\frac{BW_{Channel\,(1)} + BW_{Channel\,(2)} - 2\left|GB_{Channel\,(1)} - GB_{Channel\,(2)}\right|}{0.06 * 2^{n+1}} = 0.06 * 2^{n} \text{ [MHz]}$$

with

$n = \mu_0 - 2$

where BW_{Channel(1)} and BW_{Channel(2)} are the channel bandwidths of the two respective NR component carriers according to Table 5.3.2-1 with values in MHz, μ_0 is the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1, and GB_{Channel(i)} is the minimum guard band for channel bandwidth *i* according to Table 5.3.3-1 for the said μ value, with μ as defined in TS 38.211 [9].

The channel spacing for intra-band contiguous carrier aggregation can be adjusted to any multiple of least common multiple of channel raster and sub-carrier spacing less than the nominal channel spacing to optimize performance in a particular deployment scenario.

For intra-band non-contiguous carrier aggregation, the channel spacing between two NR component carriers in different sub-blocks shall be larger than the nominal channel spacing defined in this clause.

5.5 Configurations

- 5.5A Configurations for CA
- 5.5A.1 Configurations for intra-band contiguous CA

Table 5.5A.1-1: NR CA configurations, bandwidth combination sets, and fallback group defined for intra-band contiguous CA

NR CA configuration / Bandwidth combination set / Fallback group												
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n257B	CA_n257B	50, 100, 200, 400	400							800	0	1
CA_n257C	CA_n257B	50, 100, 200, 400	400	400						1200	0	
CA_n257D	CA_n257D	50, 100, 200	200							400	0	2
CA_n257E	CA_n257D CA_n257E	50, 100, 200	200	200						600	0	
CA_n257F	CA_n257D CA_n257E CA_n257F	50, 100, 200	200	200	200					800	0	
CA_n257G	CA_n257G	50, 100	100							200	0	3
CA_n257H	CA_n257G CA_n257H	50, 100	100	100						300	0	
CA_n257I	CA_n257G CA_n257H CA_n257I	50, 100	100	100	100					400	0	
CA_n257J	CA_n257G CA_n257H CA_n257I CA_n257J	50, 100	100	100	100	100				500	0	
CA_n257K	CA_n257G CA_n257H CA_n257I CA_n257J CA_n257J CA_n257K	50, 100	100	100	100	100	100			600	0	
CA_n257L	CA_n257G CA_n257H CA_n257I CA_n257J CA_n257J CA_n257K CA_n257L	50, 100	100	100	100	100	100	100		700	0	
CA_n257M	CA_n257G CA_n257H CA_n257H CA_n257I CA_n257J CA_n257K CA_n257L CA_n257M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n258B	CA_n258B	50, 100, 200, 400	400							800	0	1

NR CA configuration / Bandwidth combination set / Fallback group												
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n258C	CA_n258B CA_n258C	50, 100, 200, 400	400	400						1200	0	
CA_n258D	CA_n258D	50, 100, 200	200							400	0	2
CA_n258E	CA_n258D CA_n258E	50, 100, 200	200	200						600	0	
CA_n258F	CA_n258D CA_n258E CA_n258F	50, 100, 200	200	200	200					800	0	1
CA_n258G	CA_n258G	50, 100	100							200	0	3
CA_n258H	CA_n258G CA_n258H	50, 100	100	100						300	0	
CA_n258I	CA_n258G CA_n258H CA_n258I	50, 100	100	100	100					400	0	
CA_n258J	CA_n258G CA_n258H CA_n258I CA_n258J	50, 100	100	100	100	100				500	0	0
CA_n258K	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258J CA_n258K	50, 100	100	100	100	100	100			600	0	
CA_n258L	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258J CA_n258K CA_n258L	50, 100	100	100	100	100	100	100		700	0	
CA_n258M	CA_n258G CA_n258H CA_n258H CA_n258J CA_n258J CA_n258K CA_n258L CA_n258M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n259B	CA_n259B	50, 100, 200, 400	400							800	0	1
CA_n259C	CA_n259B	50, 100, 200, 400	400	400						1200	0	
CA_n259G	CA_n259G	50, 100	100							200	0	3

			NR CA con		Bandwidth	combinatio		ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n259H	CA_n259G CA_n259H	50, 100	100	100						300	0	
CA_n259I	CA_n259G CA_n259H CA_n259I	50, 100	100	100	100					400	0	
CA_n259J	CA_n259G CA_n259H CA_n259I CA_n259J	50, 100	100	100	100	100				500	0	
CA_n259K	CA_n259G CA_n259H CA_n259H CA_n259J CA_n259J CA_n259K	50, 100	100	100	100	100	100			600	0	
CA_n259L	CA_n259G CA_n259H CA_n259I CA_n259J CA_n259K CA_n259K CA_n259L	50, 100	100	100	100	100	100	100		700	0	
CA_n259M	CA_n259G CA_n259H CA_n259H CA_n259J CA_n259J CA_n259K CA_n259L CA_n259M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n260B	 CA_n260B	50, 100, 200, 400	400							800	0	1
CA_n260C	CA_n260B	50, 100, 200, 400	400	400						1200	0	
CA_n260D	CA_n260D	50, 100, 200	200							400	0	2
CA_n260E	CA_n260D CA_n260E	50, 100, 200	200	200						600	0	
CA_n260F	CA_n260D CA_n260E CA_n260F	50, 100, 200	200	200	200					800	0	
CA_n260G CA_n260H	CA_n260G CA_n260G CA_n260H	50, 100 50, 100	100 100	100						200 300	0	3

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group							
CA_n260I	CA_n260G CA_n260H CA_n260I	50, 100	100	100	100					400	0	
CA_n260J	CA_n260G CA_n260H CA_n260I CA_n260J	50, 100	100	100	100	100				500	0	
CA_n260K	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260J CA_n260K	50, 100	100	100	100	100	100			600	0	
CA_n260L	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K CA_n260K CA_n260L	50, 100	100	100	100	100	100	100		700	0	
CA_n260M	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K CA_n260L CA_n260M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n260O	CA_n260O	50, 100	50, 100							200	0	4
CA_n260P	CA_n260O CA_n260P	50, 100	50, 100	50, 100						300	0	
CA_n260Q	CA_n260O CA_n260P CA_n260Q	50, 100	50, 100	50, 100	50, 100					400	0	
CA_n261B	CA_n261B	50, 100, 200, 400	400							800	0	1
CA_n261C	CA_n261B	50	400	400						850	0	
CA_n261D	CA_n261D	50, 100, 200	200							400	0	2
CA_n261E	CA_n261D CA_n261E	50, 100, 200	200	200						600	0	
CA_n261F	CA_n261D CA_n261E CA_n261F	50, 100, 200	200	200	200					800	0	
CA_n261G	CA_n261G	50, 100	100							200	0	3

NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	combination BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group
CA_n261H	CA_n261G CA_n261H	50, 100	100	100						300	0	
CA_n261I	CA_n261G CA_n261H CA_n261I	50, 100	100	100	100					400	0	
CA_n261J	CA_n261G CA_n261H CA_n261I CA_n261I CA_n261J	50, 100	100	100	100	100				500	0	
CA_n261K	CA_n261G CA_n261H CA_n261I CA_n261I CA_n261J CA_n261K	50, 100	100	100	100	100	100			600	0	
CA_n261L	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261K CA_n261L	50, 100	100	100	100	100	100	100		700	0	
CA_n261M	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261J CA_n261K CA_n261L CA_n261M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n261O	CA_n261O	50, 100	50, 100							200	0	4
CA_n261P	CA_n261O CA_n261P	50, 100	50, 100	50, 100						300	0	
CA_n261Q	CA_n261O CA_n261P CA_n261Q	50, 100	50, 100	50, 100	50, 100					400	0	

5.5A.2 Configurations for intra-band non-contiguous CA

Configurations listed in this clause apply to downlink carrier aggregation only.

NOTE: Sub-blocks belonging to a CA configuration can be in any order. In other words certain CA configuration acronym includes all sub-block arrangements which have exactly the same sub-block set. As an example, CA_n260(2G-3O) denotes CA_n260(2O-2G-O), CA_n260(G-3O-G) etc. but these are not listed in tables separately.

Table 5.5A.2-1: NR CA configurations with single CA bandwidth class defined for intra-band non-contiguous CA

				NR	CA confi	guration /	Bandwidt	h combi	nation se	et							
NR	Uplink CA	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub	Sub	Sub	Sub	Σ(BW _{Chann}	BCS
configuration	configurati	block	block	block	block	block	block	block	block	block	block	-	-	-	-	el,block)	
_	ons											blo	blo	blo	blo	(MHz)	
												ck	ck	ck	ck	· · ·	

CA_n257(2A)	-	n257A	n257A										800	0
CA_n258(2A)	-	n258A	n258A										800	0
CA_n258(3A)	-	n258A	n258A	n258A									1200	0
CA_n258(4A)	-	n258A	n258A	n258A	n258A								1600	0
CA_n258(5A)	-	n258A	n258A	n258A	n258A	n258A							2000	0
CA_n260(2A)	CA_n260(2 A)		n260A										800	0
CA_n260(3A)	CA_n260(3 A)	n260A	n260A	n260A									1200	0
CA_n260(4A)	-	n260A	n260A	n260A	n260A								1600	0
CA_n260(5A)	-	n260A	n260A	n260A	n260A	n260A							2000	0
CA_n260(6A)	-	n260A	n260A	n260A	n260A	n260A	n260A						2400	0
CA_n260(7A)	-	n260A	n260A	n260A	n260A	n260A	n260A	n260A					2800	0
CA_n260(8A)	-	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A				2900	0
CA_n260(9A)	-	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A			2950	0
CA_n260(10A)	-	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A		n260A		2950	0
CA_n260(2D)	-	CA_n26 0D	CA_n26 0D										800	0
CA_n260(2G)	CA_n260G	CA_n26 0G	CA_n26 0G										400	0
CA_n260(3G)	-	CA_n26 0G	CA_n26 0G	CA_n26 0G									600	0
CA_n260(4G)	-	CA_n26 0G	CA_n26 0G	CA_n26 0G	CA_n26 0G								800	0
CA_n260(2H)	CA_n260G CA_n260H	CA_n26 0H	CA_n26 0H										600	0
CA_n260(2O)	-	CA_n26 00	CA_n26 00										400	0
CA_n260(3O)	-	CA_n26 00	CA_n26 00	CA_n26 0O									600	0
CA_n260(4O)	-	CA_n26 00	CA_n26 00	CA_n26 00	CA_n26 0O								800	0
CA_n260(2P)	-	CA_n26 0P	CA_n26 0P										600	0
CA_n260(3P)	-	CA_n26 0P	CA_n26 0P	CA_n26 0P									900	0
CA_n260(4P)	-	CA_n26 0P	CA_n26 0P	CA_n26 0P	CA_n26 0P								1200	0
CA_n260(2Q)	-	CA_n26 0Q	CA_n26 0Q										800	0
CA_n261(2A)	-	n261A	n261A										800	0
CA_n261(3A)	-	n261A	n261A	n261A									800	0
CA_n261(4A)	-	n261A	n261A	n261A	n261A								800	0
CA_n261(2D)	-	CA_n26 1D	CA_n26 1D										800	0

CA_n261(2G)	CA_n261G	CA_n26 1G	CA_n26 1G											400	0
CA_n261(3G)	-	CA_n26 1G	CA_n26 1G	CA_n26 1G										600	0
CA_n261(4G)	-	CA_n26 1G	CA_n26 1G	CA_n26 1G	CA_n26 1G									800	0
CA_n261(2H)	CA_n261G CA_n261H		CA_n26 1H											600	0
CA_n261(2I)	CA_n261G CA_n261H CA_n261I		CA_n26 1I											800	0
CA_n261(2O)	-	CA_n26 10	CA_n26 10											400	0
CA_n261(3O)	-	CA_n26 10	CA_n26 10	CA_n26 10										600	0
CA_n261(4O)	-	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10									800	0
CA_n261(5O)	-	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10								800	0
CA_n261(6O)	-	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10		CA_n26 10							800	0
CA_n261(7O)	-	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n2 610						800	0
CA_n261(2P)	-	CA_n26 1P	CA_n26											600	0
CA_n261(2Q)	-	CA_n26 1Q	CA_n26 1Q											800	0
NOTE 6: Unles		tated, BCS	0 is referre	d in each c	constituent	CA configu		ub-block	bandwidth	is and sh	all be les	s than th	e bandwidt	th of the operati	ng

				NR C	A configur	ation / Band	width con	nbination se	et						
CA configuration	Uplink CA configurations	Sub-block	Sub- block	Σ(BW _{Chann} el,block) (MHz)	BCS										
CA_n260(A-D)	-	n260A	CA_n2 60D											800	0
CA_n260(2A-D)	-	CA_n260	D(2A)	CA_n260 D										1200	0
CA_n260(A-2D)	-	n260A	CA_r	1260(2D)										1200	0
CA_n260(2A-2D)	-	CA_n26	D(2A)	CA_n2	60(2D)									1600	0
CA_n260(A-D-O)	-	n260A	CA_n2 60D	CA_n260 O										1000	0
CA_n260(2A-D-O)	-	CA_n260	D(2A)	CA_n260 D	CA_n26 00									1400	0
CA_n260(A-D-2O)	-	n260A	CA_n2 60D	CA_n2										1200	0
CA_n260(2A-D- 2O)	-	CA_n260		CA_n260 D	CA_n	260(20)								1600	0
CA_n260(A-G)	CA_n260G	n260A	CA_n2 60G											600	0
CA_n260(2A-G)	CA_n260G	CA_n260		CA_n260 G										1000	0
CA_n260(A-2G)	CA_n260G	n260A	CA r	1260(2G)										800	0
CA_n260(2A-2G)	CA_n260G	CA_n260	D(2A)	CA_n2	60(2G)									1200	0
CA_n260(2A-2G- O)	-	CA_n260	D(2A)	CA_n20	. ,	CA_n260 O								1400	0
CA_n260(2A-2G- 2O)	-	CA_n260		CA_n20	60(2G)	CA_n26	50(2O)							1600	0
CA_n260(3A-2G)	-	CA	A_n260(3	A)	CA_n	260(2G)								1600	0
CA_n260(4A-G)	-			260(4A)		CA_n260 G								1800	0
CA_n260(4A-2G)	-			260(4A)		CA_n26	60(2G)							2000	0
CA_n260(A-2G- 2O)	-	n260A		n260(2G)		260(20)								1200	0
CA_n260(2A-G- 2O)	-	CA_n260	D(2A)	CA_n260 G	CA_n	260(20)								1400	0
CA_n260(3A-G)	CA_n260G		_n260(3	•	CA_n26 0G									1400	0
CA_n260(A-2H)	-	n260A		n260(2H)										1000	0
CA_n260(2A-H)	-	CA_n260		CA_n260 H										1100	0
CA_n260(2A-2H)	-	CA_n260		CA_n2	60(2H)									1400	0
CA_n260(A-H)	CA_n260G CA_n260H	n260A	CA_n2 60H											700	0
CA_n260(A-O)	-	n260A	CA_n2 60O											600	0

CA_n260(A-O-P)	-	n260A	CA_n2 600	CA_n260 P							900	0
CA_n260(A-O-2P)	-	n260A	CA_n2 600		60(2P)						1200	0
CA_n260(2A-O-P)	-	CA_n26		CA_n260 O	CA_n26 0P						1300	0
CA_n260(2A-O- 2P)	-	CA_n26	0(2A)	CA_n260 O		260(2P)					1600	0
CA_n260(2A-2O- P)	-	CA_n26	0(2A)	CA_n26	60(2O)	CA_n260 P					1500	0
CA_n260(A-O-Q)	-	n260A	CA_n2 600	CA_n260 Q							1000	0
CA_n260(A-O-2Q)	-	n260A	CA_n2 600	CA_n26	60(2Q)						1400	0
CA_n260(2A-O-Q)	-	CA_n26	0(2A)	CA_n260 O	CA_n26 0Q						1400	0
CA_n260(2A-O- 2Q)	-	CA_n26	0(2A)	CA_n260 O		260(2Q)					1800	0
CA_n260(2A-2O- Q)	-	CA_n26	0(2A)	CA_n26	60(2 O)	CA_n260 Q					1600	0
CA_n260(2A-O)	-	CA_n26	0(2A)	CA_n260 O							1000	0
CA_n260(A-2O)	-	n260A	CA r	n260(2O)							800	0
CA_n260(A-2O-P)	-	n260A	CA_r	n260(2O)	CA_n26 0P						1100	0
CA_n260(A-2O- 2P)	-	n260A	CA_r	n260(2O)	CA_n	260(2P)					1400	0
CA_n260(A-2O-Q)	-	n260A		1260(20)	CA_n26 0Q						1200	0
CA_n260(A-2O- 2Q)	-	n260A	CA_r	1260(20)	CA_n	260(2Q)					1600	0
CA_n260(2A-2O)	-	CA_n26	0(2A)	CA_n26	50(20)						1200	0
CA_n260(2A-2O- 2P)	-	CA_n26	. ,	CA_n26		CA_n26					1800	0
CA_n260(2A-2O- 2Q)	-	CA_n26	0(2A)	CA_n26	60(2O)	CA_n26	60(2Q)				2000	0
CA_n260(2A-3O)	-	CA_n26	0(2A)	C	A_n260(30))					1400	0
CA_n260(3A-2O)	-		A_n260(3			260(20)			1		1600	0
CA_n260(4A-O)	-			260(4A)		CÀ_n260 O					1800	0
CA_n260(4A-3O)	-		CA_n	260(4A)		CA_n260(3O)					2200	0
CA_n260(5A-O)	-			CA_n260(54	4)	/	CA_n26 00				2200	0
CA_n260(6A-O)	-			CA_n2	260(6A)			CA_n260 O			2600	0

CA_n260(7A-O)	-			(CA_n260(7	A)			CA_n26 00		2950	0
CA_n260(8A-O)	-				CA_n	260(8A)				CA_n2 600	2950	0
CA_n260(4A-2O)	-		CA n	260(4A)		CA_n26	60(2O)				2000	0
CA_n260(4A-2Q)	-			260(4A)		CA_n26					2400	0
CA_n260(3A-30)	-	CA	A_n260(3	A)	(CA_n260(3C))				1800	0
CA_n260(A-G-O)	-	n260A	CA_n2 60G	0		,					800	0
CA_n260(A-G-2O)	-	n260A	CA_n2 60G	CA_n26	60(20)						1000	0
CA_n260(2A-G-O)	-	CA_n26	0(2A)	CA_n260 G	CA_n26 00						1200	0
CA_n260(A-2G-O)	-	n260A	CA_r	1260(2G)	CA_n26 00						1000	0
CA_n260(A-3O)	-	n260A		CA_n260(30							1000	0
CA_n260(3A-O)	-	CA	A_n260(3	A)	CA_n26 00						1400	0
CA_n260(3A-O-P)	CA_n260O CA_n260P	CA	A_n260(3	A)	CA_n26 00	CA_n260 P					1700	0
CA_n260(A-4O)	-	n260A		CA_n	260(40)						1200	0
CA_n260(2A-4O)	-	CA n26	0(2A)		CA_n2	60(40)					1600	0
CA_n260(3A-4O)	-	CA	A_n260(3	A)		ĆA_n2	260(40)	•			2000	0
CA_n260(4A-4O)	-		CA_n	260(4A)			CA_n2				2400	0
CA_n260(5A-4O)	-			CA_n260(5/	4)			CA_n26	0(4O)		2800	0
CA_n260(A-P)	-	n260A	CA_n2 60P								700	0
CA_n260(A-3P)	-	n260A		CA_n260(3							1300	0
CA_n260(A-4P)	-	n260A			260(4P)						1600	0
CA_n260(A-P-Q)	CA_n260P CA_n260Q	n260A	CA_n2 60P	Q							1100	0
CA_n260(2A-P)	-	CA_n26	0(2A)	CA_n260 P							1100	0
CA_n260(3A-P)	-	C/	A_n260(3	A)	CA_n26 0P						1500	0
CA_n260(4A-P)	-		CA_n	260(4A)		CA_n260 P					1900	0
CA_n260(5A-P)	-			CA_n260(5/	A)		CA_n26 0P				2300	0
CA_n260(6A-P)	-			CA_n2	60(6A)		•	CA_n260 P			2700	0
CA_n260(A-2P)	-	n260A	CA_r	n260(2P)							1000	0
CA_n260(2A-2P)	-	CA_n26		CA_n20	50(2P)						1400	0
CA_n260(2A-3P)	-	CA_n26		C	A_n260(3F						1700	0
CA_n260(2A-4P)	-	CA_n26			CA_n2						2000	0
CA_n260(3A-2P)	-	CA	A_n260(3	A)	CA_n	260(2P)					1800	0

CA_n260(4A-2P)	-	С	CA_n260(4A)		CA_n26	0(2P)		1	1			2200	0
CA_n260(5A-2P)	-		CA_n260(5	A)	·		260(2P)				1	2600	0
CA_n260(5A-2O)	-		CA_n260(5				260(20)					2400	0
CA_n260(6A-2O)	-			260(6A)				60(20)				2800	0
CA_n260(5A-3O)	-		CA_n260(5	A)		(CA_n260(30	D)				2600	0
CA_n260(6A-30)	-		CA_n2	260(6A)	•			A_n260(3O)			2950	0
CA_n260(7A-2O)	-			CA_n260(7	YA)			CA_n2	60(20)			2950	0
CA_n260(7A-3O)	-			CA_n260(7	Ϋ́́A)			CA	A_n260(3	C)		2950	0
CA_n260(6A-2P)	-		CA_n2	260(6A)			CA_n2	260(2P)				2950	0
CA_n260(8A-2O)	-			CA_n	260(8A)				CA_n2	260(20)		2550	0
CA_n260(A-Q)	-		_n2)Q									800	0
CA_n260(A-2Q)	-		CA_n260(2Q)									1200	0
CA_n260(2A-Q)	-	CA_n260(2A										1200	0
CA_n260(2A-2Q)	-	CA_n260(2A) CA_n2	60(2Q)								1600	0
CA_n260(3A-Q)	-		260(3A)	CA_n26 0Q								1600	0
CA_n260(3A-2Q)	-	CA_n2	260(3A)		260(2Q)							2000	0
CA_n260(4A-Q)	-		CA_n260(4A)	. –	CA_n260 Q							2000	0
CA_n260(D-2G)	-	CA_n260 (D	CA_n260(2G)									800	0
CA_n260(2D-O)	-	CA_n260(2D) CA_n260 O									1000	0
CA_n260(D-2O)	-	CA_n260 (D	CA_n260(2O)									800	0
CA_n260(A-I)	CA_n260I		_n2 01									800	0
CA_n260(D-G)	CA_n260D CA_n260G	CA_n260 CA	_n2 DG									600	0
CA_n260(D-H)	CA_n260D CA_n260H		_n2 0H									700	0
CA_n260(D-I)	CA_n260D CA_n260I		_n2 i0I									800	0
CA_n260(D-O)	CA_n260D CA_n260O		_n2 00									600	0
CA_n260(D-P)	CA_n260D CA_n260P		_n2 0P									700	0
CA_n260(D-Q)	CA_n260D CA_n260Q		_n2)Q									800	0
CA_n260(E-O)	CA_n260E CA_n260O		_n2 0E									800	0
CA_n260(E-P)		CA_n260E		1				1	1			800	0

	CA_n260E CA_n260P		CA_n2 60P								
CA_n260(E-Q)	CA_n260E CA_n260Q	CA_n260E								1000	0
CA_n260(G-H)	 CA_n260G CA_n260H	CA_n260 G	CA_n2 60H							500	0
CA_n260(G-I)	CA_n260G CA_n260I	CA_n260 G	CA_n2 60I							600	0
CA_n260(G-O)	-	CA_n260 G	CA_n2 600							400	0
CA_n260(G-2O)	-	CA_n260 G		1260(20)						600	0
CA_n260(2G-O)	-	CA_n260	. ,	CA_n260 O						600	0
CA_n260(2G-2O)	-	CA_n260		CA_n2						800	0
CA_n260(G-3O)	-	CA_n260 G		CA_n260(3	-					800	0
CA_n260(3G-O)	-	C/	A_n260(3	G)	CA_n26 00					800	0
CA_n260(2G-3O)	-	CA_n260	0(2G)	C	A_n260(30))				1000	0
CA_n260(G-40)	-	CA_n260 G		CA_n	260(40)					1000	0
CA_n260(2G-4O)	-	CA_n260	0(2G)		CA n2	(4O)				1200	0
CA_n260(4G-O)	-			260(4G)		CA_n260 O				1000	0
CA_n260(H-O)	-	CA_n260 H	CA_n2 600							500	0
CA_n260(2H-O)	-	CA_n260	0(2H)	CA_n260 O						800	0
CA_n260(O-2P)	-	CA_n260 O		1260(2P)						800	0
CA_n260(O-2Q)	-	CA_n260 O		1260(2Q)						1000	0
CA_n260(O-P)	-	CA_n260 O	60P							500	0
CA_n260(2O-P)	-	CA_n260		CA_n						700	0
CA_n260(2O-2P)	-	CA_n26	0(2P)	CA_n20	60(20)					1000	0
CA_n260(O-Q)	-	CA_n260 0	60Q							600	0
CA_n260(2O-Q)	-	CA_n260	0(20)	CA_n260 Q						800	0
CA_n260(2O-2Q)	-	CA_n260	0(20)	CA_n20	60(2Q)					1200	0
CA_n260(P-Q)	-	CA_n260P	CA_n2 60Q							700	0
CA_n261(A-D)	-	n261A	CA_n2 61D							800	0

CA_n261(A-2D)	-	n261A	CA r	n261(2D)]	ĺ	1	1	Í	800	0
CA_n261(A-D-H)	-	n261A	CA_n2 61D	CA_n261 H						800	0
CA_n261(A-D-O)	-	n261A	CA_n2 61D	CA_n261 O						800	0
CA_n261(A-D-2O)	-	n261A	CA_n2 61D	CA_n26	61(20)					800	0
CA_n261(A-G)	CA_n261G	n261A	CA_n2 61G							600	0
CA_n261(A-G-H)	CA_n261G CA_n261H	n261A	CA_n2 61G	CA_n261 H						800	0
CA_n261(A-G-I)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61G	CA_n261I						800	0
CA_n261(A-G-O)	-	n261A	CA_n2 61G	CA_n261 O						800	0
CA_n261(A-G-2O)	-	n261A	CA_n2 61G	CA_n26	61(20)					800	0
CA_n261(A-2G-O)	-	n261A	CA_r	1261(2G)	CA_n26 10					800	0
CA_n261(A-2G- 2O)	-	n261A	CA_r	1261(2G)	CA_n	261(20)				800	0
CA_n261(A-3G)	-	n261A		CA_n261(30	G)					800	0
CA_n261(A-3G-Ó)	-	n261A		CA_n261(30		CA_n261 O				800	0
CA_n261(A-2G)	CA_n261G	n261A	CA_r	n261(2G)						800	
CA_n261(A-4G)	-	n261A		CA_n	261(4G)	- -				800	0
CA_n261(A-H)	CA_n261G CA_n261H	n261A	CA_n2 61H							700	0
CA_n261(A-2H)	-	n261A		n261(2H)						800	0
CA_n261(A-H-I)	-	n261A	61H	CA_n261I						800	0
CA_n261(A-I)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61I							800	0
CA_n261(A-2I)	-	n261A		n261(2l)						 800	0
CA_n261(A-J)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61J							700	0
CA_n261(A-K)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61K							800	0
CA_n261(A-O)	-	n261A	CA_n2 610							600	0
CA_n261(A-2O)	-	n261A		n261(2O)						800	0
CA_n261(A-30)	-	n261A		CA_n261(30	D)					800	0

CA_n261(A-4O)	-	n261A			261(40)					800	0
CA_n261(A-5O)	-	n261A		CA_n261(5O)			800	0			
CA_n261(A-6O)	-	n261A		CA_n261(6O)			800	0			
CA_n261(A-7O)	-	n261A		-		CA_n261(7	70)			800	0
CA_n261(A-P)	-	n261A	CA_n2 61P							700	0
CA_n261(A-2P)	-	n261A		n261(2P)						800	0
CA_n261(A-Q)	-	n261A	CA_n2 61Q							800	0
CA_n261(A-2Q)	-	n261A		n261(2Q)						800	0
CA_n261(2A-G)	CA_n261G	CA_n26	1(2A)	CA_n261 G						800	0
CA_n261(2A-H)	CA_n261G CA_n261H	CA_n26	1(2A)	CA_n261 H						800	0
CA_n261(2A-I)	CA_n261G CA_n261H CA_n261I	CA_n26	1(2A)	CA_n261I						800	0
CA_n261(3A-G)	CA_n261G	C/	A_n261(3	A)	CA_n26 1G					800	0
CA_n261(D-G)	CA_n261D CA_n261G	CA_n261 D	CA_n2 61G							600	0
CA_n261(D-H)	CA_n261D CA_n261H	CA_n261 D	CA_n2 61H							700	0
CA_n261(D-I)	CA_n261D CA_n261I	CA_n261 D	CA_n2 61I							800	0
CA_n261(D-O)	CA_n261D CA_n261O	CA_n261 D	CA_n2 610							600	0
CA_n261(D-2O)	-	CA_n261 D	CA_I	n261(2O)						800	0
CA_n261(D-P)	CA_n261D CA_n261P	CA_n261 D	CA_n2 61P							700	0
CA_n261(D-Q)	CA_n261D CA_n261Q	CA_n261 D	CA_n2 61Q							800	0
CA_n261(E-O)	CA_n261E CA_n261O	CA_n261E	CA_n2 610							800	0
CA_n261(E-P)	CA_n261E CA_n261P	CA_n261E	CA_n2 61P							800	0
CA_n261(E-Q)	CA_n261E CA_n261Q	CA_n261E	CA_n2 61Q							800	0
CA_n261(G-I)	CA_n261G CA_n261H CA_n261I	CA_n261 G	CA_n2 61I							600	0
CA_n261(G-H)	CA_n261G CA_n261H	CA_n261 G	CA_n2 61H							500	0

CA_n261(2G-2O)	-	CA_n26	1(2G)	CA_n2	61(2O)]						800	0
CA_n261(G-O)	-	CA_n261 G	CA_n2 610									400	0
CA_n261(G-2O)	-	CA_n261 G	CA_r	1261(20)								600	0
CA_n261(2G-O)	-	CA_n26 [°]	1(2G)	CA_n261 O								600	0
CA_n261(3G-O)	-	CA	_n261(3	G)	CA_n26 10							800	0
CA_n261(H-I)	CA_n261G CA_n261H CA_n261I	CA_n261 H	CA_n2 61I									700	0
NOTE 4: Configura NOTE 5: Configura NOTE 6: Void NOTE 7: Unless ot	NOTE 1: Void NOTE 2: Void NOTE 3: Channel bandwidth per operating band defined in Table 5.3.5-1 NOTE 4: Configurations for intra-band contiguous CA defined in Table 5.5A.1-1 NOTE 5: Configurations for intra-band non-contiguous CA defined in Table 5.5A.2-1												

5.5A.3 Configurations for inter-band CA

NR CA configuration	Uplink CA configuration	NR Band	Char	Channel bandwidth (MHz) (NOTE 1)			Bandwidth combination set
			50	100	200	400	
CA_n260A- n261A	-	n260	50	100	200	400	0
		n261	50	100	200	400	
NOTE 1: The SCS	NOTE 1: The SCS of each channel bandwidth for NR band refers to Table 5.3.5-1.						

Table 5.5A.3-1: NR CA configurations for inter-band CA

5.5D Configurations for UL MIMO

The requirements specified in clause 5.5 are applicable to UE supporting UL MIMO.

6 Transmitter characteristics

6.1 General

Unless otherwise stated, the transmitter characteristics are specified over the air (OTA) with a single or multiple transmit chains.

Unless otherwise stated, for power class 3 UEs, the beam correspondence side condition for SSB and CSI-RS specified in clause 6.6.4 shall apply to the transmission tests.

Transmitter requirements for CA operation apply only when the DMRS initialization parameters (including the case when the UE applies cell ID as DMRS scrambling ID) are different across all CCs. The UE may use higher MPR values outside this limitation.

For a UE that supports 'UL full power transmission' and is configured to transmit a single layer with *nrofSRS-Ports* = 2, the requirements for UL MIMO operation apply only when it is configured for any of its declared full power modes in IE *FullPowerTransmission-r16* (as defined in TS 38.331[13]).

For a UE configured to transmit 2 layers, transmitter requirements for UL MIMO operation apply when the UE transmits on 2 ports on the same CDM group. The UE may use higher MPR values outside this limitation.

6.2 Transmitter power

6.2.1 UE maximum output power

6.2.1.0 General

NOTE: Power class 1, 2, 3, and 4 are specified based on the assumption of certain UE types with specific device architectures. The UE types can be found in Table 6.2.1.0-1.

UE Power class	UE type
1	Fixed wireless access (FWA) UE
2	Vehicular UE
3	Handheld UE
4	High power non-handheld UE

Table 6.2.1.0-1: Assumption of UE Types

Power class 3 is default power class.

6.2.1.1 UE maximum output power for power class 1

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.1-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)
n257	40.0
n258	40.0
n260	38.0
n261	40.0
NOTE 1: Minimum peak EIRP is	s defined as the lower limit without tolerance

The maximum output power values for TRP and EIRP are found in Table 6.2.1.1-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.1-2: UE maximum output power limits for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.1-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 85 %-tile CDF (dBm)					
n257	32.0					
n258	32.0					
n260	30.0					
n261	32.0					
	Minimum EIRP at 85 %-tile CDF is defined as the lower limit without tolerance					
NOTE 2: The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.						

6.2.1.2 UE maximum output power for power class 2

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.2-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)		
n257	29		
n258	29		
n261	29		
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance			

Table 6.2.1.2-1: UE minimum peak EIRP for power class 2

The maximum output power values for TRP and EIRP are found in Table 6.2.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

The minimum EIRP at the 60th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.2-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Operating band		Min EIRP at 60 %-tile CDF (dBm)
n2	257	18.0
n2	258	18.0
n2	261	18.0
NOTE 1:	Minimum EIRP at 60 %-tile CDF is defined as the lower limit without tolerance	
NOTE 2:	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.	

Table 6.2.1.2-3: UE spherical coverage for power class 2

6.2.1.3 UE maximum output power for power class 3

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.3-1. The requirement is verified with the test metric of total component of EIRP (Link=TX beam peak direction, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-1. The requirement for the UE which supports a specified in both Table 6.2.1.3-1 and Table 6.2.1.3-4.

Table 6.2.1.3-1: UE	minimum pe	eak EIRP for	power class 3
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Operating band	Min peak EIRP (dBm)	
n257	22.4	
n258	22.4	
n259	18.7	
n260	20.6	
n261	22.4	
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		
NOTE 2: Void		

The maximum output power values for TRP and EIRP are found on the Table 6.2.1.3-2. The max allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and the total component of EIRP (Link=TX beam peak direction, Meas=Link angle.

Table 6.2.1.3-2: UE maximum output power limits for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43
n260	23	43
n261	23	43

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.3-3 below. The requirement is verified with the test metric of the total component of EIRP (Link=Beam peak search grids, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-3. The requirement for the UE which supports multiple FR2 bands is specified in both Table 6.2.1.3-3 and Table 6.2.1.3-4.

Operating band		Min EIRP at 50 %-tile CDF (dBm)	
	n257	11.5	
	n258	11.5	
	n259	5.8	
n260		8	
n261		11.5	
_	lower limit without tole	%-tile CDF is defined as the grance	
NOTE 2: Void NOTE 3: The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.			

 Table 6.2.1.3-3: UE spherical coverage for power class 3

For the UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.3-1 and 6.2.1.3-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter $\Delta MB_{S,n}$, as defined in Table 6.2.1.3-4..

Table 6.2.1.3-4: UE multi-band relaxation factors for	power class 3
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Band	ΔMB _{P,n} (dB)	∆MB _{s,n} (dB)			
n257	0.7 ³	0.7 ³			
n258	0.6	0.7			
n259	0.5	0.4			
n260	0.5 ¹	0.4 ¹			
n261	0.5 ^{2,4}	0.74			
n261+n260 Note 2: n261 peak relaxation is Note 3: n257 peak and spherica n261+n257	Note 1: n260 peak and spherical relaxations are 0 dB for UE that exclusively supports n261+n260 Note 2: n261 peak relaxation is 0 dB for UE that exclusively supports n261+n260 Note 3: n257 peak and spherical relaxations are 0 dB for UE that exclusively supports n261+n257 Note 4: n261 peak and spherical relaxations are 0 dB for UE that exclusively supports				

6.2.1.4 UE maximum output power for power class 4

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.4-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)	
n257	34	
n258	34	
n260	31	
n261	34	
NOTE 1: Minimum peak EIRP is defined as the		
lower limit without tolerance		

Table 6.2.1.4-1: UE minimum peak EIRP for power class 4

The maximum output power values for TRP and EIRP are found in Table 6.2.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

Table 6.2.1.4-2: UE maximum output power limits for power class 4

The minimum EIRP at the 20th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.4-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2.1.4-3: UE spherical coverage for power class 4

Operating band	Min EIRP at 20 %-tile CDF (dBm)	
n257	25	
n258	25	
n260	19	
n261	25	
	Minimum EIRP at 20 %-tile CDF is defined as the lower limit without tolerance	
NOTE 2: The requirements in this table are verified onl under normal temperature conditions as defined in Annex E.2.1.		

6.2.2 UE maximum output power reduction

6.2.2.0 General

The requirements in clause 6.2.2 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. A UE may reduce its maximum output power due to modulation orders, transmit bandwidth configurations, waveform types and narrow allocations. This Maximum Power Reduction (MPR) is defined in clauses below. The allowed MPR for SRS, PUCCH formats 0, 1, 3 and 4, and PRACH shall be as specified for QPSK modulated DFT-s-OFDM of equivalent RB allocation. The allowed MPR for PUCCH format 2 shall be as specified for QPSK modulated CP-OFDM of equivalent RB allocation. When the maximum output power of a UE is modified by MPR, the power limits specified in clause 6.2.4 apply.

For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in clause 6.2A.2 apply.

For all power classes, the waveform defined by BW = 100 MHz, SCS = 120 kHz, DFT-S-OFDM QPSK, 20RB23 is the reference waveform with 0 dB MPR and is used for the power class definition.

6.2.2.1 UE maximum output power reduction for power class 1

For power class 1, MPR for contiguous allocations is defined as:

 $MPR = max(MPR_{WT}, MPR_{narrow})$

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$, when $BW_{alloc,RB} \le 1.44 \text{ MHz}$, $MPR_{narrow} = 10 \text{ dB}$, when $1.44 \text{ MHz} < BW_{alloc,RB} \le 10.8 \text{ MHz}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in table 5.3.2-1, and waveform types. MPR_{WT} is defined in Tables 6.2.2.1-1 and 6.2.2.1-2.

Modulation		MPRwт (dB), BW _{channel} ≤ 200 MHz		
		Outer RB allocations	Inner RB allocations	
			Region 1	Region 2
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0
	QPSK	≤ 6.5	0.0	≤ 3.0
	16 QAM	≤ 6.5	≤ 4.0	≤ 4.0
	64 QAM	≤ 6.5	≤ 5.0	≤ 5.0
CP-OFDM	QPSK	≤ 7.0	≤ 4.5	≤ 4.5
	16 QAM	≤ 7.0	≤ 5.5	≤ 5.5
	64 QAM	≤ 7.5	≤ 7.5	≤ 7.5

Table 6.2.2.1-1 MPR_{WT} for power class 1, BW_{channel} ≤ 200 MHz

Table 6.2.2.1-2 MPR_{WT} for power class 1, BW_{channel} = 400 MHz

Modulation		MPRwt (dB), BW _{channel} = 400 MHz		
		Outer RB allocations	Inner RB allocations	
			Region 1	Region 2
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0
	QPSK	≤ 6.5	0.0	≤ 3.5
	16 QAM	≤ 6.5	≤ 4.5	≤ 4.5
	64 QAM	≤ 6.5	≤ 6.5	≤ 6.5
CP-OFDM	QPSK	≤ 7.0	≤ 5.0	≤ 5.0
	16 QAM	≤ 7.0	≤ 6.5	≤ 6.5
	64 QAM	≤ 9.0	≤ 9.0	≤ 9.0

Where the following parameters are defined to specify valid RB allocation ranges for the RB allocations regions in Tables 6.2.2.1-1 and 6.2.2.1-2:

N_{RB} is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

 $RB_{end} = RB_{Start} + L_{CRB}$ - 1

 $RB_{Start,Low} = Max(1, Floor(L_{CRB}/2))$

 $RB_{Start,High} = N_{RB} - RB_{Start,Low} - L_{CRB}$

An RB allocation is an Outer RB allocation if

 $RB_{Start} < RB_{Start,Low} OR RB_{Start} > RB_{Start,High} OR L_{CRB} > Ceil(N_{RB}/2)$

An RB allocation belonging to table 6.2.2.1-1 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/3 N_{RB}) AND RB_{end} < Ceil(2/3 N_{RB})$$

An RB allocation belonging to table 6.2.2.1-2 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/4 N_{RB}) AND RB_{end} < Ceil(3/4 N_{RB}) AND L_{CRB} \le Ceil(1/4 N_{RB})$$

An RB allocation is a Region 2 inner allocation if it is NOT an Outer allocation AND NOT a Region 1 inner allocation

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2.4 apply.

6.2.2.2 UE maximum output power reduction for power class 2

For power class 2, MPR specified in clause 6.2.2.3 applies.

Table 6.2.2.2-1: Void

6.2.2.3 UE maximum output power reduction for power class 3

For power class 3, MPR for contiguous allocations is defined as:

$$MPR = max(MPR_{WT}, MPR_{narrow})$$

For transmission bandwidth configuration less than or equal to 200MHz, and $0 \le RB_{start} < Ceil(1/3 N_{RB})$ or $Ceil((2/3N_{RB}) - L_{CRB}) < RB_{start} \le N_{RB} - L_{CRB}$:

- $MPR_{narrow} = 2.5 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz,
- $MPR_{narrow} = 2.0 \text{ dB}$, when 1.44 MHz < $BW_{alloc,RB} \le 4.32 \text{ MHz}$,
- otherwise $MPR_{narrow} = 0 dB$.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types. MPR_{WT} is defined in Table 6.2.2.3-1.

Table 6.2.2.3-1 MPR _{WT} for pe	ower class 3, BWchannel	≤ 200 MHz
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Modula	tion	MPR _{WT} , BW _{channel} ≤ 200 MHz		
		Inner RB allocations, Region 1	Edge RB allocations	
DFT-s-OFDM	Pi/2 BPSK	0.0	≤ 2.0	
	QPSK	0.0	≤ 2.0	
	16 QAM	≤ 3.0	≤ 3.5	
	64 QAM	≤ 5.0	≤ 5.5	
CP-OFDM	QPSK	≤ 3.5	≤ 4.0	
	16 QAM	≤ 5.0	≤ 5.0	
	64 QAM	≤ 7.5	≤ 7.5	

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Table 6.2.2.3-1:

- $RB_{Start,Low} = max(1, L_{CRB})$, where max() indicates the largest value of all arguments.
- $RB_{Start,High} = N_{RB} RB_{Start,Low} L_{CRB}$,

An RB allocation belonging to table 6.2.2.3-1 is a Region 1 inner RB allocation if:

- $RB_{Start,Low} \le RB_{Start} \le RB_{Start,High}$, and $L_{CRB} \le ceil(N_{RB}/3)$, where ceil(x) is the smallest integer greater than or equal to x.

For transmission bandwidth configuration equal to 400MHz,

 $MPR_{narrow} = 2.5 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz, and $0 \le RB_{start} < Ceil(1/3 N_{RB})$ or $Ceil(2/3N_{RB}) \le RB_{start} \le N_{RB}-L_{CRB}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types. MPR_{WT} is defined in Table 6.2.2.3-2.

Modula	tion	MPR _{WT} , BW _{channel} = 400 MHz		
		Inner RB allocations, Region 1	Edge RB allocations	
DFT-s-OFDM	Pi/2 BPSK	0.0	≤ 3.0	
	QPSK	0.0	≤ 3.0	
	16 QAM	≤ 4.5	≤ 4.5	
	64 QAM	≤ 6.5	≤ 6.5	
CP-OFDM	QPSK	≤ 5.0	≤ 5.0	
	16 QAM	≤ 6.5	≤ 6.5	
	64 QAM	≤ 9.0	≤ 9.0	

Table 6.2.2.3-2 MPR_{WT} for power class 3, BW_{channel} = 400 MHz

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Table 6.2.2.3-2:

N_{RB} is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

$$RB_{end} = RB_{Start} + L_{CRB} - 1$$

An RB allocation belonging to table 6.2.2.3-2 is a Region 1 inner RB allocation if

 $RB_{start} \ge Ceil(1/4 N_{RB}) AND RB_{end} < Ceil(3/4 N_{RB}) AND L_{CRB} \le Ceil(1/4 N_{RB})$

For all transmission bandwidth configurations, an RB allocation is an Edge allocation if it is NOT a Region 1 inner allocation.

6.2.2.4 UE maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2.2.3 applies.

Table 6.2.2.4-1: Void

6.2.3 UE maximum output power with additional requirements

6.2.3.1 General

Additional emission requirements can be signalled by the network. Each additional emission requirement is associated with a unique network signalling (NS) value indicated in RRC signalling by an NR frequency band number of the applicable operating band and an associated value in the field *additionalSpectrumEmission*. Throughout this specification, the notion of indication or signalling of an NS value refers to the corresponding indication of an NR frequency band number of the applicable operating band (the IE field *freqBandIndicatorNR*) and an associated value of *additionalSpectrumEmission* in the relevant RRC information elements.

To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in clause 6.2.1. Unless stated otherwise, an A-MPR of 0 dB shall be used.

Table 6.2.3.1-1 specifies the additional requirements with their associated network signalling values and the allowed A-MPR and applicable operating band(s) for each NS value. The mapping of NR frequency band numbers and values of the *additionalSpectrumEmission* to network signalling labels is specified in Table 6.2.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2.2.

Network Signalling Iabel	Requirements (clause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (<i>N</i> _{RB})	A-MPR (dB)	
NS_200					N/A	
NS_201 (NOTE 1)	6.5.3.2.2	n258			6.2.3.2	
NS_202	6.5.3.2.3	n257, n258	50, 100, 200, 400	Table 5.3.2-1	6.2.3.3	
NS_203	6.5.3.2.4	n258	50, 100, 200, 400	Table 5.3.2-1	6.2.3.4	
	NOTE 1: NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.					

Table 6.2.3.1-1: Additional maximum power reduction (A-MPR)

NR Band		Value of additionalSpectrumEmission (NOTE 1)						
	0	1	2	3	4	5	6	7
n257	NS_200	NS_202						
n258	NS_200	NS_201 (NOTE 2)	NS_202	NS_203				
n259	NS_200							
n260	NS_200							
n261	NS_200							
NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in sub-clause 6.3.2 of TS 38.331 [13].								
				ditional spur	ious emissio	on requireme	nts are not a	applicable.

- 6.2.3.2 Void
- 6.2.3.2.1 Void
- Table 6.2.3.2.1-1: (Void)
- 6.2.3.2.2 Void
- Table 6.2.3.2.2-1: (Void)
- 6.2.3.2.3 Void

Table 6.2.3.2.3-1: (Void)

- 6.2.3.2.4 Void
- 6.2.3.3 A-MPR for NS_202
- 6.2.3.3.1 A-MPR for NS_202 for power class 1

For power class 1, A-MPR for NS_202 shall be 11.0 dB.

6.2.3.3.2 A-MPR for NS_202 for power class 2

For power class 2, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.3.3 A-MPR for NS_202 for power class 3

For power class 3, A-MPR for NS_202 shall be 1.0 dB.

6.2.3.3.4 A-MPR for NS_202 for power class 4

For power class 4, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.4 A-MPR for NS_203

6.2.3.4.1 A-MPR for NS_203 for power class 1

For power class 1, A-MPR for NS_203 shall be 3.0 dB if Offset frequency $< BW_{channel}$, 0.0 dB otherwise. The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the channel bandwidth.

6.2.3.4.2 A-MPR for NS_203 for power class 2

For power class 2, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.3.4.3 A-MPR for NS_203 for power class 3

For power class 3, A-MPR for NS_203 shall be 0 dB.

6.2.3.4.4 A-MPR for NS_203 for power class 4

For power class 4, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.4 Configured transmitted power

The UE can configure its maximum output power. The configured UE maximum output power $P_{CMAX,f,c}$ for carrier f of a serving cell c is defined as that available to the reference point of a given transmitter branch that corresponds to the reference point of the higher-layer filtered RSRP measurement as specified in TS 38.215 [11].

The configured UE maximum output power $P_{CMAX,f,c}$ for carrier *f* of a serving cell *c* shall be set such that the corresponding measured peak EIRP $P_{UMAX,f,c}$ is within the following bounds

$$\begin{split} P_{Powerclass} + \Delta P_{IBE} - MAX(MAX(MPR_{f,c}, \text{A-} MPR_{f,c},) + \Delta MB_{P,n}, P-MPR_{f,c}) - MAX\{T(MAX(MPR_{f,c}, \text{A-} MPR_{f,c},)), T(P-MPR_{f,c})\} \leq P_{UMAX,f,c} \leq EIRP_{max} \end{split}$$

while the corresponding measured total radiated power P_{TMAX,f,c} is bounded by

$P_{TMAX,f,c} \leq TRP_{max}$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2.1, EIRP_{max} the applicable maximum EIRP as specified in sub-clause 6.2.1, MPR_{f,c} as specified in sub-clause 6.2.2, A-MPR_{f,c} as specified in sub-clause 6.2.3, $\Delta MB_{P,n}$ the peak EIRP relaxation as specified in clause 6.2.1 and TRP_{max} the maximum TRP for the UE power class as specified in sub-clause 6.2.1. ΔP_{IBE} is 1.0 dB if UE declares support for *mpr-PowerBoost-FR2-r16*, UL transmission is QPSK, MPR_{f,c} = 0 and when NS_200 applies and the network configures the UE to operate with *mpr-PowerBoost-FR2-r16* otherwise ΔP_{IBE} is 0.0 dB. The requirement is verified in beam peak direction.

maxUplinkDutyCycle-FR2, as defined in TS 38.306 [14], is a UE capability to facilitate electromagnetic power density exposure requirements. This UE capability is applicable to all FR2 power classes.

If the field of UE capability *maxUplinkDutyCycle-FR2* is present and the percentage of uplink symbols transmitted within any 1 s evaluation period is larger than *maxUplinkDutyCycle-FR2*, the UE follows the uplink scheduling and can apply P-MPR_{f,c}.

If the field of UE capability *maxUplinkDutyCycle-FR2* is absent, the compliance to electromagnetic power density exposure requirements are ensured by means of scaling down the power density or by other means.

 $P-MPR_{f,c}$ is the power management maximum output power reduction. The UE shall apply $P-MPR_{f,c}$ for carrier f of serving cell c only for the cases described below. For UE conformance testing $P-MPR_{f,c}$ shall be 0 dB.

- a) ensuring compliance with applicable electromagnetic power density exposure requirements and addressing unwanted emissions / self desense requirements in case of simultaneous transmissions on multiple RAT(s) for scenarios not in scope of 3GPP RAN specifications;
- b) ensuring compliance with applicable electromagnetic power density exposure requirements in case of proximity detection is used to address such requirements that require a lower maximum output power.
- NOTE 1: P-MPR_{f,c} was introduced in the P_{CMAX,f,c} equation such that the UE can report to the gNB the available maximum output transmit power. This information can be used by the gNB for scheduling decisions.
- NOTE 2: P-MPR_{f,c} and *maxUplinkDutyCycle-FR2* may impact the maximum uplink performance for the selected UL transmission path.
- NOTE 3: MPE P-MPR Reporting capability *tdd-MPE-P-MPR-Reporting-r16*, as defined in TS 38.306 [14], is used to report P-MPR_{f,c} when the reporting conditions configured by gNB are met. This UE capability is applicable to all FR2 power classes.

The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB) is specified in Table 6.2.4-1.

Operating Band	∆ P (dB)	Tolerance T(∆P) (dB)			
n257, n258, n259, n260, n261	$\Delta P = 0$	0			
	0 < ∆P ≤ 2	1.5			
	2 < ∆P ≤ 3	2.0			
	3 < ∆P ≤ 4	3.0			
	4 < ∆P ≤ 5	4.0			
	5 < ∆P ≤ 10	5.0			
	10 < ∆P ≤ 15	7.0			
	15 < ∆P ≤ X	8.0			
NOTE: X is the value	ue such that Pumax,f,c lower bound, PPowerclass -				
$\Delta P - T(\Delta P)$	= minimum output powe	er specified in clause			
6.3.1					

Table 6.2.4-1: PUMAX, f, c tolerance

6.2A Transmitter power for CA

6.2A.1 UE maximum output power for CA

For downlink intra-band contiguous and non-contiguous carrier aggregation with a single uplink component carrier configured in the NR band, the maximum output power is specified in clause 6.2.1.

For uplink intra-band contiguous and non-contiguous carrier aggregation for any CA bandwidth class, the maximum output power is specified in clause 6.2.1.

Power class 3 is default power class.

6.2A.2 UE maximum output power reduction for CA

6.2A.2.1 General

The UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA. In CA operation, the UE may reduce its maximum output power due to higher order modulations and transmit bandwidth configurations. This Maximum Power Reduction (MPR) is defined in clauses below. The allowed MPR for SRS, PUCCH formats 0, 1, 3 and 4, shall be as specified for QPSK modulated DFT-s-OFDM of equivalent RB allocation. The allowed MPR for PUCCH format 2, shall be as specified for QPSK modulated CP-OFDM of equivalent RB allocation.

When the maximum output power of a UE is modified by MPR, the power limits specified in clause 6.2A.4 apply.

The requirements in the following clauses are applicable to the following CA configurations:

- intra-band contiguous uplink CA, with the aggregated channel bandwidth no greater than 800 MHz.
- intra-band non-contiguous uplink CA with UL frequency separation no greater than 1400 MHz, and no more than 3 sub-blocks. A sub-block may consist of single CC or multiple contiguous CCs.
- In case the CA configuration consists of a single UL CC, MPR for contiguous UL CA applies and where necessary, BW_{channel} shall be used as BW_{channel_CA}.

6.2A.2.2 Maximum output power reduction for power class 1

6.2A.2.2.1 Maximum output power reduction for power class 1 intra-band contiguous UL CA

For power class 1, MPR for intra-band contiguous UL CA with contiguous allocations within the cumulative aggregated bandwidth is defined as:

$$MPR_{C_CA} = max(MPR_{WT_C_CA}, MPR_{narrow})$$

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz, $MPR_{narrow} = 10 \text{ dB}$, when 1.44 MHz < $BW_{alloc,RB} \le 10.8 \text{ MHz}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 $MPR_{WT_C_CA}$ is the maximum power reduction due to modulation orders, transmit bandwidth configurations, and waveform types. $MPR_{WT_C_CA}$ is defined in Table 6.2A.2.2-1.

Wavefo	rm Type	Cumulative aggregated channel bandwidth				
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5 ¹	7.7	8.2	≤ 8.7	
	QPSK	≤ 6.5 ¹	8.7	9.7	≤ 9.7	
	16 QAM	≤ 6.5	8.7	9.2	≤ 9.7	
	64 QAM	≤ 9.0	10.7	11.2	≤ 11.7	
CP-OFDM	QPSK	≤ 6.5	8.7	8.7	≤ 9.7	
	16 QAM	≤ 6.5	8.7	8.7	≤ 9.7	
	64 QAM	≤ 9.0	10.7	11.2	≤ 11.7	
NOTE 1: (Void)						

Table 6.2A.2.2-1: Maximum power reduction (MPR_{wt c cA}) for UE power class 1

In case of a contiguous RB, DFT-s-BPSK or DFT-s-QPSK UL allocation in a single CC of a CA configuration with contiguous CCs, and whose cumulative aggregated BW \leq 400 MHz, MPR_{WT_C_CA} shall be derived instead as MAX(MPR₁, MPR₂), where:

MPR₁ shall be determined from Table 6.2.2.1-1 if CABW \leq 200 MHz, from Table 6.2.2.1-2 if CABW > 200 MHz.

MPR₂ shall be determined from Table 6.2.2.1-1 if UL BW_{channel_CA} \leq 200 MHz, from Table 6.2.2.1-2 if UL BW_{channel_CA} > 200 MHz.

and assume all UL CCs use the same SCS for the purpose of determination of inner and outer RB allocations in Table 6.2.2.1-1 and Table 6.2.2.1-2:

N_{RB} shall be chosen as the sum of N_{RB} of all constituent UL CCs in the CA configuration.

L_{CRB} shall be chosen as BW_{alloc,RB}

RB_{start} shall be derived as: RB_{start_allocatedCC}+N_{RB_unallocatedCC_low}

 $RB_{start_allocatedCC}$ is the index of the first allocated RB in the CC with allocation

N_{RB_unallocatedCC_low} is the sum of N_{RB} in all UL CCs lower in frequency compared to the CC with allocation

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest $MPR_{C_{CA}}$.

For intra-band contiguous UL CA with non-contiguous RB allocations, the following rule for MPR applies:

 $MPR = max(MPR_{C_{CA}}, -10*A + 14.4)$

Where:

 $A = N_{RB_alloc} \ / \ N_{RB_agg_C.}$

 N_{RB_alloc} is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs

6.2A.2.2.2 Maximum output power reduction for power class 1 intra-band non-contiguous UL CA

For intra-band non-contiguous UL CA, the following rule for MPR applies:

$$MPR = max(MPRNC_CA, -10*A + 14.4)$$

Where:

MPR_{NC_CA} is derived from table 6.2A.2.2-1

 $A = N_{RB_alloc} / N_{RB_agg_C.}$

 N_{RB_alloc} is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs.

Wavefo	orm Type	Cumulative aggregated channel bandwidth (CABW)					
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz		
DFT-s-OFDM	Pi/2 BPSK	≤ 6	≤ 7.7	≤ 8.2	≤ 8.7		
	QPSK	≤7	≤ 8.7	≤ 9.2	≤ 9.7		
	16 QAM	≤7	≤ 8.7	≤ 9.2	≤ 9.7		
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7		
CP-OFDM	QPSK	≤7	≤ 8.7	≤ 9.2	≤ 9.7		
	16 QAM	≤7	≤ 8.7	≤ 9.2	≤ 9.7		
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7		

Table 6.2A.2.2.2-1: MPR_{NC_CA} for UE power class 1

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest $MPR_{NC_{CA}}$.

6.2A.2.3 Maximum output power reduction for power class 2

For power class 2, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

Table 6.2A.2.3-1: (Void)

6.2A.2.4 Maximum output power reduction for power class 3

6.2A.2.4.1 Maximum output power reduction for power class 3 intra-band contiguous CA

For power class 3, MPR for intra-band contiguous UL CA with contiguous allocations within the cumulative aggregated bandwidth is denoted as $MPR_{C_{CA}}$ and is defined in Table 6.2A.2.4-1.

Table 6.2A.2.4-1: Maximum	power reduction	(MPR _{C_CA}) for UE	power class 3
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		Cumulative aggregated channel bandwidth (CABW)				
		≤ 400 MHz	> 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.0 ¹	≤ 7.7	≤ 8.2	≤ 8.7	
	QPSK	≤ 5.0 ¹	≤ 7.7	≤ 8.2	≤ 9.7	
	16 QAM	≤ 6.5	≤ 8.7	≤ 9.3	≤ 9.7	
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7	
CP-OFDM	QPSK	≤ 5.0	≤ 7.5	≤ 8.0	≤ 9.7	
	16 QAM	≤ 6.5	≤ 8.7	≤ 9.2	≤ 9.7	
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7	
NOTE 1: (Void).						

In case of a contiguous RB, DFT-s-BPSK or DFT-s-QPSK UL allocation in a single CC of a CA configuration with contiguous CCs, and whose cumulative aggregated BW \leq 400 MHz, MPR_{C_CA} shall be derived instead as MAX(MPR₁, MPR₂), where:

MPR₁ shall be determined from Table 6.2.2.3-1 if CABW \leq 200 MHz, from Table 6.2.2.3-2 if CABW > 200 MHz.

MPR₂ shall be determined from Table 6.2.2.3-1 if UL BW_{channel_CA} \leq 200 MHz, from Table 6.2.2.3-2 if UL BW_{channel_CA} > 200 MHz.

and assume all UL CCs use the same SCS for the purpose of determination of inner and outer RB allocations in Table 6.2.2.3-1 and Table 6.2.2.3-2:

 N_{RB} shall be chosen as the sum of N_{RB} of all constituent UL CCs in the CA configuration.

 L_{CRB} shall be chosen as $BW_{\text{alloc},\text{RB}}$

 $RB_{start}\ shall \ be \ derived \ as: \ RB_{start_allocatedCC} + N_{RB_unallocatedCC_low}$

 $RB_{\text{start_allocatedCC}}$ is the index of the first allocated RB in the CC with allocation

 $N_{RB_unallocatedCC_low}$ is the sum of N_{RB} in all UL CCs lower in frequency compared to the CC with allocation

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the highest contiguous MPR.

For intra-band contiguous UL CA with non-contiguous RB allocations, the following rule for MPR applies:

 $MPR = max(MPR_{C_{CA}}, -10*A + 7.0)$

Where:

 $A = N_{RB_alloc} / N_{RB_agg_C.}$

 N_{RB_alloc} is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs

6.2A.2.4.2 Maximum output power reduction for power class 3 intra-band non-contiguous CA

For intra-band non-contiguous UL CA, the following rule for MPR applies:

 $MPR = max(MPRNC_CA, -8*A + 10.0)$

Where:

MPR_{NC_CA} is derived from table 6.2A.2.4.2-1

$$A = N_{RB_alloc} / N_{RB_agg_C.}$$

 N_{RB_alloc} is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs.

		Cumulative aggregated channel bandwidth (CABW)					
		≤ 400 MHz	> 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz		
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	≤ 7.7	≤ 8.2	≤ 8.7		
	QPSK	≤ 6	≤ 7.7	≤ 8.2	≤ 8.7		
	16 QAM	≤7	≤ 8.7	≤ 9.3	≤ 9.8		
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7		
CP-OFDM	QPSK	≤ 6	≤ 7.5	≤ 8.0	≤ 8.5		
	16 QAM	≤7	≤ 8.7	≤ 9.2	≤ 9.7		
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7		

Table 6.2A.2.4.2-1: MPR_{NC_CA} for UE power class 3

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest $MPR_{NC_{CA}}$.

6.2A.2.5 Maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

6.2A.3 UE maximum output power with additional requirements for CA

6.2A.3.1 General

Additional emission requirements can be signalled by the network with network signalling value indicated by the field *additionalSpectrumEmission*. To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in clause 6.2A.1. Unless stated otherwise, an A-MPR of 0 dB shall be used. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2A.2.

For intra-band contiguous aggregation with the UE configured for transmissions on two serving cells, the maximum output power reduction specified in Table 6.2A.3.1-1 is allowed for all serving cells of the applicable uplink contiguous CA configurations according to the CA network signalling value indicated by the field *additionalSpectrumEmissionSCell*.

Table 6.2A.3.1-1 specifies the additional requirements and allowed A-MPR with corresponding network signalling label and operating band. The mapping between network signalling labels and the *additionalSpectrumEmission* IE defined in TS 38.331 [13] is specified in Table 6.2A.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2A.2.

Network Signalling value	Requirements (clause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (<i>N</i> _{RB})	A-MPR (dB)
CA_NS_200					N/A
CA_NS_201	6.5.3.2.2	n258			6.2A.3.2
CA_NS_202	6.5.3.2.3	n257, n258			6.2A.3.3
CA_NS_203	6.5.3.2.4	n258			6.2A.3.4
NOTE: CA_NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.					

Table 6.2A.3.1-1: Additional maximum power reduction (A-MPR)

Table 6.2A.3.1-2: Value of	additionalS	pectrumEmission
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0123456n257CA_NS_200CA_NS_202Image: constraint of the same name defined in clause to 38.331 [13].Image: constraint of the same name defined in clause to 38.331 [13].NOTE 2:CA_NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.	7		
n258 CA_NS_200 CA_NS_201 CA_NS_202 CA_NS_203 Image: colored colore			
n259 CA_NS_200 Image: CA_NS_200 n260 CA_NS_200 Image: CA_NS_200 n261 CA_NS_200 Image: CA_NS_200 NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in clause TS 38.331 [13].			
n260 CA_NS_200 n261 CA_NS_200 NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in clause TS 38.331 [13].			
n261 CA_NS_200 NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in clause TS 38.331 [13].			
NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in clause TS 38.331 [13].			
TS 38.331 [13].			
	e 6.3.2 o		
6.2A.3.2 Void			
6.2A.3.2.1 Void			
Table 6.2A.3.2.1-1: (Void)			
6.2A.3.2.2 Void			
0.2A.3.2.2 VOIU			
Table 6 24 2 2 2 1, ()(aid)			
Table 6.2A.3.2.2-1: (Void)			
6.2A.3.2.3 Void			
Table 6.2A.3.2.3-1: Void			
6.2A.3.2.4 Void			
6.2A.3.3 A-MPR for CA_NS_202			
$0.2A.3.3 \qquad A-WPR IOF CA_NS_202$			
6.2A.3.3.1 A-MPR for CA_NS_202 for power class 1			
For intra-band contiguous CA, A-MPR for CA_NS_202 shall be 11.0 dB.			
6.2A.3.3.2 A-MPR for CA_NS_202 for power class 2			
For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.			
6.2A.3.3.3 A-MPR for CA_NS_202 for power class 3			

For intra-band contiguous CA, A-MPR for CA_NS_202 shall be 2.0 dB.

6.2A.3.3.4 A-MPR for CA_NS_202 for power class 4

For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.

6.2A.3.4 A-MPR for CA_NS_203

6.2A.3.4.1 A-MPR for CA_NS_203 for power class 1

For intra-band contiguous CA, A-MPR for CA_NS_203 shall be 6.5 dB, if Offset frequency $< BW_{Channel_CA}$ of the UL CA configuration, 0.0 dB, otherwise

The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the lowest CC among the configured UL CA.

6.2A.3.4.2 A-MPR for CA_NS_203 for power class 2

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.3.4.3 A-MPR for CA_NS_203 for power class 3

For intra-band contiguous CA, A-MPR for CA_NS_203 shall be 2.5 dB, if Offset frequency < BW_{Channel_CA} of the UL CA configuration, 0.0 dB otherwise.

The Offset frequency is defined as the frequency from 24.25 GHz to to the lower edge of the lowest CC among the configured UL CA.

6.2A.3.4.4 A-MPR for CA_NS_203 for power class 4

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.4 Configured transmitted power for CA

A UE configured with carrier aggregation can configure its maximum output power for each uplink activated serving cell c and its total configured maximum output power P_{CMAX} . The definition of the configured UE maximum output power $P_{CMAX,f,c}$ for each carrier f of a serving cell c is used for power headroom reporting for carrier f of serving cell c only and is in accordance with that specified in clause 6.2.4 with parameters MPR, A-MPR and P-MPR replaced with those specified in subclause 6.2A.2, 6.2A.3 and 6.2.4, respectively. The UE maximum configured power P_{CMAX} in a transmission occasion is determined by the UL grants for carrier f of all serving cells c with non-zero granted power in the respective reference point.

For uplink intra-band contiguous carrier aggregation, MPR is specified in clause 6.2A.2. P_{CMAX} is calculated under the assumption that power spectral density for each RB in each component carrier is same.

The configured UE maximum output power P_{CMAX} shall be set such that the corresponding measured total peak EIRP P_{UMAX} is within the following bounds

$$\begin{array}{l} P_{Powerclass} - MAX(MAX(MPR, A-MPR) + \Delta MB_{P,n}, P-MPR) - MAX\{T(MAX(MPR, A-MPR)), T(P-MPR)\} \leq P_{UMAX} \leq EIRP_{max} \end{array}$$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2A.1, EIRP_{max} the applicable maximum EIRP as specified in sub-clause 6.2A.1, MPR as specified in sub-clause 6.2A.2, A-MPR as specified in sub-clause 6.2A.3, $\Delta MB_{P,n}$ the peak EIRP relaxation as specified in clause 6.2.1, P-MPR the power management term for the UE as described in 6.2.4.

The measured configured power P_{UMAX} for carrier aggregation is defined as

$$P_{UMAX} = 10 \log_{10} \sum_{c,f(c)} p_{UMAX,f,c}$$

where $p_{UMAX,f,c}$ is the linear value of the measured power $P_{UMAX,f,c}$ for carrier f=f(c) of serving cell c. The measured total radiated power P_{TMAX} for carrier aggregation is defined as

$$P_{TMAX} = 10 \log_{10} \sum_{c,f(c)} p_{TMAX,f,c}$$

where $p_{TMAX,f,c}$ is the linear value of the measured total radiated power $P_{TMAX,f,c}$ for carrier f = f(c) of serving cell c. The total radiated power P_{TMAX} is bounded by

$$P_{TMAX} \leq TRP_{max}$$

where TRP_{max} the maximum TRP for the UE power class as specified in sub-clause 6.2A.1.

The tolerance T(ΔP) for applicable values of ΔP (values in dB) is specified in Table 6.2A.4-1.

Operating Band	∆ P (dB)	Tolerance T(∆P) (dB)	
n257, n258, n259, n260, n261	$\Delta P = 0$	0	
	0 < ∆P ≤ 2	1.5	
	2 < ∆P ≤ 3	2.0	
	3 < ∆P ≤ 4	3.0	
	4 < ∆P ≤ 5	4.0	
	5 < ∆P ≤ 10	5.0	
	10 < ∆P ≤ 15	7.0	
	15 < ∆P ≤ X	8.0	
NOTE: X is the value	X is the value such that P_{umax} lower bound, $P_{Powerclass}$ - ΔP		
$-T(\Delta P) = m$	$- T(\Delta P) = minimum output power specified in clause$		
6.3A.1			

Table 6.2A.4-1: PUMAX tolerance

6.2D Transmitter power for UL MIMO

6.2D.1 UE maximum output power for UL MIMO

6.2D.1.0 General

The requirements in the following clauses define the maximum output power radiated by the UE with *nrofSRS-Ports* set to 2, for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. MPR shall be applied as specified in clause 6.2D.2

For the maximum output power requirement for 2-layer UL MIMO operation, a UE shall be configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.0-1.

Table 6.2D.1.0-1: UL	MIMO configuration
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Transmission scheme	DCI format	Number of layers	TPMI index
Codebook based uplink	DCI format 0_1	2	0

The maximum output power requirement for single layer transmission shall apply to a UE that supports ULFPTx feature and is configured for single layer transmission in its declared full power mode [10, TS 38.213] as specified in Table 6.2D.1.0-2.

Table 6.2D.1.0-2: PUSCH Configuration for uplink full power transmission (ULFPTx)

ULFPTx Mode	Transmission scheme	DCI format	Modulation	Number of layers	TPMI index
Mode-1	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM ¹	1	2
Mode-2	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM	1	0 or 1 ²
Mode-full	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM	1	0,1
power					
NOTE 1: For PUSCH configured with ULFPTxModes set to Mode-1, all requirements for 1-layer CP-OFDM based modulation in subsection 6.2D are assumed to be met if the requirement for 2-layer UL MIMO has been validated.					
NOTE 2:	E 2: TPMI index selected shall be based upon the full power TPMI reported by the UE [10, TS 38.213].				

6.2D.1.1 UE maximum output power for UL MIMO for power class 1

The following requirements define the maximum output power radiated by the PC1 UE. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.1-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle). Power class 1 UE is used for fixed wireless access (FWA).

Operating band	Min peak EIRP (dBm)
n257	40.0
n258	40.0
n260	38.0
n261	40.0
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance	

Table 6.2D.1.1-2: (void)

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.1-3 below for UE with UL MIMO. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.1-3: UE maximum output power limits for UL MIMO for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE with UL MIMO is defined as the spherical coverage requirement and is found in Table 6.2D.1.1-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.1-4: UE spherical coverage for UL MIMO for power class 1

Operating band	Min EIRP at 85 %-tile CDF (dBm)
n257	32.0
n258	32.0
n260	30.0
n261	32.0
NOTE 1: Minimum E	EIRP at 85 %-tile CDF is defined as
the lower limit without tolerance	

6.2D.1.2 UE maximum output power for UL MIMO for power class 2

The following requirements define the maximum output power radiated by the PC2 UE. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.2-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)
n257	29
n258	29
n261	29
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance.	
NOTE 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.	

 Table 6.2D.1.2-1: UE minimum peak EIRP for UL MIMO for power class 2

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.2-2: UE maximum output power limits for UL MIMO for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

Table 6.2D.1.2-3: (void)

The minimum EIRP at the 60th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.2-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.2-4: UE spherical coverage for UL MIMO for power class 2			
	Operating band	Min EIRP at 60 %-tile CDF (dBm)	

Operating band		
n257	18.0	
n258	18.0	
n261	18.0	
NOTE 1: Minimum EIRP at 60 %-tile CDF is defined as		
the lower limit without tolerance		

6.2D.1.3 UE maximum output power for UL MIMO for power class 3

The following requirements define the maximum output power radiated by the PC3 UE.. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.3-1 below. The period of measurement shall be at least one sub frame (1 ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.3-1: UE minimum peak EIRP for UL MIMO for power class 3

Operating band	Min peak EIRP (dBm)	
n257	22.4	
n258	22.4	
n259	18.7	
n260	20.6	
n261	22.4	
NOTE 1: Minimum peak El tolerance.	: Minimum peak EIRP is defined as the lower limit without tolerance.	
NOTE 2: Min Peak EIRP re peaks.	E 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.	

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.3-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.3-2: UE maximum output power limits for UL MIMO for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43
n260	23	43
n261	23	43

Table 6.2D.1.3-3: (void)

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.3-4 below. The requirement is verified with the test metric of EIRP (Link=spherical coverage grid, Meas=Link angle).

Operating band	Min EIRP at 50 %-tile CDF (dBm)
n257	11.5
n258	11.5
n259	5.8
n260	8
n261	11.5
NOTE 1: Minimum EIRP at 50 %-tile CDF is defined as the lower limit	
without tolerance	
NOTE 2: The requirements in this table are only applicable for UE which	

Table 6.2D.1.3-4: UE spherical coverage for UL MIMO for power class 3

6.2D.1.4 UE maximum output power for UL MIMO for power class 4

supports single band in FR2

The following requirements define the maximum output power radiated by the PC4 UE. Requirements apply to UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.4-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Min peak EIRP (dBm)
n257	34
n258	34
n260	31
n261	34
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance.	
NOTE 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.	

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

 Table 6.2D.1.4-2: UE maximum output power limits for UL MIMO for power class 4

Table 6.2D.1.4-3: (void)

The minimum EIRP at the 20th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.4-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.4-4: UE spherical coverage for UL MIMO for power class 4

Operating band	Min EIRP at 20 %-tile CDF (dBm)	
n257	25	
n258	25	
n260	19	
n261 25		
NOTE 1: Minimum E	NOTE 1: Minimum EIRP at 20 %-tile CDF is defined as	
the lower limit without tolerance		

6.2D.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO

6.2D.2.1 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 1

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.1-1 is specified in sub-clause 6.2.2.1. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 2

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.2-1 is specified in sub-clause 6.2.2.2. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.3 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 3

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.3-1 is specified in sub-clause 6.2.2.3. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.4 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 4

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.4-1 is specified in sub-clause 6.2.2.4. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3 UE maximum output power reduction with additional requirements for UL MIMO

6.2D.3.1 UE maximum output power reduction with additional requirements for UL MIMO for power class 1

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.1-1. The requirements shall be met with the configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.2 UE maximum output power reduction with additional requirements for UL MIMO for power class 2

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.2-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.3 UE maximum output power reduction with additional requirements for UL MIMO for power class 3

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.3-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.4 UE maximum output power reduction with additional requirements for UL MIMO for power class 4

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.4-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

6.2D.4 Configured transmitted power for UL MIMO

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the configured maximum output power $P_{CMAX,c}$ for serving cell *c* is defined as sum of all streams and is bound by limits set in clause 6.2.4.

6.3 Output power dynamics

6.3.1 Minimum output power

6.3.1.0 General

The minimum controlled output power of the UE is defined as the EIRP in the channel bandwidth for all transmit bandwidth configurations (resource blocks) when the power is set to a minimum value.

The minimum output power is defined as the mean power in at least one sub frame (1ms).

6.3.1.1 Minimum output power for power class 1

For power class 1 UE, the minimum output power shall not exceed the values specified in Table 6.3.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	4	47.58
	100	4	95.16
	200	4	190.20
	400	4	380.28

6.3.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n259, n260, n261	50	-13	47.58
	100	-13	95.16
	200	-13	190.20
	400	-13	380.28
NOTE 1: n260 is not applied for power class 2.			
NOTE 2: n259 is not applied for power class 2 and 4.			

6.3.2 Transmit OFF power

The transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports.

The transmit OFF power shall not exceed the values specified in Table 6.3.2-1 for each operating band supported. The requirement is verified with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n259, n260, n261	-35	-35	-35	-35
	47.58 MHz	95.16 MHz	190.20 MHz	380.28 MHz

Table 6.3.2-1: Transmit OFF power

6.3.3 Transmit ON/OFF time mask

6.3.3.1 General

The transmit ON/OFF time mask defines the transient period(s) allowed

- between transmit OFF power and transmit ON power symbols (transmit ON/OFF)
- between continuous ON-power transmissions when power change or RB hopping is applied.

In case of RB hopping, transition period is shared symmetrically.

Unless otherwise stated the minimum requirements in clause 6.5 apply also in transient periods.

The transmit ON/OFF time mask is defined as a directional requirement. The requirement is verified in beam locked mode at beam peak direction. The maximum allowed EIRP OFF power level is -30dBm at beam peak direction. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

In the following sub-clauses, following definitions apply:

- A slot transmission is a Type A transmission.
- A long subslot transmission is a Type B transmission with more than 2 symbols.
- A short subslot transmission is a Type B transmission with 1 or 2 symbols.

6.3.3.2 General ON/OFF time mask

The general ON/OFF time mask defines the observation period allowed between transmit OFF and ON power. ON/OFF scenarios include: contiguous, and non-contiguous transmission, etc

The OFF power measurement period is defined in a duration of at least one slot excluding any transient periods. The ON power is defined as the mean power over one slot excluding any transient period.



Figure 6.3.3.2-1: General ON/OFF time mask for NR UL transmission in FR2

6.3.3.3 Transmit power time mask for slot and short or long subslot boundaries

The transmit power time mask for slot and a long subslot transmission boundaries defines the transient periods allowed between slot and long subslot PUSCH transmissions. For PUSCH-PUCCH and PUSCH-SRS transitions and multiplexing the time masks in sub-clause 6.3.3.7 apply.

The transmit power time mask for slot or long subslot and short subslot transmission boundaries defines the transient periods allowed between slot or long subslot and short subslot transmissions. The time masks in sub-clause 6.3.3.8 apply.

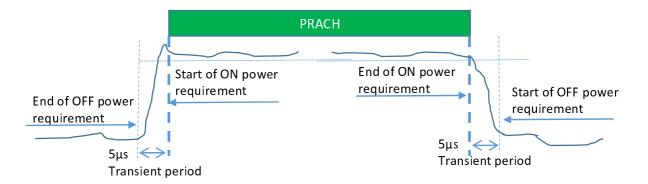
The transmit power time mask for short subslot transmissiona boundaries defines the transient periods allowed between short subslot transmissions. The time masks in sub-clause 6.3.3.9 apply.

6.3.3.4 PRACH time mask

The PRACH ON power is specified as the mean power over the PRACH measurement period excluding any transient periods as shown in Figure 6.3.3.4-1. The measurement period for different PRACH preamble format is specified in Table 6.3.3.4-1.

Format	SCS	Measurement period
A ₁	60 kHz	0.035677 ms
	120 kHz	0.017839 ms
A ₂	60 kHz	0.071354 ms
	120 kHz	0.035677 ms
A ₃	60 kHz	0.107031 ms
	120 kHz	0.053516 ms
B ₁	60 kHz	0.035091 ms
	120 kHz	0.0175455 ms
B4	60 kHz	0.207617 ms
	120 kHz	0.103809 ms
A ₁ /B ₁	60 kHz	0.035677 ms for front X1 occasion
		0.035091 ms for last occasion
		X1 = [2,5]
	120 kHz	0.017839 ms for front X1occasion
		0.017546 ms for last occasion
		X1 = [2,5]
A ₂ /B ₂	60 kHz	0.071354 ms for front X2 occasion
		0.069596 ms for last occasion
		X2 = [1,2]
	120 kHz	0.035677 ms for front X2 occasion
		0.034798 ms for last occasion
		X2 = [1,2]
A ₃ /B ₃	60 kHz	0.107031 ms for first occasion
	100 111	0.104101 ms for second occasion
	120 kHz	0.053515 ms for first occasion
	00.111-	0.052050 ms for second occasion
C ₀	60 kHz	0.026758 ms
	120 kHz	0.013379 ms
C2	60 kHz	0.083333 ms
	120 kHz	0.0416667 ms
		on PRACH occasion start from begin of 0ms or 0.5 ms boundary,
t	ne measurer	nent period will plus 0.032552 µs

Table 6.3.3.4-1: PRACH ON power measurement period





6.3.3.5 Void

6.3.3.6 SRS time mask

In the case a single SRS transmission, the ON power is defined as the mean power over the symbol duration excluding any transient period; Figure 6.3.3.6-1.

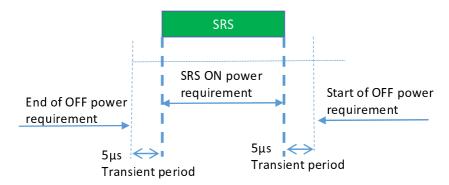


Figure 6.3.3.6-1: Single SRS time mask for NR UL transmission

In the case multiple consecutive SRS transmission, the ON power is defined as the mean power for each symbol duration excluding any transient period. See Figure 7.7.4-2

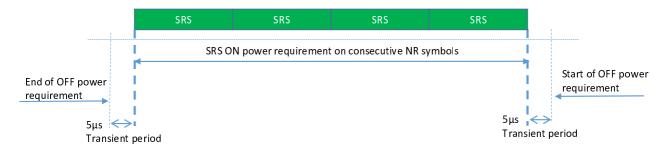


Figure 6.3.3.6-2: Consecutive SRS time mask for the case when no power change is required

When power change between consecutive SRS transmissions is required, then Figure 6.3.3.6-3 and Figure 6.3.3.6-4 apply.

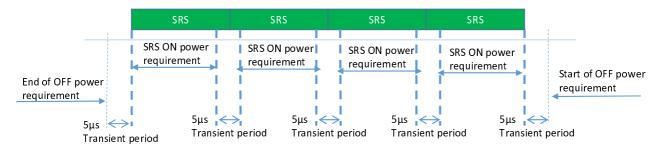


Figure 6.3.3.6-3: Consecutive SRS time mask for the case when power change is required and when 60kHz SCS is used in FR2

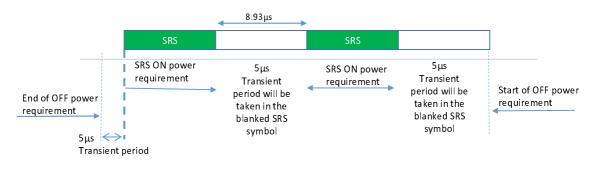


Figure 6.3.3.6-4: Consecutive SRS time mask for the case when power change is required and when 120kHz SCS is used in FR2

6.3.3.7 PUSCH-PUCCH and PUSCH-SRS time masks

The PUCCH/PUSCH/SRS time mask defines the observation period between sounding reference symbol (SRS) and an adjacent PUSCH/PUCCH symbol and subsequent UL transmissions. The time masks apply for all types of frame structures and their allowed PUCCH/PUSCH/SRS transmissions unless otherwise stated.

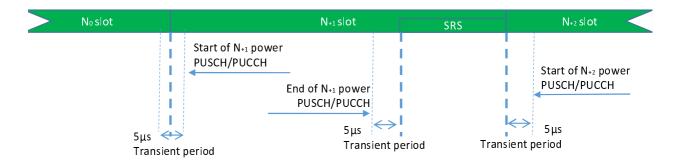


Figure 6.3.3.7-1: PUCCH/PUSCH/SRS time mask when there is a transmission before or after or both before and after SRS

When there is no transmission preceding SRS transmission or succeeding SRS transmission, then the same time mask applies as shown in Figure 6.3.3.7-1.

6.3.3.8 Transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries

The transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries defines the transient periods allowed between such transmissions.

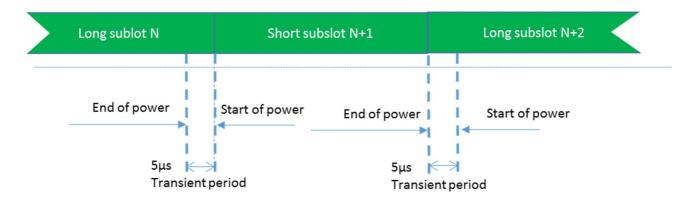


Figure 6.3.3.8-1: Consecutive slot or long subslot transmission and short subslot transmission time mask

6.3.3.9 Transmit power time mask for consecutive short subslot transmissions boundaries

The transmit power time mask for consecutive short subslot transmission boundaries defines the transient periods allowed between short subslot transmissions.

The transient period shall be equally shared as shown on Figure 6.3.3.9-2.

Figure 6.3.3.9-1: Void

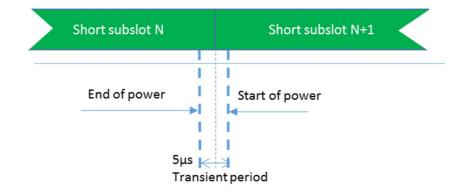


Figure 6.3.3.9-2: Consecutive short subslot transmissions time mask where DMRS is not the first symbol in the adjacent short subslot transmission

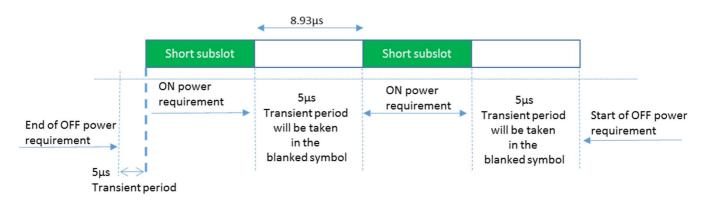


Figure 6.3.3.9-3: Consecutive short subslot (1 symbol gap) time mask for the case when transient period is required on both sides of the symbol and when 120 kHz SCS is used in FR2

6.3.4 Power control

6.3.4.1 General

The requirements on power control accuracy apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction.

6.3.4.2 Absolute power tolerance

The absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame (1 ms) at the start of a contiguous transmission or non-contiguous transmission with a transmission gap larger than 20 ms. The tolerance includes the channel estimation error RSRP estimate.

The minimum requirements specified in Table 6.3.4.2-1 apply in the power range bounded by the minimum output power as specified in sub-clause 6.3.1 ($'P_{min}'$) and the maximum output power as specified in sub-clause 6.2.1 as minimum peak EIRP ($'P_{max}'$). The intermediate power point ' P_{int}' is defined in table 6.3.4.2-2

Power Range	Tolerance
$P_{int} \ge P \ge P_{min}$	± 14.0 dB
P _{max} ≥ P > P _{int}	± 12.0 dB

Table 6.3.4.2-1: Absolute power tolerance

Table 6.3.4.2-2: Intermediate power point

Power Parameter	Value
Pint	P _{max} – 12.0 dB

6.3.4.3 Relative power tolerance

The relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame (1 ms) relatively to the power of the most recently transmitted reference sub-frame (1 ms) if the transmission gap between these sub-frames is less than or equal to 20 ms.

The minimum requirements specified in Table 6.3.4.3-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and Pint as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.3-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the measured P_{UMAX} as defined in sub-clause 6.2.4.

For a test pattern that is either a monotonically increasing or monotonically decreasing power sweep over the range specified for Tables 6.3.4.3-1 and 6.3.4.3-2, 3 exceptions are allowed for each of the test patterns. For these exceptions, the power tolerance limit is a maximum of ± 11.0 dB.

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between sub- frames, PRACH (dB)
ΔΡ < 2	±5.0
2 ≤ ΔP < 3	±6.0
3 ≤ ΔP < 4	±7.0
4 ≤ ΔP < 10	±8.0
10 ≤ ΔP < 15	±10.0
15 ≤ ΔP	±11.0
NOTE: The requirements apply with <i>ue-BeamLockFunction</i> enabled.	

Table 6.3.4.3-1: Relative power tolerance, $P_{int} \ge P \ge P_{min}$

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between sub- frames, PRACH (dB)	
ΔP < 2	± 3.0	
2 ≤ ΔP < 3	± 4.0	
3 ≤ ΔP < 4	± 5.0	
4 ≤ ΔP < 10	± 6.0	
10 ≤ ∆P < 15	± 8.0	
15 ≤ ∆P	± 9.0	
BeamLockF NOTE 2: For PUSCH allocated res no transmiss generated b periods: for	 The requirements apply with <i>ue-BeamLockFunction</i> enabled. For PUSCH to PUSCH transitions with the allocated resource blocks fixed in frequency and no transmission gaps other than those generated by downlink subframes, guard periods: for a power step ΔP = 1 dB, the relative power tolerance for transmission is ± 1.0 dB. 	

Table 6.3.4.3-2: Relative power tolerance, $P_{UMAX} \ge P > P_{int}$

6.3.4.4 Aggregate power tolerance

The aggregate power control tolerance is the ability of the UE transmitter to maintain its power in a sub-frame (1 ms) during non-contiguous transmissions within 21ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in 38.213 kept constant.

The minimum requirements specified in Table 6.3.4.4-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and P_{int} as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.4-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the maximum output power as specified in sub-clause 6.2.1.

Table 6.3.4.4-1:	Aggregate p	power tolerance,	Pint	2 P 2	\mathbf{P}_{min}
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TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± 5.5 dB
0 dB	PUSCH	± 5.5 dB

TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± 3.5 dB
0 dB	PUSCH	± 3.5 dB

6.3A Output power dynamics for CA

6.3A.1 Minimum output power for CA

Table 6.3A.1-1: Void

6.3A.1.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the minimum controlled output power of the UE is defined as the transmit power of the UE per component carrier, i.e., EIRP in the channel bandwidth of each component carrier for all transmit bandwidth configurations (resource blocks), when the power on both component carriers are set to a minimum value.

The minimum output power is defined as the mean power in at least one sub frame (1ms).

6.3A.1.1 Minimum output power for power class 1

The minimum output power shall not exceed the values specified in Table 6.3A.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	4	47.58
	100	4	95.16
	200	4	190.20
	400	4	380.28

Table 6.3A.1.1-1: Minimum output power for power class 1

6.3A.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3A.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3A.1.2-1: Minimum output power for CA for power class 2, 3, and 4

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n259, n260, n261	50	-13	47.58
Γ	100	-13	95.16
Γ	200	-13	190.20
	400	-13	380.28
NOTE 1: n260 is not appli			
NOTE 2: n259 is not appli	ed for power class 2 and 4.		

6.3A.2 Transmit OFF power for CA

For intra-band contiguous and non-contiguous carrier aggregation, the transmit OFF power is defined as the TRP in the channel bandwidth per component carrier when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of it sports.

The transmit OFF power shall not exceed the values specified in Table 6.3A.2-1 for each operating band supported.

Table 6.3A.2-1: Transmit OFF power for CA

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n259, n260, n261	-35	-35	-35	-35
	47.58 MHz	95.16 MHz	190.20 MHz	380.28 MHz

6.3A.3 Transmit ON/OFF time mask for CA

For intra-band contiguous and non-contiguous UL carrier aggregation, the general output power ON/OFF time mask specified in clause 6.3.3.2 is applicable for each component carrier during the ON power period and the transient periods. The OFF period as specified in clause 6.3.3.2 shall only be applicable for each component carrier when all the component carriers are OFF.

6.3A.4 Power control for CA

6.3A.4.1 General

The requirements in this clause apply to a UE when it has at least one of UL or DL configured for CA operation. The requirements on power control accuracy in CA operation apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction. The requirements apply for one single PUCCH, PUSCH or SRS transmission of contiguous PRB allocation per configured UL CC with power setting in accordance with Clause 7.1 of [10]

6.3A.4.2 Absolute power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission gap on each active component carriers larger than 20 ms. For SRS switching, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission or non-contiguous transmission with a transmission or non-contiguous transmission with a transmission gap on component carriers (to which SRS switching occurs) larger than 20 ms. The requirement can be tested by time aligning any transmission gaps on the component carriers. For intra-band contiguous CA, the absolute power control tolerance per configured UL CC is given in Tables 6.3.4.2-1 and 6.3.4.2-2.

6.3A.4.3 Relative power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame relative to the power of the most recently transmitted reference sub-frame if the transmission gap between these sub-frames is less than or equal to 20ms.

For intra-band contiguous CA, the requirements apply when the power of the target and reference sub-frames on each component carrier exceed the minimum output power as defined in clause 6.3A.1 and the total power is limited by P_{UMAX} as defined in clause 6.2A.4. For the purpose of these requirements, the power in each component carrier is specified over only the transmitted resource blocks. The UE shall meet the requirements in tables 6.3.4.3-1 and 6.3.4.3-2 for transmission on each assigned component carrier, when the average PSDs over each CC are aligned with each other in the reference sub-frame. The requirements apply per component carrier to:

- a. All possible combinations of PUSCH and PUCCH transitions
- b. SRS and PUSCH/PUCCH transitions, only with simultaneous SRS of constant SRS bandwidth allocated in the target and reference subrames
- c. RACH, primary component carrier

When applicable, the power step ΔP between the reference and target subframes shall be set by a TPC command and/or an uplink scheduling grant transmitted by means of an appropriate DCI Format.

6.3A.4.4 Aggregate power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the aggregate power control tolerance is the ability of the UE transmitter to maintain its power during non-contiguous transmissions within 21 ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in [10] kept constant.

For intra-band contiguous CA, the aggregate power tolerance per CC is given in Tables 6.3.4.4.1-1 and 6.3.4.4.1-2, with simultaneous PUSCH configured. The average PSDs over each assigned CC shall be aligned before the start of the test. The requirement can be tested with the transmission gaps time aligned between component carriers.

6.3D Output power dynamics for UL MIMO

6.3D.0 General

The requirements in subclause 6.3D shall be met with configurations specified in sub-clause 6.2D.1.x, where 'x' depends on power class. Unless otherwise specified, the requirements shall be verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

6.3D.1 Minimum output power for UL MIMO

6.3D.1.0 General

The minimum output power is defined as the mean power in at least one sub frame (1ms). The minimum controlled output power is defined as the EIRP, i.e. the sum of the power in the channel bandwidth for all transmit bandwidth configurations (resource blocks), when the UE power is set to a minimum value.

6.3D.1.1 Minimum output power for UL MIMO for power class 1

For UE supporting UL MIMO, the minimum output power shall not exceed the sum of the values specified in Table 6.3.1.1-1 and the quantity 10*log₁₀(Number of Layers). The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

6.3D.1.2 Minimum output power for UL MIMO for power class 2, 3 and 4

For UE supporting UL MIMO, the minimum output power shall not exceed the sum of the values specified in Table 6.3.1.2-1 and the quantity 10*log₁₀(Number of Layers).

6.3D.2 Transmit OFF power for UL MIMO

For UE supporting UL MIMO, the transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports. During DTX and measurements gaps, the transmitter is not considered OFF. The minimum output power shall not exceed the values specified in Table 6.3.2-1. The requirement is verified with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

6.3D.3 Transmit ON/OFF time mask for UL MIMO

For UE supporting UL MIMO, the ON/OFF time mask requirements in clause 6.3.3 apply.

6.4 Transmit signal quality

6.4.1 Frequency Error

The UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequency shall be accurate to within \pm 0.1 PPM observed over a period of 1 msec of cumulated measurement intervals compared to the carrier frequency received from the NR gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of Frequency (Link=TX beam peak direction, Meas=Link angle).

6.4.2 Transmit modulation quality

6.4.2.0 General

Transmit modulation quality defines the modulation quality for expected in-channel RF transmissions from the UE. The transmit modulation quality is specified in terms of:

- Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)
- EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process
- Carrier leakage
- In-band emissions for the non-allocated RB

All the parameters defined in clause 6.4.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with parameter *maxRank* (as defined in TS 38.331 [13]) set to 1. The requirements are applicable to UL transmission from each configurable antenna port (as defined in TS 38.331 [13]) of UE, enabled one at a time.

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrentList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4.2.2 and 6.4.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

6.4.2.1 Error vector magnitude

The Error Vector Magnitude is a measure of the difference between the reference waveform and the measured waveform. This difference is called the error vector. Before calculating the EVM, the measured waveform is corrected by the sample timing offset and RF frequency offset. Then the carrier leakage shall be removed from the measured waveform before calculating the EVM.

The measured waveform is further equalised using the channel estimates subjected to the EVM equaliser spectrum flatness requirement specified in sub-clauses 6.4.2.4 and 6.4.2.5. For DFT-s-OFDM waveforms, the EVM result is defined after the front-end FFT and IDFT as the square root of the ratio of the mean error vector power to the mean reference power expressed as a %. For CP-OFDM waveforms, the EVM result is defined after the front-end FFT as the square root of the mean reference power expressed as a %.

The basic EVM measurement interval in the time domain is one preamble sequence for the PRACH and one slot for PUCCH and PUSCH in the time domain. The EVM measurement interval is reduced by any symbols that contains an allowable power transient in the measurement interval as as defined in clause 6.3.3.

The RMS average of the basic EVM measurements over 10 subframes for the average EVM case, and over 60 subframes for the reference signal EVM case, for the different modulation schemes shall not exceed the values specified in Table 6.4.2.1-1 for the parameters defined in Table 6.4.2.1-2 or 6.4.2.1-3, depending on UE power class. For EVM evaluation purposes, all 13 PRACH preamble formats and all 5 PUCCH formats are considered to have the same EVM requirement as QPSK modulated.

The requirement is verified with the test metric of EVM (Link=TX beam peak direction, Meas=Link angle).

Parameter	Unit	Average EVM level	Reference signal EVM level
Pi/2 BPSK	%	30.0	30.0
QPSK	%	17.5	17.5
16 QAM	%	12.5	12.5
64 QAM	%	8.0	8.0

Parameter	Unit	Level
UE EIRP	dBm	≥ 4
UE EIRP for UL 16 QAM	dBm	≥7
UE EIRP for UL 64 QAM	dBm	≥11
Operating conditions		Normal conditions

Parameter	Unit	Level
UE EIRP	dBm	≥ -13
UE EIRP for UL 16 QAM	dBm	≥ -10
UE EIRP for UL 64 QAM	dBm	≥ -6
Operating conditions		Normal conditions

Table 6.4.2.1-3: Parameters for Error Vector Magnitude for power class 2, 3, and 4

6.4.2.2 Carrier leakage

6.4.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier. The measurement interval is one slot in the time domain. The relative carrier leakage power is a power ratio of the additive sinusoid waveform to the power in the modulated waveform.

The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

6.4.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum confined within the configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.2-1 for power class 1 UEs.

Table 6.4.2.2.2-1: Minimum requirements for relative carrier leakage power for power class 1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

6.4.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.3-1 for power class 2.

Table 6.4.2.2.3-1: Minimum requirements for relative carrier leakage power for power class 2

Parameters	Relative Limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

6.4.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.4-1 for power class 3 UEs.

Table 6.4.2.2.4-1: Minimum requirements for relative carrier leakage power for power class 3

Parameters	Relative Limit (dBc)
EIRP > 0 dBm	-25
-13 dBm ≤ EIRP ≤ 0 dBm	-20

6.4.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.5-1 for power class 4.

Table 6.4.2.2.5-1: Minimum requirements for relative carrier leakage power for power class 4

Parameters	Relative Limit (dBc)
EIRP > 11 dBm	-25
-13 dBm ≤ EIRP ≤ 11 dBm	-20

6.4.2.3 In-band emissions

6.4.2.3.1 General

The in-band emission is defined as the average across 12 sub-carriers and as a function of the RB offset from the edge of the allocated UL transmission bandwidth. The in-band emission is measured as the ratio of the UE output power in a non–allocated RB to the UE output power in an allocated RB. The IBE requirement does not apply if UE declares support for *mpr-PowerBoost-FR2-r16*, UL transmission is QPSK,MPR_{f,c} = 0 and when NS_200 applies, and the network configures the UE to operate with *mpr-PowerBoost-FR2-r16*.

The basic in-band emissions measurement interval is identical to that of the EVM test.

The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

6.4.2.3.2 In-band emissions for power class 1

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.2-1 for power class 1 UEs.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 27 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 27 dBm	
Carrier leakage	dBc	-25	Output power > 17 dBm	Carrier frequency (NOTES 4, 5)
		-20	4 dBm ≤ Output power ≤ 17 dBm	

Table 6.4.2.3.2-1: Requirements for in-band emissions for power class 1

NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. \overline{P}_{RB} is defined in NOTE 10. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit depend on the parameter txDirectCurrentLocation in UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3). NOTE 7: N_{RB} is the Transmission Bandwidth Configuration (see Clause 5.3). NOTE 8: EVM s the limit for the modulation format used in the allocated RBs. NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth). NOTE 10: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm. NOTE 11: All powers are EIRP in beam peak direction.

6.4.2.3.3 In-band emissions for power class 2

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.3-1 for power class 2.

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description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 16 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 16 dBm	
Carrier leakage	dBc	-25	Output power > 6 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 6 dBm	
NOTE 1: An	in-ban	d emissions combined	limit is evaluated in each non-allocated RB. For each such	RB, the minimum
			pply. P_{RB} is defined in NOTE 10.	
RE Pi/ the NOTE 3: Th ba NOTE 4: Th RE NOTE 5: Th <i>Up</i> an	B to the 2 BPSP e measure applie sed on e measure applie to the e applie blinkTxL y alloca	measured average pow (with Spectrum Shapin ured power in the alloca cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the DirectCurrent IE, and ar ted RB.	is limit depend on the parameter <i>txDirectCurrentLocation</i> in the those that are enclosed in the RBs containing the DC free	Ill allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated
RE Pi/ NOTE 3: Th ba NOTE 4: Th RE NOTE 5: Th <i>Up</i> an NOTE 6: L _C	B to the 2 BPSH e measure applie sed on the measure to the e applie blinkTxL y alloca RB is the	measured average pow with Spectrum Shapir ured power in the allocat cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the DirectCurrent IE, and ar ted RB. Transmission Bandwi	wer per allocated RB, where the averaging is done across a ng, the limit is expressed as a ratio of measured power in or ated RB with highest PSD is limit are those that are enclosed in the reflection of the all to the carrier frequency, but excluding any allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in the those that are enclosed in the RBs containing the DC free dth (see Clause 5.3).	Ill allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated
RE Pi/ NOTE 3: Th ba NOTE 4: Th RE NOTE 5: Th <i>Up</i> an NOTE 6: L _C NOTE 7: N _R	3 to the 2 BPSk e measure sed on e measure 3 to the e applic blinkTxL y alloca RB is the B is the	measured average power with Spectrum Shapin ured power in the allocate cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the DirectCurrent IE, and ar ted RB. Transmission Bandwidt	wer per allocated RB, where the averaging is done across a ng, the limit is expressed as a ratio of measured power in or ated RB with highest PSD is limit are those that are enclosed in the reflection of the all to the carrier frequency, but excluding any allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in re those that are enclosed in the RBs containing the DC free dth (see Clause 5.3). dth Configuration (see Clause 5.3).	all allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated
RE Pi/ the NOTE 3: Th ba NOTE 4: Th RE NOTE 5: Th <i>Up</i> an NOTE 6: L _C NOTE 7: N _R NOTE 8: EV	3 to the 2 BPSk e measure sed on e measure 3 to the e applic blinkTxL y alloca RB is the B is the M s the	measured average power with Spectrum Shapin ured power in the allocation cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the <i>DirectCurrent</i> IE, and an uted RB. Transmission Bandwice ilimit for the modulatio	wer per allocated RB, where the averaging is done across a ng, the limit is expressed as a ratio of measured power in or ated RB with highest PSD is limit are those that are enclosed in the reflection of the all to the carrier frequency, but excluding any allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in re those that are enclosed in the RBs containing the DC free dth (see Clause 5.3). th Configuration (see Clause 5.3). n format used in the allocated RBs.	all allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated quency but excluding
RE Pi/ the NOTE 3: Th ba NOTE 4: Th RE NOTE 5: Th <i>Up</i> an NOTE 6: L _C NOTE 7: N _R NOTE 8: EV NOTE 9: Δ _R	B to the 2 BPSF e measure applie sed on e measure to the e applie blinkTxL y alloca _{RB} is the _B is the _B is the B is the	measured average pow with Spectrum Shapin ured power in the alloca cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the DirectCurrent IE, and an ated RB. Transmission Bandwid Transmission Bandwid e limit for the modulatio starting frequency offs	wer per allocated RB, where the averaging is done across a ng, the limit is expressed as a ratio of measured power in or ated RB with highest PSD is limit are those that are enclosed in the reflection of the all to the carrier frequency, but excluding any allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in the those that are enclosed in the RBs containing the DC free dth (see Clause 5.3). dth Configuration (see Clause 5.3). n format used in the allocated RBs. et between the allocated RB and the measured non-allocated is solved.	all allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated quency but excluding
$\begin{array}{c} RE\\ Pi_{\mathcal{U}}\\ the\\ NOTE 3: & Th\\ ba\\ NOTE 4: & Th\\ RE\\ NOTE 5: & Th\\ \mathcal{U}_{\mathcal{U}}\\ an\\ NOTE 5: & L_{C}\\ NOTE 7: & N_{R}\\ NOTE 9: & \Delta_{R}\\ \Delta_{R} \end{array}$	3 to the (2 BPS) (2	measured average power with Spectrum Shapin ured power in the allocate cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the <i>DirectCurrent</i> IE, and an anted RB. Transmission Bandwidth Transmission Bandwidth is the modulation starting frequency offs or the first adjacent RB	wer per allocated RB, where the averaging is done across a ng, the limit is expressed as a ratio of measured power in or ated RB with highest PSD is limit are those that are enclosed in the reflection of the all to the carrier frequency, but excluding any allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in re those that are enclosed in the RBs containing the DC free dth (see Clause 5.3). dth Configuration (see Clause 5.3). n format used in the allocated RBs. et between the allocated RB and the measured non-allocated outside of the allocated bandwidth).	all allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated quency but excluding ed RB (e.g. $\Delta_{RB} = 1$ or
$\begin{array}{c} RE\\ Pi_{\mathcal{U}}\\ the\\ NOTE 3: & Th\\ ba\\ NOTE 4: & Th\\ RE\\ NOTE 5: & Th\\ \mathcal{U}_{\mathcal{U}}\\ an\\ NOTE 5: & L_{C}\\ NOTE 7: & N_{R}\\ NOTE 9: & \Delta_{R}\\ \Delta_{R} \end{array}$	3 to the (2 BPS) (2	measured average power with Spectrum Shapin ured power in the allocate cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the <i>DirectCurrent</i> IE, and an anted RB. Transmission Bandwidth Transmission Bandwidth is the modulation starting frequency offs or the first adjacent RB	wer per allocated RB, where the averaging is done across a ng, the limit is expressed as a ratio of measured power in or ated RB with highest PSD is limit are those that are enclosed in the reflection of the all to the carrier frequency, but excluding any allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in the those that are enclosed in the RBs containing the DC free dth (see Clause 5.3). dth Configuration (see Clause 5.3). n format used in the allocated RBs. et between the allocated RB and the measured non-allocated is solved.	all allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocated quency but excluding ed RB (e.g. $\Delta_{RB} = 1$ or
NOTE 3: Th ba NOTE 3: Th ba NOTE 4: Th RE NOTE 5: Th U_{μ} an NOTE 6: L _c NOTE 7: N _R NOTE 7: N _R NOTE 9: Δ_{R} NOTE 9: Δ_{R} NOTE 10: \overline{P}	B to the (2 BPSF) (2 BPSF)	measured average power with Spectrum Shapin ured power in the allocate cable frequencies for the symmetry with respect urement bandwidth is measured total power cable frequencies for the <i>DirectCurrent</i> IE, and an anted RB. Transmission Bandwidth Transmission Bandwidth is the modulation starting frequency offs or the first adjacent RB	wer per allocated RB, where the averaging is done across a hig, the limit is expressed as a ratio of measured power in or ated RB with highest PSD are in the reflection of the allocated RB with highest PSD are in all allocated regulations of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit is expressed as a ratio of measured power in all allocated RBs. 1 RB and the limit depend on the parameter <i>txDirectCurrentLocation</i> in the those that are enclosed in the RBs containing the DC free of the allocated S. 1 RB and the allocated RBs. 1 RB and the allocated RBs. 1 RB and the allocated RB and the measured non-allocated outside of the allocated bandwidth). 1 mitted power over 10 sub-frames normalized by the number and the number of the allocated RB and the measured by the number of the allocated RB and the measured by the number of the allocated RB and the measured by the number of the allocated RB and the measured by the number of the allocated RB and the measured by the number of the allocated RB and the reflexible to the number of the allocated RB and the reflexible to the number of the allocated RB and the reflexible to the number of the allocated RB and the reflexible to the number of the allocated RB and the reflexible to the number of the allocated RB and the reflexible to the number of the reflexible to the the theorem of the the theorem of theorem of the theorem of the	all allocated RBs. For the non-allocated RB to llocated bandwidth, er in one non-allocate quency but excluding ed RB (e.g. $\Delta_{RB} = 1$ or

Table 6.4.2.3.3-1: Requirements for in-band emissions for power class 2

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6.4.2.3.4 In-band emissions for power class 3

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.4-1 for power class 3 UEs.

description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB	ma	$ax \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}}, \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 10 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 10 dBm	
Carrier leakage	dBc	-25	Output power > 0 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 0 dBm limit is evaluated in each non-allocated RB. For each s	
NOTE 2: Th RE Pi/ the	e meas 3 to the 2 BPSk e measu e applic	urement bandwidth is 1 measured average pov (with Spectrum Shapin ured power in the alloca cable frequencies for th	pply. P_{RB} is defined in NOTE 10. I RB and the limit is expressed as a ratio of measured ver per allocated RB, where the averaging is done acro ing, the limit is expressed as a ratio of measured power ated RB with highest PSD is limit are those that are enclosed in the reflection of t	oss all allocated RBs. For in one non-allocated RB to
NOTE 4: Th RE NOTE 5: Th	e meas 8 to the e applic	urement bandwidth is 1 measured total power i cable frequencies for th	to the carrier frequency, but excluding any allocated R I RB and the limit is expressed as a ratio of measured n all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocat</i> e those that are enclosed in the RBs containing the D0	Bs. power in one non-allocated <i>ion</i> in
NOTE 4: Th RE NOTE 5: Th Up an NOTE 6: L _{CI}	e meas to the e applic <i>linkTxE</i> y alloca _{RB} is the	urement bandwidth is 1 measured total power i cable frequencies for th DirectCurrent IE, and an ted RB. Pransmission Bandwid	I RB and the limit is expressed as a ratio of measured n all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocat</i> e those that are enclosed in the RBs containing the D0 dth (see Clause 5.3).	Bs. power in one non-allocated <i>ion</i> in
NOTE 4: Th RE NOTE 5: Th $U\mu$ an NOTE 6: L _{CI} NOTE 7: N _R NOTE 8: EV NOTE 9: Δ_{R}	e meas B to the e applic dinkTxL y alloca RB is the B is the M s the B is the	urement bandwidth is 1 measured total power i cable frequencies for th <i>DirectCurrent</i> IE, and ar- ted RB. Transmission Bandwid Transmission Bandwid limit for the modulation starting frequency offse	RB and the limit is expressed as a ratio of measured n all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocat</i> e those that are enclosed in the RBs containing the D0	Bs. power in one non-allocated <i>ion</i> in C frequency but excluding

Table 6.4.2.3.4-1: Requirements for in-band emissions for power class 3

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6.4.2.3.5 In-band emissions for power class 4

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.5-1 for power class 4 UEs.

Parameter description	Unit	Limit (NOTE 1)		Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 21 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 21 dBm	
Carrier leakage	dBc	-25	Output power > 11 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 11 dBm	
NOTE 1: A	n in-ban	d emissions combined l	imit is evaluated in each non-allocated RB. For each such	RB, the minimum
NOTE 2: TI R P th NOTE 3: TI bi NOTE 4: TI R	he meas B to the i/2 BPSI he meas he applie ased on he meas B to the	surement bandwidth is 1 measured average pow 4 with Spectrum Shapin ured power in the alloca cable frequencies for thi symmetry with respect surement bandwidth is 1 measured total power i	ply. \overline{P}_{RB} is defined in NOTE 10. RB and the limit is expressed as a ratio of measured power ver per allocated RB, where the averaging is done across a ig, the limit is expressed as a ratio of measured power in or ited RB with highest PSD is limit are those that are enclosed in the reflection of the al to the carrier frequency, but excluding any allocated RBs. RB and the limit is expressed as a ratio of measured power n all allocated RBs. is limit depend on the parameter <i>txDirectCurrentLocation</i> in	Il allocated RBs. For he non-allocated RB to located bandwidth, er in one non-allocated
U	UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.			
		Transmission Bandwid		
			th Configuration (see Clause 5.3).	
	NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.			
	NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth).			ed RB (e.g. $\Delta_{RB} = 1$ or
				r of allocated RBs.
	NOTE 10: P _{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.			
NOTE 11: A	ll powers	s are EIRP in beam pea	k direction.	

Table 6.4.2.3.5-1: Requirements for in-band emissions for power class 4

6.4.2.4 EVM equalizer spectrum flatness

The EVM measurement process (as described in Annex F) entails generation of a zero-forcing equalizer. The EVM equalizer spectrum flatness is defined in terms of the maximum peak-to-peak ripple of the equalizer coefficients (dB) across the allocated uplink block. The basic measurement interval is the same as for EVM.

For Pi/2 BPSK modulation, the minimum requirements are defined in Clause 6.4.2.5.

The peak-to-peak variation of the EVM equalizer coefficients contained within the frequency range of the uplink allocation shall not exceed the maximum ripple specified in Table 6.4.2.4-1 for normal conditions. For uplink allocations contained within both Range 1 and Range 2, the coefficients evaluated within each of these frequency ranges shall meet the corresponding ripple requirement and the following additional requirements: the relative difference between the maximum coefficient in Range 1 and the minimum coefficient in Range 2 (Table 6.4.2.4-1) must not be larger than 7 dB, and the relative difference between the maximum coefficient in Range 1 must not be larger than 8 dB (see Figure 6.4.2.4-1).

The requirement is verified with the test metric of EVM SF (Link=TX beam peak direction, Meas=Link angle).

	Frequency range	Maximum ripple (dB)
	F _{UL_Meas} – F_center ≤ X MHz	6 (p-p)
	(Range 1)	
	F _{UL_Meas} – F_center > X MHz	9 (p-p)
	(Range 2)	
NOTE 1:	$F_{\text{UL}_\text{Meas}}$ refers to the sub-carrier frequency for which	the equalizer coefficient is
	evaluated	
	F_center refers to the center frequency of the CC	
NOTE 3:	X, in MHz, is equal to 30 % of the CC bandwidth	

Table 6.4.2.4-2: (Void)

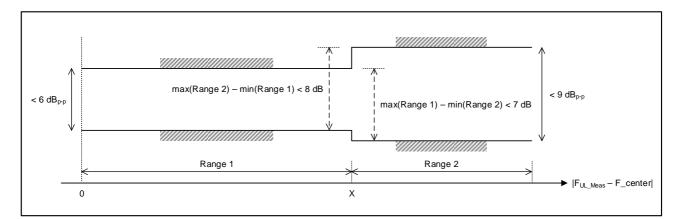


Figure 6.4.2.4-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation of the coefficients indicated under normal conditions

6.4.2.5 EVM spectral flatness for Pi/2 BPSK modulation

These requirements are defined for Pi/2 BPSK modulation. The EVM equalizer coefficients across the allocated uplink block shall be modified to fit inside the mask specified in Table 6.4.2.5-1 for normal conditions, prior to the calculation of EVM. The limiting mask shall be placed to minimize the change in equalizer coefficients in a sum of squares sense.

Frequency range	Parameter	Maximum ripple (dB)		
F _{UL_Meas} – F_center ≤ X MHz (Range 1)	X1	6 (p-p)		
F _{UL_Meas} – F_center > X MHz (Range 2)	X2	14 (p-p)		
NOTE 1: F _{UL_Meas} refers to the sub-carrier frequency for which the equalizer coefficient is evaluated NOTE 2: F_center refers to the center frequency of an allocated block of PRBs NOTE 3: X, in MHz, is equal to 25% of the bandwidth of the PRB allocation NOTE 4: See Figure 6.4.2.5-1 for description of X1, X2 and X3				

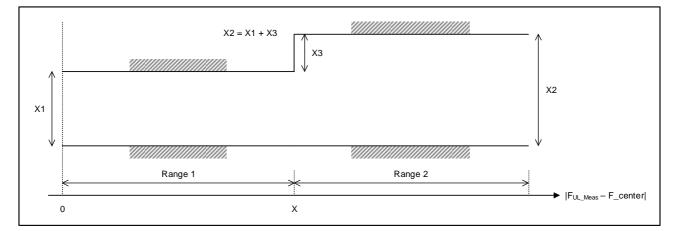


Figure 6.4.2.5-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation. F_center denotes the center frequency of the allocated block of PRBs.

This requirement does not apply to other modulation types. The UE shall be allowed to employ spectral shaping for Pi/2 BPSK. The shaping filter shall be restricted so that the impulse response of the transmit chain shall meet

$$\left| \tilde{a}_{t}(t,0) \right| \geq \left| \tilde{a}_{t}(t,\tau) \right| \quad \forall \tau \neq 0$$

20log₁₀ $\left| \tilde{a}_{t}(t,\tau) \right| < -15 \text{ dB} \quad 1 < \tau < \text{M} - 1$

1,

Where:

 $|\tilde{a}_t(t,\tau)| = IDFT\{ |\tilde{a}_t(t,f)| e^{j\varphi(t,f)} \},$

f is the frequency of the M allocated subcarriers,

 $\tilde{a}(t,f)$ and $\phi(t,f)$ are the amplitude and phase response, respectively of the transmit chain

0dB reference is defined as $20\log_{10}$ | $\tilde{a}_t(t,0)$ |

6.4A Transmit signal quality for CA

6.4A.0 General

The requirements in this clause apply if the UE has at least one of UL or DL configured for CA.

6.4A.1 Frequency error

The requirements in this clause apply to UEs of all power classes.

For intra-band contiguous and non-contiguous carrier aggregation, the UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequencies per band shall be accurate to within \pm 0.1 PPM observed over a period of 1ms of cumulated measurement intervals compared to the carrier frequency of primary component carrier received from the gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction.

6.4A.2 Transmit modulation quality

6.4A.2.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in clauses 6.4A.2.1, 6.4A.2.2, and 6.4A.2.3.

All the parameters defined in clause 6.4A.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4A.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with both UL polarizations active.

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrenList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4A.2.2 and 6.4A.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

The UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA.

6.4A.2.1 Error Vector magnitude

The requirements in this clause apply to UEs of all power classes. For intra-band contiguous and non-contiguous carrier aggregation, the Error Vector Magnitude requirement of clause 6.4.2.2 is defined for each component carrier. Requirements only apply with PRB allocation in one of the component carriers. Similar transmitter impairment removal procedures are applied for CA waveform before EVM calculation as is specified for non-CA waveform.

6.4A.2.2 Carrier leakage

6.4A.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier and is measured on the component carrier with PRBs allocated. The measurement interval is one slot in the time domain.

Note: When UE has DL configured for non-contiguous CA, carrier leakage may land outside the spectrum occupied by all configured UL and DL CC.

The relative carrier leakage power is a power ratio of the additive sinusoid waveform and the modulated waveform. The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

6.4A.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.2-1 for power class 1 UEs.

Table 6.4A.2.2.2-1: Minimum requirements for relative carrier leakage for power class 1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

6.4A.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.3-1 for power class 2.

Table 6.4A.2.2.3-1: Minimum requirements for relative carrier leakage power class 2

Parameters	Relative limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

6.4A.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.4-1 for power class 3 UEs.

Table 6 4 A 2 2 4 4. Minimum rec	wiromonto for rolative	operation lookage	nowar alace 2
Table 6.4A.2.2.4-1: Minimum rec	quirements for relative	e carrier leakage	power class 3

Parameters	Relative limit (dBc)
Output power > 0 dBm	-25
-13 dBm ≤ Output	-20
power EIRP ≤ 0 dBm	

6.4A.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.5-1 for power class 4 UEs.

Parameters	Relative limit (dBc)
Output power > 11 dBm	-25
-13 dBm ≤ Output power EIRP ≤ 11 dBm	-20

6.4A.2.3 Inband emissions

6.4A.2.3.1 General

Inband emission requirement is defined over the spectrum occupied by all configured UL and DL CCs. The measurement interval is as defined in clause 6.4.2.4. The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in this clause apply with all component carriers active and with one single contiguous PRB allocation in one of uplink component carriers. The inband emission is defined as the interference falling into the non-allocated resource blocks for all component carriers.

6.4A.2.3.2 Inband emissions for power class 1

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.2-1 for power class 1 UEs.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 27 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 27 dBm	
Carrier leakage	dBc	-25	Output power > 17 dBm	Carrier frequency (NOTES 4, 5)
		-20	4 dBm ≤ Output power ≤ 17 dBm	

NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. P RB is defined in NOTE 9. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD. Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable NOTE 3: frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency reported DC location position, but excluding any allocated RBs. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1). NOTE 7: EVM s the limit for the modulation format used in the allocated RBs. NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or Δ_{RR}^{o} = -1 for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB. NOTE 9: P_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm. NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.3.3 Inband emissions for power class 2

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.3-1 for power class 2.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 16 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 16 dBm	
Carrier leakage	dBc	-25	Output power > 6 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 6 dBm	

Table 6.4A.2.3.3-1: Requirements for in-band emissions for power class 2

NOTE 1:	An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum
	requirement is calculated as the higher of ($\overline{P_{RB}}$ - 25 dB) and the power sum of all limit values (General, IQ
	Image or Carrier leakage) that apply. P_{RB} is defined in NOTE 9.
NOTE 2:	The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
NOTE 3:	Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the reported DC location position, but excluding any allocated RBs.
NOTE 4:	The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
NOTE 5:	The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
NOTE 6:	L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
NOTE 7:	EVM s the limit for the modulation format used in the allocated RBs.
NOTE 8:	Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
NOTE 9:	P _{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs,
	measured in dBm.
NOTE 10	All powers are EIRP in beam peak direction.

6.4A.2.3.4 Inband emissions for power class 3

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.4-1 for power class 3 UEs.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 10 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 10 dBm	
Carrier leakage	dBc	-25	Output power > 0 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 0 dBm	

Table 6.4A.2.3.4-1: Requirements for in-band emissions for power class 3

NOTE 1:	An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum
	requirement is calculated as the higher of ($\overline{P_{RB}}$ - 25 dB) and the power sum of all limit values (General, IQ
	Image or Carrier leakage) that apply. P_{RB} is defined in NOTE 9.
NOTE 2:	The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
NOTE 3:	Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the reported DC location position, but excluding any allocated RBs.
NOTE 4:	The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
NOTE 5:	•
NOTE 6:	L _{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
NOTE 7:	EVM s the limit for the modulation format used in the allocated RBs.
NOTE 8:	Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
NOTE 9:	P _{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs,
	measured in dBm.
NOTE 10	All powers are EIRP in beam peak direction.

6.4A.2.3.5 Inband emissions for power class 4

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.5-1 for power class 4 UEs.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}}, \end{bmatrix}$	Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 21 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 21 dBm	
Carrier leakage	dBc	-25	Output power > 11 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 11 dBm	

Table 6.4A.2.3.5-1: Requirements for in-band emissions for power class 4

NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. $\overline{P_{RB}}$ is defined in NOTE 9. NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD. NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the reported DC location position, but excluding any allocated RBs. NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs. NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB. NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1). NOTE 7: EVM s the limit for the modulation format used in the allocated RBs. NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or Δ_{RR} = -1 for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB. \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, NOTE 9: measured in dBm. NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.4 EVM equalizer spectrum flatness

6.4D Transmit signal quality for UL MIMO

6.4D.0 General

For a UE supporting UL MIMO, the transmit modulation quality requirements in clause 6.4 apply but with all references to sub-clauses 6.3.1.x in clause 6.4 redirected to sub-clauses 6.3D.1.x, where 'x' depends on power class. The requirements apply when the UE is configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.0-1.

The requirement may alternatively be verified in each of the single layer UL MIMO configurations as specified in Table 6.4D.0-1. In this case, the transmit modulation quality requirements in clause 6.4 apply without modification.

Table 6.4D.0-1: Alternative UL MIMO configuration for transmit signal quality tests

Transmission scheme	DCI format	TPMI Index
Codebook based uplink	DCI format 0_1	0
Codebook based uplink	DCI format 0_1	1

6.4D.1 Frequency error for UL MIMO

For a UE supporting UL MIMO, the UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequency at each layer shall be accurate to within \pm 0.1 PPM observed over a period of 1ms of cumulated measurement intervals compared to the carrier frequency received from the NR Node B.

6.4D.2 Transmit modulation quality for UL MIMO

For UE supporting UL MIMO, the transmit modulation quality requirements are specified per layer in terms of:

Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)

EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process

Carrier leakage (caused by IQ offset)

For UE supporting UL MIMO, the transmit modulation quality requirements are specified as the total component of EIRP in terms of:In-band emissions for the non-allocated RB

The requirements are defined as directional requirements. The requirements are verified in beam locked mode in the TX beam peak direction (Link=TX beam peak direction, Meas=Link angle).

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrentList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4D.2.2 and 6.4D.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

6.4D.3 Time alignment error for UL MIMO

For a UE with multiple physical antenna ports supporting UL MIMO, this requirement applies to frame timing differences between transmissions on multiple physical antenna ports in the codebook transmission scheme.

The time alignment error (TAE) is defined as the average frame timing difference between any two transmissions on different physical antenna ports.

For a UE with multiple physical antenna ports, the Time Alignment Error (TAE) shall not exceed 130 ns.

6.4D.4 Requirements for coherent UL MIMO

For coherent UL MIMO, Table 6.4D.4-1 lists the maximum allowable difference between the measured relative power and phase errors between different physical antenna ports in any slot within the specified time window from the last transmitted SRS on the same antenna ports, for the purpose of uplink transmission (codebook or non-codebook usage) and those measured at that last SRS. The requirements in Table 6.4D.4-1 apply when the UL transmission power at each physical antenna port is larger than 0 dBm for SRS transmission and for the duration of time window. The requirement is verified with the test metric of EIRP (Link=TX Beam peak direction, Meas=Link angle).

Table 6.4D.4-1: Maximum allowable difference of relative phase and power errors in a given slot compared to those measured at last SRS transmitted

	Difference of relative phase error	Difference of relative power error	Time window
ſ	40 degrees	4 dB	20 msec

The above requirements apply when all of the following conditions are met within the specified time window:

- UE is not signaled with a change in number of SRS ports in SRS-config, or a change in PUSCH-config
- UE remains in DRX active time (UE does not enter DRX OFF time)
- No measurement gap occurs
- No instance of SRS transmission with the usage antenna switching occurs
- Active BWP remains the same
- EN-DC and CA configuration is not changed for the UE (UE is not configured or de-configured with PScell or SCell(s))

6.5 Output RF spectrum emissions

6.5.1 Occupied bandwidth

Occupied bandwidth is defined as the bandwidth containing 99 % of the total integrated mean power of the transmitted spectrum on the assigned channel. The occupied bandwidth for all transmission bandwidth configurations (Resources Blocks) shall be less than the channel bandwidth specified in Table 6.5.1-1.

The occupied bandwidth is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of OBW (Link=TX beam peak direction, Meas=Link angle).

	Occupied channel bandwidth / Channel bandwidth				
	50 100 200 400				
	MHz	MHz	MHz	MHz	
Channel bandwidth	50	100	200	400	
(MHz)					

Table 6.5.1-1: Occupied channel bandwidth

6.5.2 Out of band emissions

6.5.2.0 General

The Out of band emissions are unwanted emissions immediately outside the assigned channel bandwidth resulting from the modulation process and non-linearity in the transmitter but excluding spurious emissions. This out of band emission limit is specified in terms of a spectrum emission mask and an adjacent channel leakage power ratio. Additional requirements to protect specific bands are also considered.

The requirements in clause 6.5.2.1 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in clause 6.5A.2.1 apply.

All out of band emissions for frequency range 2 are TRP.

6.5.2.1 Spectrum emission mask

The spectrum emission mask of the UE applies to frequencies (Δf_{OOB}) starting from the ± edge of the assigned NR channel bandwidth. For frequencies offset greater than F_{OOB} as specified in Table 6.5.2.1-1 the spurious requirements in clause 6.5.3 are applicable.

The power of any UE emission shall not exceed the levels specified in Table 6.5.2.1-1 for the specified channel bandwidth. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Spectrum emission limit (dBm) / Channel bandwidth							
∆f _{оов} (MHz)	50 MHz	100 MHz	200 MHz	400 MHz	Measurement bandwidth		
± 0-5	-5	-5	-5	-5	1 MHz		
± 5-10	-13	-5	-5	-5	1 MHz		
± 10-20	-13	-13	-5	-5	1 MHz		
± 20-40	-13	-13	-13	-5	1 MHz		
± 40-100	-13	-13	-13	-13	1 MHz		
± 100-200		-13	-13	-13	1 MHz		
± 200-400			-13	-13	1 MHz		
± 400-800				-13	1 MHz		

Table 6.5.2.1-1: General NR spectrum emission mask for frequency range 2.

6.5.2.2 Void

6.5.2.3 Adjacent channel leakage ratio

Adjacent Channel Leakage power Ratio (ACLR) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency. ACLR requirement is specified for a scenario in which adjacent carrier is another NR channel.

NR Adjacent Channel Leakage power Ratio (NR_{ACLR}) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency at nominal channel spacing. The assigned NR channel power and adjacent NR channel power are measured with rectangular filters with measurement bandwidths specified in Table 6.5.2.3-1.

If the measured adjacent channel power is greater than -35 dBm then the NR_{ACLR} shall be higher than the value specified in Table 6.5.2.3-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

	Channel bandwidth / NR _{ACLR} / Measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
NR _{ACLR} for band n257, n258, n261	17 dB	17 dB	17 dB	17 dB
NR _{ACLR} for band n259, n260	16 dB	16 dB	16 dB	16 dB
NR channel measurement bandwidth (MHz)	47.58	95.16	190.20	380.28
Adjacent channel centre frequency offset (MHz)	+50 / -50	+100 / -100	+200 / -200	+400 / -400

Table 6.5.2.3-1: General requirements for NR_{ACLR}

6.5.3 Spurious emissions

Spurious emissions are emissions which are caused by unwanted transmitter effects such as harmonics emission, parasitic emissions, intermodulation products and frequency conversion products, but exclude out of band emissions unless otherwise stated. The spurious emission limits are specified in terms of general requirements in line with SM.329 [7] and NR operating band requirement to address UE co-existence. Spurious emissions are measured as TRP.

To improve measurement accuracy, sensitivity and efficiency, the resolution bandwidth may be smaller than the measurement bandwidth. When the resolution bandwidth is smaller than the measurement bandwidth, the result should be integrated over the measurement bandwidth in order to obtain the equivalent noise bandwidth of the measurement bandwidth.

Unless otherwise stated, the spurious emission limits apply for the frequency ranges that are more than F_{OOB} (MHz) in Table 6.5.3-1 starting from the edge of the assigned NR channel bandwidth. The spurious emission limits in Table 6.5.3-2 apply for all transmitter band configurations (NRB) and channel bandwidths. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

Table 6.5.3-1: Boundary between NR out of band and spurious emission domain

Channel bandwidth	50	100	200	400
	MHz	MHz	MHz	MHz
ООВ boundary F _{ООВ} (MHz)	100	200	400	800

Frequency Range	Maximum Level	Measurement bandwidth
30 MHz ≤ f < 1000 MHz	-36 dBm	100 kHz
1 GHz ≤ f < 12.75 GHz	-30 dBm	1 MHz
12.75 GHz \leq f \leq 2 nd harmonic of the upper frequency edge of the UL operating band in GHz	-13 dBm	1 MHz

Table 6.5.3-2: Spurious emissions limits

6.5.3.1 Spurious emission band UE co-existence

This clause specifies the requirements for the specified NR band, for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

NR Band	Spurious emission						
	Protected band/frequency range Frequency range (MHz)			Maximum Level (dBm)	MBW (MHz)	NOTE	
n257	NR Band n260	F_{DL_low}	-	F _{DL_high}	-2	100	
	Frequency range	57000	-	66000	2	100	
	Frequency range	23600	-	24000	1	200	3
n258	Frequency range	57000	-	66000	2	100	
n259	NR Band 257	FDL_low	-	F_{DL_high}	-5	100	
	NR Band 261	FDL_low	-	F_{DL_high}	-5	100	
	Frequency range	36000	-	37000	7	1000	
	Frequency range	57000	-	66000	2	100	
n260	NR Band 257	F_{DL_low}	-	F_{DL_high}	-5	100	
	NR Band 261	FDL_low	-	F_{DL_high}	-5	100	
	Frequency range	57000	I	66000	2	100	
n261	NR Band 260	FDL_low	-	F_{DL_high}	-2	100	
	Frequency range	57000	-	66000	2	100	
NOTE 1: NOTE 2:	F _{DL_low} and F _{DL_high} refer to each NR frequency band specified in Table 5.2-1						
NOTE 3:	The protection of frequency range 23600-24000 MHz is meant for protection of satellite passive services.						

Table 6.5.3.1-1: Requirements

6.5.3.2 Additional spurious emissions

6.5.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

6.5.3.2.2 Void

Table 6.5.3.2.2-1: (Void)

6.5.3.2.3 Additional spurious emission requirements for NS_202

When "NS_202" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.3-1.

Frequency Range	Maximum Level	Measurement bandwidth	NOTE	
7.25 GHz \leq f \leq 2 nd harmonic of the upper frequency edge of the UL operating band	-10 dBm	100 MHz		
23.6 GHz ≤ f ≤ 24.0 GHz	+1 dBm	200 MHz	1	
NOTE 1: This requirement also applies for the frequency ranges that are less than F _{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth. The protection of frequency range 23600 - 24000 MHz is meant for protection of satellite passive services.				

Table 6.5.3.2.3-1: Additional requirements (NS_202)

6.5.3.2.4 Additional spurious emission requirements for NS_203

When "NS_203" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.4-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth.

Table 6.5.3.2.4-1: Additional requirements (NS_203)

Frequency band (GHz)	Spectrum emission limit (dBm)	Measurement bandwidth
$23.6 \le f \le 24.0$	+1	200 MHz

6.5A Output RF spectrum emissions for CA

6.5A.1 Occupied bandwidth for CA

6.5A.1.0 General

The occupied bandwidth for UL CA is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction. In case the CA configuration consists of a single UL CC, the occupied bandwidth requirement defined in subclause 6.5.1 applies.

6.5A.1.1 Occupied bandwidth for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the occupied bandwidth is a measure of the bandwidth containing 99 % of the total integrated power of the transmitted spectrum. The occupied bandwidth for UL CA shall be less than the UL aggregated channel bandwidth defined in clause 5.3A.

6.5A.1.2 Occupied bandwidth for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the occupied bandwidth requirement is met when the ratio of the transmitted power in all sub-blocks of the UL CA configuration to the total integrated power of the transmitted spectrum is greater than 99%.

6.5A.2 Out of band emissions

6.5A.2.1 Spectrum emission mask for CA

6.5A.2.1.0 General

The requirements specified in this clause shall apply if the UE has at least one of UL or DL configured for CA or if the UE is configured for single CC operation with different channel bandwidths in UL and DL carriers. In case the CA

configuration consists of a single UL CC, spectrum emission mask defined in subclause 6.5.2.1 applies. Spectral emission mask requirements do not apply at any frequency where IBE requirements of clause 6.4A.2.3 apply.

The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

6.5A.2.1.1 Spectrum emission mask for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the spectrum emission mask of the UE applies to frequencies (Δf_{OOB}) starting from the ± edge of the UL aggregated channel bandwidth (Table 5.3A.5-1). For any bandwidth class defined in Table 5.3A.5-1, the UE emission shall not exceed the levels specified in Table 6.5A.2.1-1.

Table 6.5A.2.1.1-1: General NR spectrum emission mask for intra-band contiguous CA in frequency range 2

<u> </u>	Any carrier aggregation bandwidth class	Measurement bandwidth
± 0-0.1*BW _{Channel_CA}	-5	1 MHz
\pm 0.1*BW _{Channel_CA} -	-13	1 MHz
2*BWChannel_CA		
NOTE 1: (void)		

6.5A.2.1.2 Spectrum emission mask for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the spectrum emission mask requirement is defined as a composite spectrum emissions mask. Composite spectrum emission mask applies to frequencies up to $\pm \Delta f_{OOB}$ starting from the edge of each UL sub-block. Composite spectrum emission mask is defined as follows:

- a) Composite spectrum emission mask is a combination of individual spectrum emissions masks defined for each sub-block. If for some frequency, spectrum emission masks from multiple sub-blocks overlap, the spectrum emission mask allowing the highest power spectral density applies for that frequency
- b) In case a sub-block comprises of multiple component carriers, the spectrum emissions mask is defined in subclause 6.5A.2.1.1 or in case of a single component carrier, the sub-block spectrum emission mask is defined in subclause 6.5.2.1
- c) If for some frequency the spectrum emission mask of one sub-block overlaps another sub-block, the emission mask does not apply for that frequency.
- d) If carrier leakage or I/Q image lands inside the spectrum occupied by the configured UL and DL CCs, exception to the general spectrum emission mask limit applies. For carrier leakage the requirements specified in section 6.4A.2.2 shall apply. For I/Q image the requirements specified in section 6.4A.2.3 shall apply.

6.5A.2.3 Adjacent channel leakage ratio for CA

6.5A.2.3.1 Adjacent channel leakage ratio for CA intra-band contiguous UL CA

In case the CA configuration consists of a single UL CC, the adjacent channel leakage ratio defined in subclause 6.5.2.3 applies. For intra-band contiguous UL carrier aggregation, the carrier aggregation NR adjacent channel leakage power ratio (CA NR_{ACLR}) is the ratio of the filtered mean power centred on the UL aggregated channel bandwidth to the filtered mean power centred on an adjacent UL aggregated channel bandwidth at spacing equal to the UL aggregated channel bandwidth. The assigned UL aggregated channel bandwidth power and adjacent UL aggregated channel bandwidth power are measured with rectangular filters with measurement bandwidths specified in Table 6.5A.2.3.1-1. If the measured adjacent channel power is greater than -35 dBm then the CA NR_{ACLR} shall be higher than the value specified in Table 6.5A.2.3.1-1.

_	CA bandwidth class / CA NR _{ACLR} / Measurement bandwidth Any CA bandwidth class				
CA NR _{ACLR} for band n257, n258, n261	17 dB				
CA NR _{ACLR} for band n259, n260	16 dB BW _{Channel_CA} − 2*BW _{GB}				
NR channel measurement bandwidth ¹					
Adjacent channel centre frequency offset (in MHz)	+ BW _{Channel_CA} / - BW _{Channel_CA}				
NOTE 1: BW _{GB} is defined in clause 5.3A.2.					

6.5A.2.3.2 Adjacent channel leakage ratio for CA intra-band non-contiguous UL CA

For intra-band non-contiguous carrier aggregation, adjacent channel leakage power ratio (CA NR_{ACLR}) is the ratio of the sum of the filtered mean powers centred on each sub-block bandwidth to the filtered mean power centred on an adjacent sub-block frequency at nominal spacing equal to the sub-block bandwidth. The power in the configured UL CCs and power in the sub-block bandwidth adjacent to each sub-block of configured UL CCs are measured with rectangular filters with measurement bandwidths specified in Table 6.5A.2.3.1-2. In case a sub-block consists of a single component carrier, the measurement bandwidths and adjacent frequency offset from subclause 6.5.2.3 shall be used. If the measured adjacent sub-block power is greater than -35 dBm then the CA NR_{ACLR} shall be higher than the value specified in Table 6.5A.2.3.1-2.

No requirement applies in the gap between neighbouring sub-blocks if the frequency span between the lowest edge of the upper sub-block and the highest edge of the lower sub-block is smaller than the bandwidth of either sub-block.

	CA bandwidth class / CA NR _{ACLR} / Measurement bandwidth			
	Any CA bandwidth class			
CA NR _{ACLR} for band n257, n258, n261	17 dB			
CA NR _{ACLR} for band n260	16 dB			
NR channel measurement bandwidth ¹	$\Sigma(BW_{Channel,block})$			
Adjacent sub-block centre frequency offset (in MHz)	+ BWChannel,block / - BWChannel_block			
NOTE 1: BWChannel_block is defined in clause NOTE 2: 'Adjacent sub-block centre frequency of configuration	95.3A.2.			

6.5A.3 Spurious emissions for CA

6.5A.3.0 General spurious emissions for CA

6.5A.3.0.0 General

This clause specifies the spurious emission requirements for carrier aggregation. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

In case the CA configuration consists of a single UL CC, spurious emissions requirements defined in subclause 6.5.3 apply. Spurious emissions requirements do not apply at any frequency where IBE requirements of clause 6.4A.2.3 apply.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

6.5A.3.0.1 Spurious emissions for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the spurious emission limits apply for the frequency ranges that are more than F_{OOB} (MHz) from the edge of the UL aggregated channel bandwidth, where F_{OOB} is defined as the twice the UL aggregated channel bandwidth. For frequencies Δf_{OOB} greater than F_{OOB} , the spurious emission requirements in Table 6.5.3-2 are applicable.

6.5A.3.0.2 Spurious emissions for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the spurious emission requirement is defined as a composite spurious emission requirement which is a combination of individual spurious emission requirements defined for each UL sub-block. The limits in Table 6.5.3-2 apply for the frequency ranges that are more than F_{OOB} (MHz) from the edge of each UL sub-block but excludes frequency ranges that coincide with another UL sub-block. No spurious emission limit applies in the gap between neighbouring UL sub-blocks if the frequency span between the lowest edge of the upper sub-block and the highest edge of the lower sub-block is smaller than F_{OOB} L + F_{OOB} H.

6.5A.3.1 Spurious emission band UE co-existence for UL CA

This clause specifies the requirements for the specified contiguous or non-contiguous ULcarrier aggregation configurations for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in Table 6.5A.3-1 apply.

CA band	Spurious emission									
	Protected band / frequency range	Frequency range (MHz)			Maximum Level (dBm)	MBW (MHz)	NOTE			
CA_n257	NR Band n260	F _{DL_low}	-	F_{DL_high}	-2	100				
	Frequency range	57000	-	66000	2	100				
	Frequency range	23600	-	24000	1	200	2			
CA_n258	Frequency range	57000	-	66000	2	100				
CA_n259	NR Band 257	FDL_low	-	FDL_high	-5	100				
	NR Band 261	F _{DL_low}	-	F _{DL_high}	-5	100				
	Frequency range	36000	-	37000	7	1000				
	Frequency range	57000	-	66000	2	100				
CA_n260	NR Band 257	F _{DL_low}	-	F_{DL_high}	-5	100				
	NR Band 261	F _{DL_low}	-	F_{DL_high}	-5	100				
	Frequency range	57000	-	66000	2	100				
CA_n261	NR Band 260	F _{DL_low}	-	F _{DL_high}	-2	100				
	Frequency range	57000	-	66000	2	100				
	w and F _{DL_high} refer to each NR frec protection of frequency range 2360 ces.					satellite pa	ssive			

Table 6.5A.3.1-1: Requirements for CA

6.5A.3.2 Additional spurious emissions

6.5A.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

6.5A.3.2.2 Void

6.5A.3.2.3 Additional spurious emission requirements for CA_NS_202

When "CA_NS_202" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.3-1.

6.5A.3.2.4 Additional spurious emission requirements for CA_NS_203

When "CA_NS_203" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.4-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) as defined in section 6.5A.3.

6.5D Output RF spectrum emissions for UL MIMO

6.5D.1 Occupied bandwidth for UL MIMO

For UE(s) supporting UL MIMO, the occupied bandwidth requirement in clause 6.5.1 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.5D.2 Out of band emissions for UL MIMO

For UE(s) supporting UL MIMO, the out of band emissions requirements in clause 6.5.2 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.5D.3 Spurious emissions for UL MIMO

For UE(s) supporting UL MIMO, the spurious emissions requirements in clause 6.5.3 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.6 Beam correspondence

6.6.1 General

Beam correspondence is the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping. Unless explicitly addressed in subclauses below, the beam correspondence requirement is fulfilled if the UE meets the corresponding minimum peak EIRP requirement and spherical coverage requirement for that power class with its autonomously chosen UL beams and without uplink beam sweeping.

- 6.6.2 Void
- 6.6.3 Void

6.6.4 Beam correspondence for power class 3

6.6.4.1 General

The beam correspondence requirement for power class 3 UEs consists of three components: UE minimum peak EIRP (as defined in Clause 6.2.1.3), UE spherical coverage (as defined in Clause 6.2.1.3), and beam correspondence tolerance (as defined in Clause 6.6.4.2). The beam correspondence requirement is fulfilled if the UE satisfies one of the following conditions, depending on the UE's beam correspondence capability IE *beamCorrespondenceWithoutUL-BeamSweeping*, as defined in TS 38.306 [14]:

- If *beamCorrespondenceWithoutUL-BeamSweeping* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with its autonomously chosen UL beams and without uplink beam sweeping. Such a UE is considered to have met the beam correspondence tolerance requirement.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceSSB-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.2.
- If *beamCorrespondenceWithoutUL-BeamSweeping* and *beamCorrespondenceCSI-RS-based-r16* are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.3.
- If *beamCorrespondenceWithoutUL-BeamSweeping* is not present, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].
- If *beamCorrespondenceWithoutUL-BeamSweeping* is not present and *beamCorrespondenceSSB-based-r16* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.2. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].
- If *beamCorrespondenceWithoutUL-BeamSweeping* is not present and *beamCorrespondenceCSI-RS-based-r16* is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.3. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].

6.6.4.2 Beam correspondence tolerance for power class 3

The beam correspondence tolerance requirement $\Delta EIRP_{BC}$ for power class 3 UEs is defined based on a percentile of the distribution of $\Delta EIRP_{BC}$, defined as $\Delta EIRP_{BC} = EIRP_2 - EIRP_1$ over the link angles spanning a subset of the spherical coverage grid points, such that

- EIRP₁ is the total EIRP in dBm calculated based on the beam the UE chooses autonomously (corresponding beam) to transmit in the direction of the incoming DL signal, which is based on beam correspondence without relying on UL beam sweeping.
- EIRP₂ is the best total EIRP (beam yielding highest EIRP in a given direction) in dBm which is based on beam correspondence with relying on UL beam sweeping.
- The link angles are the ones corresponding to the top N^{th} percentile of the EIRP₂ measurement over the whole sphere, where the value of N is according to the test point of EIRP spherical coverage requirement for power class 3, i.e. N = 50.

For power class 3 UEs, the requirement is fulfilled if the UE's corresponding UL beams satisfy the maximum limit in Table 6.6.4.2-1.

Operating band	Max ∆EIRP _{BC} at 85 th %-tile ∆EIRP _{BC} CDF (dB)	
n257	3.0	
n258	3.0	
n259	3.2	
n260	3.2	
n261	3.0	
NOTE: The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1		

 Table 6.6.4.2-1: UE beam correspondence tolerance for power class 3

6.6.4.3 Side Conditions

6.6.4.3.1 Side Condition for beam correspondence based on SSB and CSI-RS

The beam correspondence requirements are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided and Type D QCL shall be maintained between SSB and CSI-RS.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-1 and Table 6.6.4.3.1-2.

Table 6.6.4.3.1-1: Conditions for SSB based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-96.2	≥6
	n258	-96.2	
	n259	-90.7	
	n260	-91.9	
	n261	-96.2	
NOTE 1: Fo	or UEs that support mult	iple FR2 bands, the Minimum SSB_RP values for all ang	les are
NOTE 2: Va		UE multi-band relaxation factor in dB specified in clause of diated requirements reference point to give minimum SSE	

Table 6.6.4.3.1-2: Conditions for CSI-RS based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum CSI-RS_RP Note 2	CSI-RS Ês/lot
	dBm / SCS _{CSI-RS}		dB
		SCS _{CSI-RS} = 120 kHz	
All angles Note 1	n257	-96.2	≥6
	n258	-96.2	Ī
	n259	-90.7	
	n260	-91.9	
	n261	-96.2	
NOTE 1: Fo	r UEs that support multip	le FR2 bands, the Minimum CSI-RS_RP values are inc	reased by
NOTE 2: Va		relaxation factor in dB specified in clause 6.2.1. ated requirements reference point to give minimum CSI	-RS Ês/lot,

6.6.4.3.2 Side Condition for SSB based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on SSB are only applied under the following side conditions:

- The downlink reference signal SSB is provided and CSI-RS is not provided.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-1.

6.6.4.3.3 Side Condition for CSI-RS based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on CSI-RS are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-2 and SSB signal is provided according to Table 6.6.4.3.3-1.

Table 6.6.4.3.3-1: SSB signal conditions for CSI-RS based beam correspondence requirements

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-101.2	≥1
	n258	-101.2	
	n259	-95.7	
	n260	-96.9	
	n261	-101.2	
NOTE 1: Fo	r UEs that support mult	iple FR2 bands, the Minimum SSB_RP values for all ang	les are
inc	creased by $\Delta MB_{S,n}$, the	UE multi-band relaxation factor in dB specified in clause (5.2.1.
NOTE 2: Va	lues specified at the ra	diated requirements reference point to give minimum SSI	3 Ês/lot,
wit	h no applied noise.		

6.6.4.4 Applicability

For UEs supporting more than one type of beam correspondence, the following applicability rules apply:

- If a UE meets enhanced beam correspondence requirements either based on SSB or based on CSI-RS, it is considered to have met the beam correspondence requirements based on SSB and CSI-RS.
- For a UE supporting either SSB based or CSI-RS based enhanced beam correspondence, the UE shall meet the supported enhanced beam correspondence requirements.
- For a UE supporting both SSB based and CSI-RS based enhanced beam correspondence, the UE shall meet both SSB based and CSI-RS based enhanced beam correspondence requirements and the following applicability rules for verifying the requirements apply:
 - The enhanced beam correspondence requirements shall be verified with the SSB based enhanced beam correspondence side conditions in clause 6.6.4.3.2. If the UE meets the SSB based enhanced beam correspondence requirements using the side conditions in clause 6.6.4.3.2 and meets the minimum peak EIRP requirement as defined in clasue 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.4.3.3, where the link direction is determined in the SSB based enhanced beam correspondence test, the UE is considered to have met both the SSB based and CSI-RS based enhanced beam correspondence requirements.
 - Otherwise, if UE does not meet the minimum peak EIRP requirement as defined in clasue 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.4.3.3, the enhanced beam correspondence requirements shall be further verified for the UE with the CSI-RS based enhanced beam correspondence side conditions in clause 6.6.4.3.3.

6.6.5 Void

6.6A Beam correspondence for CA

For intra-band CA in FR2, the same beam correspondence relationship for beam management is supported across CCs in this release of the specification and no requirement is specified. Beam correspondence performance for intra-band CA is fulfilled if the beam correspondence requirements defined in clause 6.6 is met for non-CA case.

7 Receiver characteristics

7.1 General

Unless otherwise stated, the receiver characteristics are specified over the air (OTA). The reference receive sensitivity (REFSENS) is defined assuming a 0 dBi reference antenna located at the center of the quiet zone.

7.2 Diversity characteristics

The minimum requirements on effective isotropic sensitivity (EIS) apply to two measurements, corresponding to DL signals in orthogonal polarizations.

7.3 Reference sensitivity

7.3.1 General

The reference sensitivity power level REFSENS is defined as the EIS level at the centre of the quiet zone in the RX beam peak direction, at which the throughput shall meet or exceed the requirements for the specified reference measurement channel.

7.3.2 Reference sensitivity power level

7.3.2.1 Reference sensitivity power level for power class 1

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.1-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257	-97.5	-94.5	-91.5	-88.5
n258	-97.5	-94.5	-91.5	-88.5
n260	-94.5	-91.5	-88.5	-85.5
n261	-97.5	-94.5	-91.5	-88.5
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4				

Table 7.3.2.1-1: Reference sensitivity for power class 1

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Table 7.3.2.1-2: Uplink configuration for reference sensitivity

Operating band	NR Band / Channel bandwidth / NRB / SCS / Duplex mode					
	50 MHz	100 MHz	200 MHz	400 MHz	SCS	Duplex Mode
n257	32	64	128	256	120 kHz	TDD
n258	32	64	128	256	120 kHz	TDD
n260	32	64	128	256	120 kHz	TDD
n261	32	64	128	256	120 kHz	TDD

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

Table 7.3.2.1-3: Reserved

Operating band	Network Signalling value

7.3.2.2 Reference sensitivity power level for power class 2

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.2-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth				
	50 MHz	100 MHz	200 MHz	400 MHz	
n257	-92.0	-89.0	-86.0	-83.0	
n258	-92.0	-89.0	-86.0	-83.0	
n261	-92.0	-89.0	-86.0	-83.0	
NOTE 1: The tran	NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4				

Table 7.3.2.2-1: Reference sensitivity for power class 2

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.3 Reference sensitivity power level for power class 3

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.3-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

For the UEs that support multiple FR2 bands, the minimum requirement for Reference sensitivity in Table 7.3.2.3-1 shall be increased per band, respectively, by the reference sensitivity relaxation parameter $\Delta MB_{P,n}$ as specified in clause 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.2.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.2.3-1 and Table 6.2.1.3-4.

Operating band	REFSENS (dBm) / Channel bandwidth				
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz			
n257	-88.3	-85.3	-82.3	-79.3	
n258	-88.3	-85.3	-82.3	-79.3	
n259	-84.7	-81.7	-78.7	-75.7	
n260	-85.7	-82.7	-79.7	-76.7	
n261	-88.3	-85.3	-82.3	-79.3	
NOTE 1: The trans	NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4				

Table	7.3.2.3-1:	Reference	sensitivity
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The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.4 Reference sensitivity power level for power class 4

The throughput shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.4-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating band	REFSENS (dBm) / Channel bandwidth				
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz			
n257	-97.0	-94.0	-91.0	-88.0	
n258	-97.0	-94.0	-91.0	-88.0	
n260	-95.0	-92.0	-89.0	-86.0	
n261	-97.0	-94.0	-91.0	-88.0	
NOTE 1: The trans	NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4				

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.3 Void

7.3.4 EIS spherical coverage

7.3.4.1 EIS spherical coverage for power class 1

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.1

The maximum EIS at the 85th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.1-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	EIS at 85 th %-tile CCDF (dBm) / Channel bandwidth							
	50 MHz	200 MHz	400 MHz					
n257	-89.5	-86.5	-83.5	-80.5				
n258	-89.5	-86.5	-83.5	-80.5				
n260	-86.5	-83.5	-80.5	-77.5				
n261 -89.5 -86.5		-86.5	-83.5	-80.5				
	NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4							
	The EIS spherical coverage requirements are verified only under normal thermal							
cc	conditions as defined in Annex E.2.1.							

Table 7.3.4.1-1: EIS spherical coverage for power class 1

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.2 EIS spherical coverage for power class 2

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.2

The maximum EIS at the 60th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.2-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	EIS at 60 th %-tile CCDF (dBm) / Channel bandwidth					
	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-81.0	-78.0	-75.0	-72.0		
n258	-81.0	-78.0	-75.0	-72.0		
n261 -81.0		-78.0	-75.0	-72.0		
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4						
NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal						
conditior	ns as defined in Anne	ex E.2.1.				

Table 7.3.4.2-1: EIS spherical coverage for power class 2

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.3 EIS spherical coverage for power class 3

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.3

The maximum EIS at the 50th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.3-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

For the UEs that support multiple FR2 bands, the minimum requirement for EIS spherical coverage in Table 7.3.4.3-1 shall be increased per band, respectively, by the EIS spherical coveragerelaxation parameter $\Delta MB_{S,n}$ as specified in clause 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.4.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.4.3-1 and Table 6.2.1.3-4.

Operating band	EIS at 50 th %-tile CCDF (dBm) / Channel bandwidth					
	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-77.4	-74.4	-71.4	-68.4		
n258	-77.4	-74.4	-71.4	-68.4		
n259	-71.9	-68.9	-65.9	-62.9		
n260	-73.1	-70.1	-67.1	-64.1		
n261	-77.4	-74.4	-71.4	-68.4		
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4						
NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal						
condition	s as defined in Ann	ex E.2.1.				

 Table 7.3.4.3-1: EIS spherical coverage for power class 3

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.4 EIS spherical coverage for power class 4

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.4

The maximum EIS at the 20th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.4-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Operating band	EIS at 20 th %-tile CCDF (dBm) / Channel bandwidth					
	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-88.0	-85.0	-82.0	-79.0		
n258	-88.0	-85.0	-82.0	-79.0		
n260	-83.0	-80.0	-77.0	-74.0		
n261	-88.0	-85.0	-82.0	-79.0		
NOTE 1: The transmitter shall be set to PUMAX as defined in clause 6.2.4						
NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal						
condition	s as defined in Anne	ex E.2.1.				

Table 7.3.4.4-1: EIS spherical coverage for power class 4

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3A Reference sensitivity for DL CA

7.3A.1 General

7.3A.2 Reference sensitivity power level for CA

7.3A.2.1 Intra-band contiguous CA

For each component carrier in the intra-band contiguous carrier aggregation, the throughput in QPSK R = 1/3 shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity values determined from clause 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.1-1.

Table 7.3A.2.1-1: ΔR_{IBC} EIS Relaxation for CA operation by aggregated channel bandwidth

Aggregated Channel BW 'BW _{Channel_CA} ' (MHz)	ΔR _{IBC} (dB)
BW _{Channel_CA} ≤ 800	0.0
800 < BW _{Channel_CA} ≤ 1200	0.5

7.3A.2.2 Intra-band non-contiguous CA

For each component carrier in the intra-band non-contiguous carrier aggregation, the throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity values determined from clause 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.2-1. The configured downlink spectrum is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs.

able 7.3A.2.2-1: ΔRIBN	EIS Relaxation	for CA operation
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Configured DL spectrum (MHz)	ΔR _{IBNC} (dB)
≤ 800	0.0
> 800 and ≤ 1400	0.5
> 1400 and ≤ 2400	1.5

7.3A.2.3 Inter-band CA

The inter-band requirement applies for all active component carriers. The throughput for each component carrier shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity for each carrier specified in section 7.3.2, and relaxation $\Delta R_{IB,P,n}$ applied to peak reference sensitivity requirement. $\Delta R_{IB,P,n}$ is specified in Table 7.3A.2.3-1. The requirement on each component carrier shall be met when the power in the component carrier in the other band is set to its EIS spherical coverage requirement for interband CA specified in sub-clause 7.3A.3.3.

For the combination of intra-band and inter-band carrier aggregation, the intra-band CA relaxation, ΔR_{IBC} and ΔR_{IBNC} , are also applied according to the clause 7.3A.2.1 and 7.3A.2.2.

Table 7.3A.2.3-1: $\Delta R_{IB,P,n}$ reference sensitivity relaxation for inter-band CA for power class 3

NR CA band combination	NR band	ΔR _{IB,P,n} (dB)
CA_n260-n261	n260	3.5
	n261	3.5

7.3A.3 EIS spherical coverage for DL CA

- 7.3A.3.1 Void
- 7.3A.3.2 Void

7.3A.3.3 EIS spherical coverage for inter-band CA

The inter-band CA requirement applies per operating band, for all active component carriers with UL assigned to one band and one DL component carrier per band. The requirement on each component carrier shall be met when the power in the component carrier in the other band is set to its EIS spherical coverage requirement for inter-band CA specified in this sub-clause.

The inter-band CA spherical coverage requirement for each power class will be satisfied if the intersection set of spherical coverage areas exceeds the common coverage requirement. Intersection set of spherical coverage areas is defined as a fraction of area of full sphere measured around the UE where both bands meet their defined individual EIS spherical coverage requirements for inter-band CA operation. The common coverage requirement is determined as <100-percentile rank> %, where 'percentile rank' is the percentile value in the specification of spherical coverage for that power class from clause 7.3.4.The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

The reference measurement channels and throughput criterion shall be as specified in clause 7.3A.2.3. The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in clause 7.3.2.

Unless otherwise specified, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3.1-1) configured.

The required spherical coverage EIS for each band in inter-band CA operation is given in clause 7.3.4 and modified by $\Delta R_{IB,S,n}$. The value of $\Delta R_{IB,S,n}$ is defined in Table 7.3A.3.3-1.

Table 7.3A.3.3-1: ΔR_{IB,S,n} EIS spherical coverage requirement relaxation for inter-band CA for power class 3

NR CA band combination	NR band	ΔR _{IB,S,n} (dB)
CA_n260-n261	n260	3.5
	n261	3.5

7.3D Void

7.4 Maximum input level

The maximum input level is defined as the maximum mean power, for which the throughput shall meet or exceed the minimum requirements for the specified reference measurement channel.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved.

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annex A (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with parameters specified in Table 7.4.-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Rx Parameter		Units		bandwidth		
			50	100	200	400
			MHz	MHz	MHz	MHz
Power in transmission dBm -25 (NOTE 2)						
bandw	idth configuration		-27 (NOTE 3)			
NOTE 1:	1: The transmitter shall be set to 4 dB below the P _{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.					
NOTE 2:	Reference measurement channel is specified in Annex A.3.3.2: QPSK, R=1/3 variant with one sided dynamic OCNG Pattern as described in Annex A.					
NOTE 3:	Reference measurement channel is specified in Annex A.3.3.5: 256QAM, R=4/5 variant with one sided dynamic OCNG Pattern as described in Annex A.					

Table 7.4-1: Maximum input level

Table 7.4-2: Void

7.4A Maximum input level for DL CA

Table 7.4A-1: Void

Table 7.4A-2: Void

7.4A.1 Maximum input level for Intra-band contiguous CA

For intra-band contiguous carrier aggregation the input level is defined as the cumulative received power, summed over the transmission bandwidth configurations of each active DL CC. All DL CCs shall be active throughout the test. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. At the maximum input level, the specified relative throughput shall meet or exceed the minimum requirements for the specified reference measurement channel over each component carrier. The minimum requirement is specified in Table 7.4A-1.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Rx Parameter	Units	Level			
Power summed over transmission bandwidth	dBm	-25 (NOTE 2)			
configurations of all active DL CCs		-27 (NOTE 3)			
NOTE 1: The transmitter shall be set to 4 dB below the PUMAX,f,c as defined in clause 6.2.4, with					
uplink configuration specified in Table 7.3.2.1-2					
NOTE 2: Reference measurement channel in	NOTE 2: Reference measurement channel in each CC is specified in Annex A.3.3.2: QPSK, R=1/3				
variant with one sided dynamic OCNG Pattern as described in Annex A.					
NOTE 3: Reference measurement channel is specified in Annex A.3.3.5: 256QAM, R=4/5 variant					
with one sided dynamic OCNG Pattern as described in Annex A.					

Table 7.4A.1-1: Maximum input level for Intra-band contiguous CA

7.4A.2 Maximum input level for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation the requirement of section 7.4A.1 applies

7.4A.3 Maximum input level for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the maximum input level is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.4 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.4A.1 and 7.4A.2 for each band while all downlink carriers are active.

7.4D Void

7.5 Adjacent channel selectivity

Adjacent Channel Selectivity (ACS) is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an adjacent channel signal at a given frequency offset from the centre frequency of the assigned channel. ACS is the ratio of the receive filter attenuation on the assigned channel frequency to the receive filter attenuation on the adjacent channel(s).

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

The UE shall fulfil the minimum requirement specified in Table 7.5-1 for all values of an adjacent channel interferer up to -25 dBm. However, it is not possible to directly measure the ACS, instead the lower and upper range of test parameters are chosen in Table 7.5-2 and Table 7.5-3 where the throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2, with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Operating band	Units	Adjacent channel selectivity / Channel bandwidt			
		50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n261	dB	23	23	23	23
n259, n260	dB	22	22	22	22

Table 7.5-1: Adjacent channel selectivity

Rx Parameter	Units	Channel bandwidth				
		50 MHz	100 MHz	200 MHz	400 MHz	
Power in	dBm		REFSENS + 14 dB			
Transmission						
Bandwidth						
Configuration	alDura	DEFOENO		DEECENO	DEESENIS	
Pinterferer for	dBm	REFSENS		REFSENS	REFSENS	
band n257, n258, n261		+ 35.5 dB	+35.5 dB	+35.5 dB	+35.5 dB	
PInterferer for	dBm	REFSENS	REFSENS	REFSENS	REFSENS	
band n259,		+ 34.5 dB	+34.5 dB	+34.5 dB	+34.5 dB	
n260						
BWInterferer	N _{Interferer} MHz 50 100 200 400					
FInterferer (offset)	MHz 50 100 200 400					
		-50	-100	-200	-400	
		NOTE 3	NOTE 3	NOTE 3	NOTE 3	
				nannel specified in Anne:		
dynamic OCNG Pattern as described in Annex A.3.2 and set-up according to Annex C.						
NOTE 2: The REFSENS power level is specified in Clause 7.3.2, which are applicable to different UE power classes.						
NOTE 3: The absolute value of the interferer offset FInterferer (offset) shall be further adjusted to (CEIL(FInterferer /SCS)						
	+ 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer					
	have sam					
		shall be set to 4 dB be e 7.3.2.1-2.	elow the PUMAX,f,c as	defined in clause 6.2.4,	with uplink configuration	
specin		C 1.J.Z. 1-Z.				

Table 7.5-2: Adjacent channel selectivity test parameters, Case 1

Table 7.5-3: Adjacent channel selectivity test parameters, Case 2

Rx Parameter	Units	Channel bandwidth				
		50 MHz	100 MHz	200 MHz	400 MHz	
Power in Transmission Bandwidth Configuration for band n257, n258, n261	dBm	-46.5	-46.5	-46.5	-46.5	
Power in Transmission Bandwidth Configuration for band n259, n260	dBm	-45.5	-45.5	-45.5	-45.5	
PInterferer	dBm			-25		
BWInterferer	MHz	50	100	200	400	
F _{Interferer} (offset)	MHz	50 / -50 NOTE 2	100 / -100 NOTE 2	200 / -200 NOTE 2	400 / -400 NOTE 2	
 NOTE 1: The interferer consists of the Reference measurement channel specified in Annex 3.2 with one sided dynamic OCNG Pattern TDD as described in Annex A and set-up according to Annex C. NOTE 2: The absolute value of the interferer offset F_{Interferer} (offset) shall be further adjusted to (CEIL(F_{Interferer} /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS. NOTE 3: The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2. 						

7.5A Adjacent channel selectivity for DL CA

Table 7.5A-1: Void

Table 7.5A-2: Void

Table 7.5A-3: Void

7.5A.1 Adjacent channel selectivity for Intra-band contiguous CA

For intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. The UE shall fulfil the minimum requirement specified in Table 7.5A.1-1 for an adjacent channel interferer on either side of the aggregated downlink signal at a specified frequency offset and for an interferer power up to -25 dBm.

The throughput of each carrier shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.5A.1-1: Adjacent channel selectivity for intra-band contiguous CA

Operating band	Units	Adjacent channel selectivity / CA bandwidth class All CA bandwidth class
n257, n258, n261	dB	23
n259, n260	dB	22

Table 7.5A.1-2: Adjacent channel selectivity test parameters for intra-band contiguous CA, Case 1

Rx Parameter	Units	All CA bandwidth Classes			
Pw in Transmission Bandwidth		REFSENS + 14 dB			
Configuration, per CC					
PInterferer for band n257, n258, n261	dBm	Aggregated power + 21.5			
PInterferer for band n259, n260	dBm	Aggregated power + 20.5			
BWInterferer	MHz	BW _{Channel_CA}			
FInterferer (offset)	MHz				
		+ BWchannel CA			
		/			
		- BW _{channel} CA			
		NOTE 3			
		measurement channel specified in Annex			
,	CNG Patte	rn as described in Annex A and set-up			
according to Annex C.	~	protion botwoon the contex of the			
	TE 2: The Finterferer (offset) is the frequency separation between the center of the				
	aggregated CA bandwidth and the center frequency of the Interferer signal				
	3: The absolute value of the interferer offset $F_{Interferer}$ (offset) shall be further adjusted to				
	(CEIL(F _{Interferer} //SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the carrier closest to the interferer in MHz. The interfering signal has the same SCS as				
that of the closest corrier.					
IOTE 4: The transmitter shall be set to 4 dB below the PUMAX, f,c as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.					

Rx Parameter	Units	All CA bandwidth classes					
Pw in Transmission Bandwidth Configuration,	dBm	- 46.5					
aggregated power for band n257, n258, n261							
Pw in Transmission Bandwidth Configuration,	dBm	- 45.5					
aggregated power for band n259, n260							
Pinterferer	dBm	- 25					
BWInterferer	MHz	BWChannel_CA					
F _{Interferer} (offset)	MHz	+ BW _{channel CA}					
		/					
		- BW _{channel} CA					
	NOTE 3						
	NOTE 1: The interferer consists of the Reference measurement channel specified in Annex						
A.3.3.2 with one sided dynamic OCN		1 TDD as described in Annex					
A.5.2.1 and set-up according to Anne							
NOTE 2: The Finterferer (offset) is the frequency							
aggregated CA bandwidth and the ce							
NOTE 3: The absolute value of the interferer offset FInterferer (offset) shall be further adjusted to							
(CEIL(FInterferer /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the							
carrier closest to the interferer in MHz. The interfering signal has the same SCS as							
that of the closest carrier.							
NOTE 4: The transmitter shall be set to 4 dB below the PUMAX, f, c as defined in clause 6.2.4,							
with uplink configuration specified in	Table 7.3.2.1-2	2.					

Table 7.5A.1-3: Adjace	nt channel selectivit	ty test parameters	for intra-band co	ntiquous CA, Case 2

7.5A.2 Adjacent channel selectivity for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation with two component carriers, two different requirements apply for out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier as specified in clauses 7.5. For in-gap, the requirement applies if the following minimum gap condition is met:

$$\Delta f_{ACS} \geq \mathbf{BW}_1/2 + \mathbf{BW}_2/2 + \max(\mathbf{BW}_1, \mathbf{BW}_2),$$

where Δf_{ACS} is the frequency separation between the center frequencies of the component carriers and BW_k are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirements specified in clauses 7.5 for each component carrier considered. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met.

For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active and the input power shall be distributed among the active DL CCs so their PSDs are aligned with each other.

7.5A.3 Adjacent channel selectivity for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the adjacent channel requirements are defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.5 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clauses 7.5A.1 and 7.5A.2 for each band while all downlink carriers are active.

7.5D Void

7.6 Blocking characteristics

7.6.1 General

The blocking characteristic is a measure of the receiver's ability to receive a wanted signal at its assigned channel frequency in the presence of an unwanted interferer on frequencies other than those of the spurious response or the adjacent channels, without this unwanted input signal causing a degradation of the performance of the receiver beyond a specified limit. The blocking performance shall apply at all frequencies except those at which a spurious response occurs.

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

7.6.2 In-band blocking

In-band blocking is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel.

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Rx parameter	Units	Channel bandwidth			
		50 MHz	100 MHz	200 MHz	400 MHz
Power in	dBm		REFSEN	S + 14 dB	
Transmission					
Bandwidth					
Configuration					
BWInterferer	MHz	50	100	200	400
PInterferer	dBm	REFSENS + 35.5	REFSENS + 35.5	REFSENS + 35.5	REFSENS + 35.5
for bands n257,		dB	dB	dB	dB
n258, n261					
PInterferer	dBm	REFSENS + 34.5	REFSENS + 34.5	REFSENS + 34.5	REFSENS + 34.5
for band n259,		dB	dB	dB	dB
n260					
Floffset	MHz	≤ -100 & ≥ 100	≤ -200 & ≥ 200	≤ -400 & ≥ 400	≤ -800 & ≥ 800
		NOTE 5	NOTE 5	NOTE 5	NOTE 5
FInterferer	MHz	F _{DL_low} + 25	F _{DL_low} + 50	F _{DL_low} + 100	F _{DL_low} + 200
		to	to	to	to
		F _{DL_high} - 25	F _{DL_high} - 50	F _{DL_high} - 100	F _{DL_high} - 200
			measurement channel		
			escribed in Annex A.5.2		
		ower level is specified i	n Clause 7.3.2, which a	are applicable according	g to different UE
power of					
	3: The wanted signal consists of the reference measurement channel specified in Annex A.3.3.2 with one				
	sided dynamic OCNG pattern OP.1 TDD as described in Annex A.5.2.1 and set-up according to Annex C.				
	Floffset is the frequency separation between the center of the channel bandwidth and the center frequency of				
	the Interferer signal.				
	The absolute value of the interferer offset Floffset shall be further adjusted (CEIL(FInterferer /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same				
	th SCS the	e sub-carrier spacing of	f the wanted signal in N	IHz. Wanted and interfe	erer signal have same
SCS.		·····	deter distante de sin er di		
			ulated interfering signal		
	The transmitter shall be set to 4 dB below the PUMAX, f,c as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.				
specifie	a in Table	1.3.Z.1-Z.			

Table 7.6.2-1: In band blocking requirements

- 7.6.3 Void
- 7.6A Blocking characteristics for DL CA
- 7.6A.1 General
- 7.6A.2 In-band blocking

Table 7.6A.2-1: Void

Table 7.6A.2-2: Void

7.6A.2.1 In-band blocking for Intra-band contiguous CAFor intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. The UE shall fulfil the minimum requirement specified in Table 7.6A.2-1 for in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel and an interferer power shall not exceed -25 dBm. The throughput of each carrier shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Rx Parameter	, Units	All CA bandwidth classes				
Power in dBm		REFSENS + 14 dB				
Transmissio	n					
Bandwidth						
Configuratio	n,					
per CC						
Pinterferer f	or dBm	Aggregated power + 21.5 dB				
band n257,						
n258, n261 Pinterferer fe	or dBm	Aggregated power + 20.5 dB				
band n260	ubiii	Aggregated power + 20.0 db				
BWInterferer	MHz	BWChannel CA				
Floffset	MHz					
		+2*BW _{Channel_CA} / -2*BW _{Channel_CA}				
NOTE 5		NOTE 5				
FInterferer	MHz	F _{DL_low} + 0.5*BW _{Channel_CA}				
		То				
		FDL_high - 0.5*BWChannel_CA				
		onsists of the Reference measurement channel specified in				
		vith one sided dynamic OCNG Pattern OP.1 TDD as described in				
		and set-up according to Annex C.				
		power level is specified in Table 7.3.2-1.				
		nal consists of the reference measurement channel specified in QPSK, R=1/3 with one sided dynamic OCNG pattern OP.1 TDD as				
		nex A.5.2.1 and set-up according to Annex C.				
		set) is the frequency separation between the center of the				
	aggregated CA bandwidth and the center frequency of the Interferer signal.					
	5: The absolute value of the interferer offset F _{Interferer} (offset) shall be further adjusted to					
	(CEIL(FInterferer /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the					
	carrier closest to the interferer in MHz. The interfering signal has the same SCS as					
	that of the closest carrier.					
		alues for unwanted modulated interfering signals are interferer center				
	equencies.	shall be ast to 4 dD below the D				
		shall be set to 4 dB below the $P_{UMAX,f,c}$ as defined in clause 6.2.4, guration specified in Table 7.3.2.1.2				
W	nui upiink confi	guration specified in Table 7.3.2.1-2.				

7.6A.2.2 In-band blocking for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation with two component carriers, the requirement applies to out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier with parameters as specified in 7.6.2-1. The requirement associated to the maximum channel between across the component carriers is selected. For in-gap, the requirement shall apply if the following minimum gap condition is met:

$$\Delta f_{IBB} \ge 0.5(BW_1 + BW_2) + 2 \max(BW_1, BW_2),$$

where Δf_{IBB} is the frequency separation between the center frequencies of the component carriers and BW_k are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirement specified in Table 7.6.2-1 for each component carrier. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met. For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active and the input power shall be distributed among the active DL CCs so their PSDs are aligned with each other.

7.6A.2.3 In-band blocking for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the in-band blocking requirements are defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.6.2 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clauses 7.6A.2.1 and 7.6A.2.2 for each band while all downlink carriers are active.

7.6D \	/oid
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7.	7	Vo	bic

7.8 Void

7.9 Spurious emissions

The spurious emissions power is the power of emissions generated or amplified in a receiver. The spurious emissions power level is measured as TRP.

The power of any narrow band CW spurious emission shall not exceed the maximum level specified in Table 7.9-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Table 7.9-1: General receiver spurious emission requirements

Frequency range	Measurement bandwidth	Maximum level	NOTE							
30MHz ≤ f < 1GHz	100 kHz	-57 dBm	1							
$1 GHz \le f \le 2^{nd}$ harmonic of the upper frequency edge of the DL operating band in GHz	1 MHz	-47 dBm								
NOTE 1: Unused PDCCH resources are padded with resource element groups with power level given by PDCCH as defined in Annex C.3.1.										

7.10 Void

Annex A (normative): Measurement channels

- A.1 General
- A.2 UL reference measurement channels
- A.2.1 General
- A.2.2 Void

A.2.3 Reference measurement channels for TDD

For UL RMCs defined below, TDD slot pattern defined in Table A.2.3-1 will be used for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, TDD slot patterns defined for reference sensitivity tests in Table A.3.3.1-1 will be used.

	Parameter	Va	lue	
		SCS 60 kHz	SCS 120 kHz	
		(µ=2)	(µ=3)	
TDD Slot C	Configuration pattern (Note 1)	DDDSUUUU	7DS8U	
Special	Slot Configuration (Note 2)	S=4D+6G+4U	S=12D+2G	
refer	enceSubcarrierSpacing	60 kHz	120 kHz	
UL-DL configuration	dl-UL-TransmissionPeriodicity	2 ms	2 ms	
	nrofDownlinkSlots	3	7	
	nrofDownlinkSymbols	4	12	
	nrofUplinkSlot	4	8	
	nrofUplinkSymbols	4	0	
Ind	lexes of active UL slots	mod(slot index, 40) = {36,,39}	mod(slot index, 80) = {72,,79}	
symbols	s a slot with a mix of The field is for inforn pectively. The field is	nation.		

Table A.2.3-1: Additional reference channels	parameters for TDD
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A.2.3.1 DFT-s-OFDM Pi/2-BPSK

Paramete	r Allocated resource blocks (L _{CRB})	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	pi/2 BPSK	0	24	16	2	1	132	132
	16	11	pi/2 BPSK	0	504	16	2	1	2112	2112
	32	11	pi/2 BPSK	0	1032	16	2	1	4224	4224
	64	11	pi/2 BPSK	0	2024	16	2	1	8448	8448
	128	11	pi/2 BPSK	0	3976	24	2	2	16896	16896
	256	11	pi/2 BPSK	0	7944	24	2	3	33792	33792
	DM-RS positio	ons are set to	nd single-syml symbols 2, 7,	11. DMRS	is [TDM'ed]					
NOTE 2:			CS table 6.1.4.							
NOTE 3:	If more than one Code Block is present, an additional CRC sequence of $L = 24$ Bits is attached to each Code Block (otherwise $L = 0$ Bit)									
NOTE 4:	requiring at lea	ast one sub f	are given by Ta rame (1ms) for g mod(slot inde	the measu	rement peri	od. For other	requiremer	nts, indexes	of active UL	

NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB.}

Table A.2.3.1-2: Void

A.2.3.2 DFT-s-OFDM QPSK

Table A.2.3.2-1: Reference Channels for DFT-s-OFDM QPSK

Parameter	Allocated resource blocks (L _{CRB)}	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	QPSK	2	48	16	2	1	264	132
	16	11	QPSK	2	808	16	2	1	4224	2112
	20	11	QPSK	2	1032	16	2	1	5280	2640
	32	11	QPSK	2	1608	16	2	1	8448	4224
	64	11	QPSK	2	3240	16	2	1	16896	8448
	128	11	QPSK	2	6408	24	2	2	33792	16896
	256	11	QPSK	2	12808	24	2	4	67584	33792
NOTE 2: N	M-RS positio	ns are set to based on MC	and single-syml symbols 2, 7, CS table 6.1.4.	11. DMRS 1-1 defined	is [TDM'ed] in 38.214.	with PUSCH	data. DM-F	RS symbols	are not cou	nted.
NOTE 3: If	more than or	ne Code Blo	ck is present, a	in additiona	I CRC sequ	ence of $L = 24$	4 Bits is att	ached to ea	ch Code Blo	ock

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
 NOTE 5: The PMCs apply to all channel handwidth where Leas 5 Mas.

NOTE 5: The RMCs apply to all channel bandwidth where $L_{CRB} \le N_{RB}$.

Table A.2.3.2-2: Void

A.2.3.3 DFT-s-OFDM 16QAM

Table A.2.3.3-1: Reference	Channels for DF	T-s-OFDM 16QAM
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Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	16QAM	10	176	16	2	1	528	132
	16	11	16QAM	10	2792	16	2	1	8448	2112
	32	11	16QAM	10	5632	24	1	1	16896	4224
	64	11	16QAM	10	11272	24	1	2	33792	8448
	128	11	16QAM	10	22536	24	1	3	67584	16896
	256	11	16QAM	10	45096	24	1	6	135168	33792
NOTE 2: NOTE 3:	DM-RS positio MCS Index is I f more than or	ons are set to based on MO ne Code Blo	and single-syml o symbols 2, 7, CS table 6.1.4. ck is present, a	11. DMRS 1-1 defined	is [TDM'ed] in 38.214.	with PUSCH	data. DM-F	RS symbols	are not cou	nted.
NOTE 4:		ive UL slots	are given by Ta rame (1ms) for							

given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.3-2: Void

A.2.3.4 DFT-s-OFDM 64QAM

Table A.2.3.4-1: Reference Channels for DFT-s-OFDM 64QAM

Paramete	r Allocated resource blocks (L _{CRB)}	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	64QAM	18	408	16	2	1	792	132
	16	11	64QAM	18	6400	24	1	1	12672	2112
	32	11	64QAM	18	12808	24	1	2	25344	4224
	64	11	64QAM	18	25608	24	1	4	50688	8448
	128	11	64QAM	18	51216	24	1	7	101376	16896
	256	11	64QAM	18	102416	24	1	13	202752	33792
NOTE 2:	DM-RS position MCS Index is I If more than or	ons are set to based on MO ne Code Blo	and single-syml symbols 2, 7, CS table 6.1.4. ck is present, a	11. DMRS 1-1 defined	is [TDM'ed] in 38.214.	with PUSCH	data. DM-F	RS symbols	are not cou	nted.
	If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit) Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1. The RMCs apply to all channel bandwidth where $L_{CRB} \le N_{RB}$.									

Table A.2.3.4-2: Void

A.2.3.5 CP-OFDM QPSK

Paramete	r Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	QPSK	2	48	16	2	1	264	132
	16	11	QPSK	2	808	16	2	1	4224	2112
	32	11	QPSK	2	1608	16	2	1	8448	4224
	33	11	QPSK	2	1672	16	2	1	8712	4356
	66	11	QPSK	2	3368	16	2	1	17424	8712
	132	11	QPSK	2	6536	24	2	2	34848	17424
	264	11	QPSK	2	13064	24	2	4	69696	34848
NOTE 1:			and single-syml symbols 2, 7,							
-			CS table 5.1.3.							
NOTE 3:	If more than or (otherwise L =		ck is present, a	n additiona	I CRC sequ	ence of $L = 2$	4 Bits is att	ached to ea	ch Code Blo	ock
NOTE 5:	The RMCs ap	oly to all cha	nnel bandwidth	where L _{CR}	Β≤ N _{RB.}	C C	-			

Table A.2.3.5-1: Reference Channels for CP-OFDM QPSK

Table A.2.3.5-2: Void

A.2.3.6 CP-OFDM 16QAM

Parameter	Allocated resource blocks (L _{CRB)}	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	16QAM	10	176	16	2	1	528	132
	16	11	16QAM	10	2792	16	2	1	8448	2112
	32	11	16QAM	10	5632	24	1	1	16896	4224
	33	11	16QAM	10	5760	24	1	1	17424	4356
	66	11	16QAM	10	11528	24	1	2	34848	8712
	132	11	16QAM	10	23040	24	1	3	69696	17424
	264	11	16QAM	10	46104	24	1	6	139392	34848
NOTE 1: P	USCH mappi	ing Type-A a	and single-sym	bol DM-RS	configuratio	on Type-1 with	2 addition	al DM-RS sy	mbols, suc	h that the
D	M-RS positio	ons are set to	symbols 2, 7,	11. DMRS	is [TDM'ed]	with PUSCH	data. DM-F	RS symbols	are not cou	nted.
NOTE 2: M	ICS Index is I	based on M	CS table 5.1.3.	1-1 defined	in 38.214.			-		
NOTE 3: If	more than or	ne Code Blo	ck is present, a	n additiona	I CRC sequ	ence of $L = 2$	4 Bits is att	ached to ea	ch Code Blo	ock
(0	otherwise L =	0 Bit)			-					

NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

NOTE 5: The RMCs apply to all channel bandwidth where $L_{CRB} \le N_{RB}$.

Table A.2.3.6-2: Void

A.2.3.7 CP-OFDM 64QAM

Table A.2.3.7-1: Reference	Channels for	CP-OFDM 64QAM
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Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	64QAM	19	408	16	2	1	792	132
	16	11	64QAM	19	6400	24	1	1	12672	2112
	32	11	64QAM	19	12808	24	1	2	25344	4224
	33	11	64QAM	19	13064	24	1	2	26136	4356
	66	11	64QAM	19	26120	24	1	4	52272	8712
	132	11	64QAM	19	53288	24	1	7	104544	17424
	264	11	64QAM	19	106576	24	1	13	209088	34848
NOTE 2: NOTE 3:	DM-RS positio MCS Index is I	ons are set to based on MO ne Code Blo	nd single-syml symbols 2, 7, CS table 5.1.3. ck is present, a	11. DMRS 1-1 defined	is [TĎM'ed] in 38.214.	with PUSCH	data. DM-F	RS symbols	are not cou	nted.

NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
 NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.7-2: Void

A.3 DL reference measurement channels

A.3.1 General

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 are applicable for measurements of the Receiver Characteristics (clause 7).

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 also apply for the modulated interferer used in Clauses 7.5 and 7.6 with test specific bandwidths.

CSI-RS configuration parameter defined in Table A.3.1-2 and Table A.3.1-3 are used for verifying the beam correspondence requirement, 2 slots of CSI-RS shall be provided at each test grid point. The DL channel shall be configured for zero power on all tones except those used by CSI-RS in slots containing CSI-RS for beam refinement, and the DL and UL channel sizes shall be the same during verification.

Para	Parameter		Value
CORESET frequency domain allocation			Full BW
CORESET time	CORESET time domain allocation		2 OFDM symbols at the begin of each slot
PDSCH m	apping type		Туре А
PDSCH start s	symbol index (S)		2
Number of consecutiv	e PDSCH symbols (L)		12
PDSCH PI	RB bundling	PRBs	2
Dynamic P	RB bundling		false
MCS table for T	BS determination		64QAM
Overhead value fo	r TBS determination		0
First DMRS position for	Type A PDSCH mapping		2
DMR	S type		Type 1
Number of ac	Iditional DMRS		2
FDM between D	FDM between DMRS and PDSCH		Disable
CSI-RS for tracking	First subcarrier index in the PRB used for CSI-RS (k0)		0 for CSI-RS resource 1,2
	OFDM symbols in the PRB used for CSI-RS		$I_0 = 8$ for CSI-RS resource 1 $I_0 = 12$ for CSI-RS resource 2
	Number of CSI-RS ports		1 for CSI-RS resource 1,2
	CDM Type		'No CDM' for CSI-RS resource 1,2
	Density (p)		3 for CSI-RS resource 1,2
	CSI-RS periodicity	Slots	60 kHz SCS: 80 for CSI-RS resources 1 and 2 120 kHz SCS: 160 for CSI-RS resources 1 and 2
	CSI-RS offset	Slots	60 kHz SCS: 40 for CSI-RS resources 1 and 2 120kHz SCS: 80 for CSI-RS resources 1 and 2
	Frequency Occupation		Start PRB 0 Number of PRB = BWP size
	QCL info		TCI state #0
PTRS co	nfiguration		PTRS is not configured

Table A.3.1-1: Test parameters

Resource Type	aperiodic
Resource Set Config	•
repetition	on
aperiodicTriggeringOffset	Depending on UE capability
Resource Config	
nzp-CSI-RS-Resourceld	30 for resource #0
	31 for resource #1
	32 for resource #2
	33 for resource #3
	34 for resource #4
	35 for resource #5
	36 for resource #6
	37 for resource #7
powerControlOffset	0
powerControlOffsetSS	db0
nrofPorts	1
firstOFDMSymbolInTimeDomain	6 for resource #0
	7 for resource #1
	8 for resource #2
	9 for resource #3
	10 for resource #4
	11 for resource #5
	12 for resource #6
	13 for resource #7
cdm-Type	noCDM
density	3
nrofRBs	48 for channel
	bandwidth≥100MHz
	32 for channel
	bandwidth=50MHz
qcl-info	Type D to SSB

Table A.3.1-2: CSI-RS parameters for beam correspondence based on SSB and CSI-RS

CSI-RS configuration parameter defined in Table A.3.1-3 is used for verifying the beam correspondence requirement, CSI-RS shall be provided once every 10msec.

Resource Type	aperiodic
Resource Set Config	·
repetition	on
aperiodicTriggeringOffset	Depending on UE capability
Resource Config	
nzp-CSI-RS-ResourceId	30 for resource #0
	31 for resource #1
	32 for resource #2
	33 for resource #3
	29+N for resource #(N-1), where N is maxNumberRxBeam in UE capability IE of
	MIMO-ParametersPerBand
powerControlOffset	0
powerControlOffsetSS	db0
nrofPorts	1
firstOFDMSymbolInTimeDomain	6 for resource #0
	7 for resource #1
	8 for resource #2
	9 for resource #3
	5+N for resource #(N-1), where N=maxNumberRxBeam-1 in UE capability IE of
	MIMO-ParametersPerBand
cdm-Type	noCDM
density	3
nrofRBs	48 for channel bandwidth≥100MHz
	32 for channel bandwidth=50MHz
qcl-info	Type D to SSB

A.3.2 Void

A.3.3 DL reference measurement channels for TDD

A.3.3.1 General

	Parameter	Va	lue	
		SCS 60 kHz (µ=2)	SCS 120 kHz (µ=3)	
TDD Slot Conf	iguration pattern (Note 1)	DDDSU DDDSU		
Special Slot	Configuration (Note 2)	S=4D+6G+4U	S=10D+2G+2U	
reference	eSubcarrierSpacing	60 kHz	120 kHz	
UL-DL	dI-UL-	1.25 ms	0.625 ms	
configuration	TransmissionPeriodicity			
-	nrofDownlinkSlots	3	3	
	nrofDownlinkSymbols	4	10	
	nrofUplinkSlot	1	1	
	nrofUplinkSymbols	4	2	
Number	of HARQ Processes	8 8		
The number of	slots between PDSCH and	K1 = 4 if mod(i,5) = 0	K1 = 4 if mod(i,5) = 0	
corresponding HA	RQ-ACK information (Note 3)	K1 =3 if mod(i,5) = 1	K1 =3 if mod(i,5) = 1	
		K1 =7 if mod(i,5) = 2	K1 =7 if mod(i,5) = 2	
		where i is slot index per frame;	where i is slot index per frame;	
		i = {0,,39}	i = {0,,79}	
		enotes a slot with a mix of DL, UL	and guard symbols; U denotes	
	h all UL symbols. The field is for			
		ls, respectively. The field is for info	ormation.	
NOTE 3: i is the slo	ot index per frame.			

Table A.3.3.1-1. Additional test parameters for TDD

A.3.3.2 FRC for receiver requirements for QPSK

	Parameter	Unit		Value	
	Channel bandwidth	MHz	50	100	200
Subc	arrier spacing configuration μ		2	2	2
ŀ	Allocated resource blocks		66	132	264
	ocarriers per resource block		12	12	12
Alloca	ated slots per Frame (NOTE 7)		23 /24	23 / 24	23 / 24
	MCS index		4	4	4
	Modulation		QPSK	QPSK	QPSK
	Target Coding Rate		1/3	1/3	1/3
	n number of HARQ transmissions		1	1	1
	rmation Bit Payload per Slot				
	0 and Slot i, if mod(i, 5) = {3,4} for from {0,,79} (NOTE 5)	Bits	N/A	N/A	N/A
	t i, if mod(i, 5) = {0,1,2} for i from {1,,79} (NOTE 6)	Bits	4224	8456	16896
	Transport block CRC	Bits	24	24	24
	LDPC base graph		1	1	1
Nun	nber of Code Blocks per Slot				
	0 and Slot i, if mod(i, 5) = {3,4} for from {0,,79} (NOTE 5)	CBs	N/A	N/A	N/A
For Slot	t i, if mod(i, 5) = {0,1,2} for i from {1,,79} (NOTE 6)	CBs	1	2	3
	nary Channel Bits Per Slot				
	0 and Slot i, if mod(i, 5) = {3,4} for from {0,,79} (NOTE 5)	Bits	N/A	N/A	N/A
	t i, if mod(i, 5) = {0,1,2} for i from {1,,79} (NOTE 6)	Bits	14256	28512	57024
Max. Th	roughput averaged over 1 frame (NOTE 8)	Mbps	10.138	20.294	40.550
NOTE 2: NOTE 3: NOTE 4:	Additional parameters are specifie If more than one Code Block is pre- is attached to each Code Block (of SS/PBCH block is transmitted in si Slot i is slot index per 2 frames When this DL RMC used together requiring at least one sub frame (1 (2,45,6,7) for i fram (0, -70)	esent, an add therwise L = 0 lot 0 with peri with the UL F ms) for the m	itional CRC s) Bit). odicity 20 ms RMC for the the neasurement	sequence of s ransmitter re period, Slot	L = 24 Bits quirements i, if mod(i,
 8) = {3,4,5,6,7} for i from {0,,79} together with the TDD UL-DL configuration specified in A2.3. NOTE 6: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 8) = {0,1,2} for i from {0,,79} together with the TDD UL-DL configuration specified in A2.3. 					
NOTE 7:	RMC; second number correspond frame of the RMC.	s to the numb	er slots alloc		
NOTE 8:	Throughput is averaged over 2nd	frame of RMC).		

Table A.3.3.2-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit	t Value				
Channel bandwidth	MHz	50	100	200	400	
Subcarrier spacing configuration μ		3	3	3	3	
Allocated resource blocks		32	66	132	264	
Subcarriers per resource block		12	12	12	12	
Allocated slots per Frame (NOTE 7)		47 / 48	47 / 48	47 / 48	47 / 48	
MCS index		4	4	4	4	
Modulation		QPSK	QPSK	QPSK	QPSK	
Target Coding Rate		1/3	1/3	1/3	1/3	
Maximum number of HARQ transmissions		1	1	1	1	
Information Bit Payload per Slot						
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	Bits	N/A	N/A	N/A	N/A	
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	Bits	2088	4224	8456	16896	
Transport block CRC	Bits	16	24	24	24	
LDPC base graph		2	1	1	1	
Number of Code Blocks per Slot						
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	CBs	N/A	N/A	N/A	N/A	
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	CBs	1	1	2	3	
Binary Channel Bits Per Slot						
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	Bits	N/A	N/A	N/A	N/A	
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	Bits	6912	14256	28512	57024	
Max. Throughput averaged over 1 frame (NOTE 8)	Mbps	10.022	20.275	40.589	81.101	
 NOTE 1: Additional parameters are specifie NOTE 2: If more than one Code Block is proattached to each Code Block (othe NOTE 3: SS/PBCH block is transmitted in s NOTE 4: Slot i is slot index per 2 frames NOTE 5: When this DL RMC used together at least one sub frame (1ms) for th from {0,,159} together with the T NOTE 6: When this DL RMC used together at least one sub frame (1ms) for th from {0,,159} together with the T 	esent, an addi erwise L = 0 B slot 0 with peri with the UL R ne measureme TDD UL-DL co with the UL R ne measureme	itional CRC : Bit). odicity 20 m RMC for the t ent period, S onfiguration : RMC for the t ent period, S	sequence of s ransmitter r Slot i, if mode specified in ransmitter r slot i, if mode	f L = 24 Bits equirements (i, 16) = {7, A2.3. equirements (i, 16) = {0,	s requiring .,15} for i s requiring	
NOTE 7: First number corresponds to the n number corresponds to the number NOTE 8: Throughput is averaged over 2nd	umber slots a er slots allocat	llocated in th ted in the se	ne first frame	e of the RMC		

Table A.3.3.2-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

A.3.3.3 FRC for receiver requirements for 16QAM

A.3.3.4 FRC for receiver requirements for 64QAM

Unit		Value	
MHz	50	100	200
	2	2	2
	66	132	264
	12	12	12
	23 / 24	23 / 24	23 / 24
	19	19	19
	64QAM	64QAM	64QAM
	1/2	1/2	1/2
	1	1	1
Bits	N/A	N/A	N/A
Bits	20496	40976	81976
Bits	24	24	24
	1	1	1
CBs	N/A	N/A	N/A
CBs	3	5	10
			N/A
	40392	80784	161568
Mbps	49.190	98.343	196.742
esent, an add therwise L = (lot 0 with peri ontaining PDS ime domain. (umber slots a	itional CRC s) Bit). odicity 20 ms CH with 1 pc Overhead for Illocated in th	equence of ort, per 2PRE TBS calcula e first frame	L = 24 Bits 3 in ation is of the
	MHz MHz Bits Bits Bits CBs CBs CBs CBs CBs CBs d in Table A.3 esent, an add therwise L = 0 lot 0 with peri ontaining PDS ime domain. 0 umber slots a	MHz 50 2 66 12 23 / 24 19 64QAM 1/2 1 Bits N/A Bits 20496 Bits 24 1 1 CBs N/A Bits 24 1 1 CBs N/A Bits 40392 Mbps 49.190 d in Table A.3.1-1 and Tallesent, an additional CRC stherwise L = 0 Bit). Iot 0 with periodicity 20 ms Domtaining PDSCH with 1 pc ime domain. Overhead for umber slots allocated in th	MHz 50 100 2 2 2 66 132 12 12 12 12 23 / 24 23 / 24 23 / 24 19 19 19 64QAM 64QAM 1/2 1/2 1 1 Bits N/A N/A Bits 20496 40976 Bits 24 24 1 1 1 CBs N/A N/A CBs 3 5 Bits N/A N/A Bits 40392 80784 Mbps 49.190 98.343 d in Table A.3.1-1 and Table A.3.3.1-1 esent, an additional CRC sequence of

Table A.3.3.4-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit	Value				
Channel bandwidth	MHz	50	100	200	400	
Subcarrier spacing configuration $^{\mu}$		3	3	3	3	
Allocated resource blocks		32	66	132	264	
Subcarriers per resource block		12	12	12	12	
Allocated slots per Frame (NOTE 6)		47 / 48	47 / 48	47 / 48	47 / 48	
MCS index		19	19	19	19	
Modulation		64QAM	64QAM	64QAM	64QAM	
Target Coding Rate		1/2	1/2	1/2	1/2	
Maximum number of HARQ transmissions		1	1	1	1	
Information Bit Payload per Slot						
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	Bits	N/A	N/A	N/A	N/A	
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159}	Bits	9992	20496	40976	81976	
Transport block CRC	Bits	24	24	24	24	
LDPC base graph		1	1	1	1	
Number of Code Blocks per Slot						
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	CBs	N/A	N/A	N/A	N/A	
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159}	CBs	2	3	5	10	
Binary Channel Bits Per Slot						
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159}	Bits	N/A	N/A	N/A	N/A	
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159}	Bits	19584	40392	80784	161568	
Max. Throughput averaged over 1 frame (NOTE 7)	Mbps	47.962	98.381	196.685	393.485	
NOTE 1: Additional parameters are specifie NOTE 2: If more than one Code Block is pre attached to each Code Block (othe NOTE 3: SS/PBCH block is transmitted in s	esent, an ado erwise L = 0 I	litional CRC : Bit).			is	
NOTE 4: Slot i is slot index per frame NOTE 5: PTRS is configured on symbols co domain, per symbol in time domain	ontaining PDS	SCH with 1 p				
NOTE 6: First number corresponds to the number	umber slots a	allocated in th	ne first fram	e of the RM	C; second	

Table A.3.3.4-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

number corresponds to the number slots allocated in the second frame of the RMC. NOTE 7: Throughput is averaged over 2nd frame of RMC.

A.3.3.5 FRC for receiver requirements for 256QAM

Parameter	Unit		Value				
Channel bandwidth	MHz	50	100	200			
Subcarrier spacing configuration μ		2	2	2			
Allocated resource blocks		66	132	264			
Subcarriers per resource block		12	12	12			
Allocated slots per Frame (NOTE 6)		23 / 24	23 / 24	23 / 24			
MCS index		24	24	24			
Modulation		256QAM	256QAM	256QAM			
Target Coding Rate		4/5	4/5	4/5			
Maximum number of HARQ transmissions		1	1	1			
Information Bit Payload per Slot							
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}	Bits	N/A	N/A	N/A			
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}	Bits	44040	88064	176208			
Transport block CRC	Bits	24	24	24			
LDPC base graph		1	1	1			
Number of Code Blocks per Slot							
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}	CBs	N/A	N/A	N/A			
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}	CBs	6	11	21			
Binary Channel Bits Per Slot							
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79}	Bits	N/A	N/A	N/A			
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,79}	Bits	54648	109296	218592			
Max. Throughput averaged over 1 frame (NOTE 7)	Mbps	105.696	211.354	422.899			
 NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1. NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame NOTE 4: Slot i is slot index per 2 frames NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6. NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC. 							
NOTE 7: Throughput is averaged over 2nd frame of RMC.							

Table A.3.3.5-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

MHz	50 3 32 12 47 / 48 24	100 3 66 12 47/48	200 3 132 12 47/48	400 3 264 12
	32 12 47 / 48	66 12 47 / 48	132 12	264
	12 47 / 48	12 47 / 48	12	-
	12 47 / 48	12 47 / 48	12	-
	47 / 48	47 / 48		
	24		4//40	47 / 48
		24	24	24
	256QAM	256QAM	256QAM	256QAM
	4/5	4/5	4/5	4/5
	1	1	1	1
Bits	N/A	N/A	N/A	N/A
Bits	21504	44040	88064	176208
Bits	24	24	24	24
	1	1	1	1
CBs	N/A	N/A	N/A	N/A
CBs	3	6	11	21
Bits	N/A	N/A	N/A	N/A
Bits	26496	54648	109296	218592
Mbps	103.219	211.392	422.707	845.798
sent, an addi rwise L = 0 B ot 0 of each f ntaining PDS i. Overhead f imber slots al r slots allocat	tional CRC s it). rame CH with 1 po or TBS calcu llocated in th ed in the sec	sequence of ort, per 2PR ulation is assing the first frame	L = 24 Bits B in frequer sumed to be of the RMC	ncy 6. C; second
r r r	Bits Bits CBs CBs Bits Bits Bits Mbps I in Table A.3 sent, an addi wise L = 0 B of 0 of each f ntaining PDS . Overhead f mber slots allocat	4/5 1 Bits N/A Bits 21504 Bits 24 1 1 CBs N/A CBs N/A Bits 24 1 1 CBs N/A Bits N/A Bits N/A Bits 103.219 In Table A.3.1-1 and Ta 103.219 In Table A.3.1-1 and Ta 103.219 In Table A.3.1-1 and Ta 100.219 In Table A.3.1-1 and Ta	4/5 4/5 1 1 Bits N/A N/A Bits 21504 44040 Bits 21504 44040 Bits 24 24 1 1 1 CBs N/A N/A CBs 3 6 Bits 26496 54648 Mbps 103.219 211.392 I in Table A.3.1-1 and Table A.3.3.1- sent, an additional CRC sequence of wise L = 0 Bit). ot 0 of each frame ot 0 of each frame ntaining PDSCH with 1 port, per 2PR Overhead for TBS calculation is asses mber slots allocated in the first frame slots allocated in the second frame	4/54/54/5111BitsN/AN/AN/ABits215044404088064Bits242424111CBsN/AN/AN/ACBs3611Bits2649654648109296Mbps103.219211.392422.707I in Table A.3.1-1 and Table A.3.3.1-1. sent, an additional CRC sequence of L = 24 Bits wise L = 0 Bit).experience of L = 24 Bits wise L = 0 Bit).Ntaining PDSCH with 1 port, per 2PRB in frequer . Overhead for TBS calculation is assumed to be mber slots allocated in the first frame of the RMC.

Table A.3.3.5-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

- A.4 Void
- A.5 OFDMA Channel Noise Generator (OCNG)
- A.5.1 OCNG Patterns for FDD
- A.5.2 OCNG Patterns for TDD
- A.5.2.1 OCNG TDD pattern 1: Generic OCNG TDD Pattern for all unused REs

Table A.5.2.1-1: OP.1 TDD: Generic OCNG TDD Pattern for all unused REs

OCNG Appliance OCNG Parameters	Control Region (Core Set)	Data Region		
Resources allocated	All unused REs (Note 1)	All unused REs (Note 2)		
Structure	PDCCH	PDSCH		
Content	Uncorrelated pseudo random QPSK modulated data	Uncorrelated pseudo random QPSK modulated data		
Transmission scheme for multiple antennas ports transmission	Single Tx port transmission	Spatial multiplexing using any precoding matrix with dimensions same as the precoding matrix for PDSCH		
Subcarrier Spacing	Same as for RMC PDCCH in the active BWP	Same as for RMC PDSCH in the active BWP		
Power Level	Same as for RMC PDCCH	Same as for RMC PDSCH		
Note 1: All unused REs in the active CORESETS appointed by the search spaces in use. Note 2: Unused available REs refer to REs in PRBs not allocated for any physical channels, CORESETs, synchronization signals or reference signals in channel bandwidth.				

Annex B (informative): Void

Annex C (normative): Downlink physical channels

C.1 General

C.2 Setup

Table C.2-1 describes the downlink Physical Channels that are required for connection set up.

Physical Channel
PBCH
SSS
PSS
PDCCH
PDSCH
PBCH DMRS
PDCCH DMRS
PDSCH DMRS
CSI-RS
PTRS

Table C.2-1: Downlink Physical Channels required for connection set-up

C.3 Connection

C.3.1 Measurement of Receiver Characteristics

Unless otherwise stated, Table C.3.1-1 is applicable for measurements on the Receiver Characteristics (clause 7).

	Parameter	Unit	Value			
	SSS transmit power	W	Test specific			
	EPRE ratio of PSS to SSS	dB	0			
	EPRE ratio of PBCH to SSS	dB	0			
	EPRE ratio of PBCH to PBCH DMRS	dB	0			
	EPRE ratio of PDCCH to SSS	dB	0			
	EPRE ratio of PDCCH to PDCCH DMRS	dB	0			
	EPRE ratio of PDSCH to SSS	dB	0			
	EPRE ratio of PDSCH to PDSCH DMRS (Note 1)	dB	-3			
	EPRE ratio of CSI-RS to SSS	dB	0			
	EPRE ratio of PTRS to PDSCH	dB	Test specific			
	EPRE ratio of OCNG DMRS to SSS	dB	0			
	EPRE ratio of OCNG to OCNG DMRS (Note 1) dB 0					
Note 1:	Note 1: No boosting is applied to any of the channels except PDSCH DMRS. For PDSCH DMRS, 3 dB power boosting is applied assuming DMRS Type 1 configuration when DMRS and PDSCH are TDM'ed and only half of the DMRS REs are occupied.					
Note 2:	·					

Annex D (normative): Characteristics of the interfering signal

D.1 General

Unless otherwise stated, a modulated full bandwidth NR downlink signal, which equals to channel bandwidth of the wanted signal for Single Carrier case is used as interfering signals when RF performance requirements for NR UE receiver are defined. For intra-band contiguous CA case, a modulated NR downlink signal which equals to the aggregated channel bandwidth of the wanted signal is used.

D.2 Interference signals

Table D.2-1 describes the modulated interferer for different channel bandwidth options.

	С	Intra band			
	50 MHz	100 MHz	200 MHz	400 MHz	contiguous CA
BWInterferer	50 MHz	100 MHz	200 MHz	400MHz	BW _{Channel_CA}
RB	NOTE1				
NOTE 1: The RB configured for interfering signal is the same as maximum RB number					
defined in Table 5.3.2-1 for each sub-carrier spacing.					

Annex E (normative): Environmental conditions

E.1 General

This annex specifies the environmental requirements of the UE. Within these limits the requirements of the present documents shall be fulfilled.

E.2 Environmental

The requirements in this clause apply to all types of UE(s).

E.2.1 Temperature

All RF requirements for UEs operating in FR2 are defined over the air and can only be tested in an OTA chamber.

The UE shall fulfil all the requirements in the temperature range for extreme conditions, as defined in Table E.2.1-1, unless explicitly stated otherwise in any requirement.

Table E.2.1-1: Temperature conditions

+ 25 °C ± 10 °C	For normal (room temperature) conditions with relative humidity of 25 % to 75 %
-10°C to +55°C	For extreme conditions
-10 C to +33 C	T of extreme conditions

Outside this temperature range the UE, if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation.

E.2.2 Voltage

Editor's note: This requirement is incomplete. The following aspects are either missing or not yet determined:

Methodology to control the voltage in a case which a power cable is not connected to DUT is FFS since it is not agreed whether we can connect the power cable to DUT at the OTA measurement situation yet.

The UE shall fulfil all the requirements in the full voltage range, i.e. the voltage range between the extreme voltages.

The manufacturer shall declare the lower and higher extreme voltages and the approximate shutdown voltage. For the equipment that can be operated from one or more of the power sources listed below, the lower extreme voltage shall not be higher, and the higher extreme voltage shall not be lower than that specified below.

Power source	Lower extreme voltage	Higher extreme voltage	Normal conditions voltage
AC mains	0,9 * nominal	1,1 * nominal	nominal
Regulated lead acid battery	0,9 * nominal	1,3 * nominal	1,1 * nominal
Nonregulated batteries:			
Leclanché	0,85 * nominal	Nominal	Nominal
Lithium	0,95 * nominal	1,1 * Nominal	1,1 * Nominal
Mercury/nickel & cadmium	0,90 * nominal		Nominal

Table E.2.2-1: Voltage conditions

Outside this voltage range the UE if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation. In particular, the UE shall inhibit all RF transmissions when the power supply voltage is below the manufacturer declared shutdown voltage.

E.2.3 Void

Annex F (normative): Transmit modulation

F.1 Measurement Point

Figure F.1-1 shows the measurement point for the unwanted emission falling into non-allocated RB(s) and the EVM for the allocated RB(s).

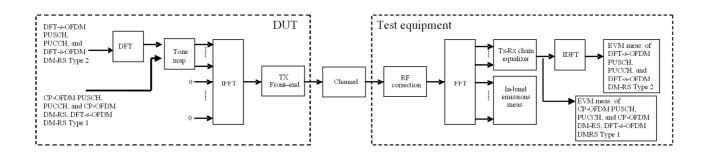


Figure F.1-1: EVM measurement points

F.2 Basic Error Vector Magnitude measurement

The EVM is the difference between the ideal waveform and the measured waveform for the allocated RB(s)

$$EVM = \sqrt{\frac{\sum_{v \in T_m} |z'(v) - i(v)|^2}{|T_m| \cdot P_0}}$$

where

 T_m is a set of $|T_m|$ modulation symbols with the considered modulation scheme being active within the measurement period,

z'(v) are the samples of the signal evaluated for the EVM,

i(v) is the ideal signal reconstructed by the measurement equipment, and

 P_0 is the average power of the ideal signal. For normalized modulation symbols P_0 is equal to 1.

The basic EVM measurement interval is defined over one slot in the time domain for PUCCH and PUSCH and over one preamble sequence for the PRACH.

F.3 Basic in-band emissions measurement

The in-band emissions are a measure of the interference falling into the non-allocated resources blocks. The in-band emission requirement is evaluated for PUCCH and PUSCH transmissions. The in-band emission requirement is not evaluated for PRACH transmissions.

The in-band emissions are measured as follows

$$Emissions_{absolute}(\Delta_{RB}) = \begin{cases} \frac{1}{|T_s|} \sum_{t \in T_s} \sum_{\substack{max(f_{\min}, f_l + 12 \cdot \Delta_{RB} + \Delta f) \\ max(f_{\min}, f_l + 12 \cdot \Delta_{RB} + \Delta f)}} |Y(t, f)|^2, \Delta_{RB} < 0\\ \frac{1}{|T_s|} \sum_{t \in T_s} \sum_{\substack{min(f_{\max}, f_h + 12 \cdot \Delta_{RB} + \Delta f) \\ f_h + (12 \cdot \Delta_{RB} - 11) + \Delta f}} |Y(t, f)|^2, \Delta_{RB} > 0 \end{cases}$$

where

 T_s is a set of $|T_s|$ OFDM symbols with the considered modulation scheme being active within the measurement period,

 Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB),

 $f_{\rm min}$ (resp. $f_{\rm max}$) is the lower (resp. upper) edge of the UL system BW,

 f_l and f_h are the lower and upper edge of the allocated BW, and

Y(t, f) is the frequency domain signal evaluated for in-band emissions as defined in the clause (ii)

The relative in-band emissions are, given by

$$Emissions_{relative}(\Delta_{RB}) = \frac{Emissions_{absolute}(\Delta_{RB})}{\frac{1}{|T_s| \cdot N_{RB}} \sum_{t \in T_s} \sum_{f_i}^{f_i + (12 \cdot N_{RB} - 1)\Delta f} |Y(t, f)|^2}$$

where

 N_{RB} is the number of allocated RBs

The basic in-band emissions measurement interval is defined over one slot in the time domain. When the PUSCH or PUCCH transmission slot is shortened due to multiplexing with SRS, the in-band emissions measurement interval is reduced by one OFDM symbol, accordingly.

In the evaluation of in-band emissions, the timing is set according to $\Delta \tilde{t} = \Delta \tilde{c}$, where sample time offsets $\Delta \tilde{t}$ and $\Delta \tilde{c}$ are defined in clause F.4.

F.4 Modified signal under test

Implicit in the definition of EVM is an assumption that the receiver is able to compensate a number of transmitter impairments.

The DFT-s-OFDM modulated signals or PRACH signal under test is modified and, in the case of DFT-s-OFDM modulated signals, decoded according to:

$$Z'(t,f) = IDFT\left\{\frac{FFT\left\{z(v-\Delta \tilde{t}) \cdot e^{-j2\pi\Delta \tilde{y}_{v}}\right\}e^{j2\pi j\Delta \tilde{t}}}{\tilde{a}(t,f) \cdot e^{j\tilde{\varphi}(t,f)}}\right\}$$

where

Z(V) is the time domain samples of the signal under test.

The CP-OFDM modulated signals or PUSCH demodulation reference signal or CP-OFDM modulated signals under test is equalised and, in the case of PUCCH data signal decoded according to:

$$Z'(t,f) = \frac{FFT\left\{z(v - \Delta \tilde{t}) \cdot e^{-j2\pi\Delta \tilde{f}v}\right\}}{\tilde{a}(t,f) \cdot e^{j\tilde{\varphi}(t,f)}}$$

where

Z(v) is the time domain samples of the signal under test.

To minimize the error, the signal under test should be modified with respect to a set of parameters following the procedure explained below.

Notation:

 $\Delta \tilde{t}$ is the sample timing difference between the FFT processing window in relation to nominal timing of the ideal signal.

 Δf is the RF frequency offset.

 $\widetilde{\varphi}(t,f)$ is the phase response of the TX chain.

 $\widetilde{a}(t, f)$ is the amplitude response of the TX chain.

In the following $\Delta \tilde{c}$ represents the middle sample of the EVM window of length W (defined in the next clauses) or the last sample of the first window half if W is even.

The EVM analyser shall

- detect the start of each slot and estimate $\Delta \tilde{t}$ and $\Delta \tilde{f}$,
- determine $\Delta \widetilde{c}$ so that the EVM window of length W is centred
 - on the time interval determined by the measured cyclic prefix minus 16κ samples of the considered OFDM symbol for symbol l for subcarrier spacing configuration μ in a subframe, with l = 0 or $l = 7*2^{\mu}$ for normal CP, i.e. the first 16κ samples of the CP should not be taken into account for this step. In the determination of the number of excluded samples, a sampling rate of $1/T_c$ is assumed. If a different sampling rate is used, the number of excluded samples is scaled linearly.
 - on the measured cyclic prefix of the considered OFDM symbol symbol for all other symbols for normal CP and for symbol 0 to 11 for extended CP.
 - on the measured preamble cyclic prefix for the PRACH

To determine the other parameters a sample timing offset equal to $\Delta \tilde{c}$ is corrected from the signal under test. The EVM analyser shall then

- correct the RF frequency offset $\Delta \widetilde{f}$ for each time slot, and

apply an FFT of appropriate size. The chosen FFT size shall ensure that in the case of an ideal signal under test, there is no measured inter-subcarrier interference.

The carrier leakage shall be removed from the evaluated signal before calculating the EVM and the in-band emissions; however, the removed relative carrier leakage power also has to satisfy the applicable requirement.

At this stage the allocated RBs shall be separated from the non-allocated RBs. In the case of PUCCH and PUSCH EVM, the signal on the non-allocated RB(s), Y(t, f), is used to evaluate the in-band emissions.

Moreover, the following procedure applies only to the signal on the allocated RB(s).

- In the case of PUCCH and PUSCH, the UL EVM analyzer shall estimate the TX chain equalizer coefficients $\widetilde{a}(t,f)$ and $\widetilde{\varphi}(t,f)$ used by the ZF equalizer for all subcarriers by time averaging at each signal subcarrier of the amplitude and phase of the reference and data symbols. The time-averaging length is 1 slot. This process creates an average amplitude and phase for each signal subcarrier used by the ZF equalizer. The knowledge of data modulation symbols may be required in this step because the determination of symbols by demodulation is not reliable before signal equalization.
- In the case of PRACH, the UL EVM analyzer shall estimate the TX chain coefficients $\tilde{a}(t)$ and $\tilde{a}(t)$ used for phase and amplitude correction and are seleted so as to minimize the resulting EVM. The TX chain coefficients are not dependent on frequency, i.e. $\widetilde{a}(t,f) = \widetilde{a}(t)$ and $\widetilde{\phi}(t,f) = \widetilde{\phi}(t)$. The TX chain coefficient are chosen independently for each preamble transmission and for each $\Delta \tilde{t}$.

At this stage estimates of $\Delta \tilde{f}$, $\tilde{a}(t,f)$, $\tilde{\varphi}(t,f)$ and $\Delta \tilde{c}$ are available. $\Delta \tilde{t}$ is one of the extremities of the window W, i.e. $\Delta \tilde{t}$ can be $\Delta \tilde{c} + \alpha - \left| \frac{W}{2} \right|$ or $\Delta \tilde{c} + \left| \frac{W}{2} \right|$, where $\alpha = 0$ if W is odd and $\alpha = 1$ if W is even.

The EVM analyser shall then

- calculate EVM₁ with
$$\Delta \tilde{t}$$
 set to $\Delta \tilde{c} + \alpha - \left\lfloor \frac{W}{2} \right\rfloor$

- calculate EVM_h with $\Delta \tilde{t}$ set to $\Delta \tilde{c} + \left| \frac{W}{2} \right|$.

Window length F 5

F.5.1 Timing offset

As a result of using a cyclic prefix, there is a range of $\Delta \tilde{t}$, which, at least in the case of perfect Tx signal quality, would give close to minimum error vector magnitude. As a first order approximation, that range should be equal to the length of the cyclic prefix. Any time domain windowing or FIR pulse shaping applied by the transmitter reduces the $\Delta \tilde{t}$ range within which the error vector is close to its minimum.

F.5.2 Window length

The window length W affects the measured EVM and is expressed as a function of the configured cyclic prefix length. In the case where equalization is present, as with frequency domain EVM computation, the effect of FIR is reduced. This is because the equalization can correct most of the linear distortion introduced by the FIR. However, the time domain windowing effect can't be removed.

F.5.3 Window length for normal CP

Table F.5.3-1 and Table F.5.3-2 below specify the EVM window length (W) for normal CP for FR2.

Table F.5.3-1: EVM window length for normal CP for 60 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)
50	1024	72	36	50
100	2048	144	72	50
200	4096	288	144	50
Note 1: These percentages are informative and apply to all OFDM symbols within subframe except for symbol 0 of slot 0 and slot 2. Symbol 0 of slot 0 and slot 2 may have a longer CP and therefore a lower percentage.				

Table F.5.3-2: EVM window length for normal CP for 120 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)
50	512	36	18	50
100	1024	72	36	50
200	2048	144	72	50
400	4096	288	144	50
OF	Note 1: These percentages are informative and apply to all OFDM symbols within subframe except for symbol 0 of slot 0 and slot 4. Symbol 0 of slot 0 and slot 4 may have a longer CP and therefore a lower percentage.			

F.5.4 Window length for Extended CP

Table F.5.4-1 below specifies the EVM window length (W) for extended CP. The number of CP samples excluded from the EVM window is the same as for normal CP length.

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)
50	1024	256	220	85.9
100	2048	512	440	85.9
200	4096	1024	880	85.9
Note 1: These percentages are informative.				

Table F.5.4-1: EVM window length for extended CP for 60 kHz SCS

F.5.5 Window length for PRACH

The table below specifies the EVM window length for PRACH preamble formats for $L_{RA} = 139$ and $\Delta f^{RA} = 15 \cdot 2^{\mu} \text{ kHz}_{\text{where }} \mu \in \{2,3\}$.

Preamble format	$\begin{array}{c c} \textbf{Cyclic} \\ \textbf{prefix} \\ N_{cp} \\ \textbf{length} \end{array}$	Nominal FFT size ¹	EVM window length <i>W</i> in FFT samples	Ratio of <i>W</i> to CP ²	
A1	1152·2 ^{-µ}	8192·2 ^{-µ}	576·2 ^{-µ}	50.0%	
A2	2304·2 ^{-µ}	8192·2 ^{-µ}	1728·2 ^{-µ}	75.0%	
A3	3456·2 ^{-µ}	8192·2 ^{-µ}	2880·2 ^{-µ}	83.3%	
B1	864·2 ^{-µ}	8192·2 ^{-µ}	288·2 ^{-µ}	33.3%	
B2	1440·2 ^{-µ}	8192·2 ^{-µ}	864·2 ^{-µ}	60.0%	
B3	2016·2 ^{-µ}	8192·2 ^{-µ}	1440·2 ^{-µ}	71.4%	
B4	3744·2 ^{-µ}	8192·2 ^{-µ}	3168·2 ^{-µ}	84.6%	
C0	4960·2 ^{-µ}	8192·2 ^{-µ}	4384·2 ^{-µ}	88.4%	
C2	8192·2 ^{-µ}	8192·2 ^{-µ}	7616·2 ^{-µ}	93.0%	
	scaling of the window length is applied				

Table F.5.5-1: EVM window length for PRACH formats for L_{RA} = 139

F.6 Averaged EVM

The general EVM is averaged over basic EVM measurements for n slots in the time domain.

$$\overline{EVM} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{i}^{2}}$$

where n is

$$n = \begin{cases} 40, for 60 \ kHz \ SCS \\ 80, for 120 \ kHz \ SCS \end{cases}$$

for PUCCH, PUSCH.

The EVM requirements shall be tested against the maximum of the RMS average at the window W extremities of the EVM measurements:

Thus $\overline{\text{EVN}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_l$ in the expressions above and $\overline{\text{EVN}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_h$. Thus we get:

$$EVM = \max(EVM, EVM_h)$$

The calculation of the EVM for the demodulation reference signal, EVM_{DMR5} , follows the same procedure as calculating the general EVM, with the exception that the modulation symbol set T_m defined in clause F.2 is restricted to symbols containing uplink demodulation reference signals.

The basic EVM_{DMRS} measurements are first averaged over n slots in the time domain to obtain an intermediate average $\overline{EVM_{DMRL}}$

$$\overline{EVM}_{DMRS} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{DMRS,i}^2}$$

In the determination of each $EVM_{DMRS,i}$, the timing is set to $\Delta \tilde{t} = \Delta \tilde{t}_l$ if $EVM > EVM_h$, and it is set to $\Delta \tilde{t} = \Delta \tilde{t}_h$ otherwise, where EVM_h and EVM_h are the general average EVM values calculated in the same n slots over which the intermediate average EVM_{DMRS} is calculated. Note that in some cases, the general average EVM may be calculated only for the purpose of timing selection for the demodulation reference signal EVM.

Then the results are further averaged to get the EVM for the demodulation reference signal, EVM_{DMRS} ,

$$EVM_{DMRS} = \sqrt{\frac{1}{6} \sum_{j=1}^{6} \overline{EVM}_{DMRS,j}^2}$$

The PRACH EVM, EVM_{PRACH} , is averaged over 2 preamble sequence measurements for long preamble formats as defined in table 6.3.3.1-1 in [9] and averaged over 10 preamble sequence measurements for short preamble formats as defined in table 6.3.3.1-2 in [9].

The EVM requirements shall be tested against the maximum of the RMS average at the window W extremities of the EVM measurements:

Thus $\overline{\text{EVM}}_{\text{PRACH,l}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_l$ and $\overline{\text{EVM}}_{\text{PRACH,h}}$ is calculated using $\Delta \tilde{t} = \Delta \tilde{t}_h$.

Thus we get:

$$EVM_{PRACH} = \max(EVM_{PRACH}, EVM_{PRACH})$$

F.7 Spectrum Flatness

The data shall be taken from FFT coded data symbols and the demodulation reference symbols of the allocated resource block.

Annex G(normative): Difference of relative phase and power errors

G.0 General

This annex gives further information needed for understanding and implementing 6.4D.4. The following terms should be understood as follows:

- Relative phase error: refers to the phase difference between signals at different antenna ports, which should be ideally 0. It should be understood as for a slot i.e. (slot) relative phase. It is calculated based on DMRS symbols of that slot or on SRS symbols.
- Difference of relative phase error: refers to the difference between the relative phase error determined per slot and the relative phase error determined based on the SRS transmitted.

G.1 Measurement Point

Figure G.1-1 shows the measurement point for the difference of relative phase and power errors. To separate signals from the two transmitters, it is necessary for the test equipment to perform joint demodulation by inverting the 2x2 composite channel ('HGW') resulting from DUT precoding 'W' and antenna virtualization 'G' and OTA channel between DUT and test equipment 'H'. Post processing refers to the calculation of the phase/power errors, the averaging of phase and power errors per RB per slot per channel port and the calculation of difference between relative phases.

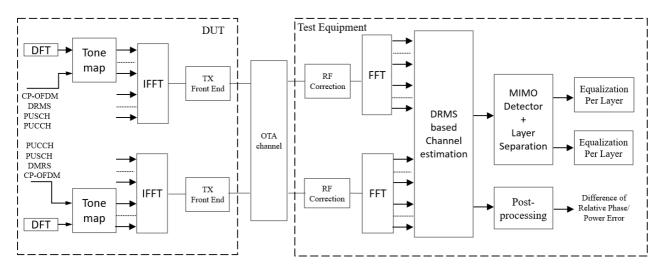


Figure G.1-1 - Measurement point for difference of relative phase/power error for UL coherent MIMO

G.2 Relative Phase Error Measurement

Here are listed the different aspects that may lead to different interpretations.

G.2.1 Symbols used

Phase error is determined based on DMRS REs (3 DMRS symbols per slot).

G.2.2 CFO (carrier frequency offset) correction

The TE performs a CFO correction on a slot-by-slot basis using a common frequency correction at the two uplink layers.

G.2.3 Steps of the measurement method

Below are detailed the steps necessary to obtain the maximum difference of relative phase error during the 20ms time window.

1 Determination for each subcarrier and at each antenna port, the SRS relative phase error based on the last SRS transmitted on Ant1 and Ant2, that relative phase error serves as a reference for the calculation of the difference of relative phase error for each slot inside the 20 ms time window.

The output is the "SRS relative phase error" vector for the last SRS transmitted: $[1 \times number_of_subcarriers]$.

2 Calculation for the last SRS transmitted, for each RB of the SRS relative phase errors based on the arithmetic mean of the subcarrier SRS relative phase errors determined in previous step.

The output is the "SRS relative phase error" vector for the last SRS transmitted: $[1 \times number_of_RBs]$.

- 3 CFO correction on slot-by-slot basis using a common frequency correction for both antenna ports.
- 4 Determination for each subcarrier and at each antenna port, the phase over the slot being analyzed. The phase is extracted from the channel estimate derived from the 3 DMRS symbols of the slot using the LSE technique.

The output is one vector of dimension $[1 \times number_of_subcarriers]$ for each antenna port.

5 Calculation for a slot for each subcarrier of the relative phase error (difference between the vectors determined in the previous step).

The output is subcarrier relative phase errors of a slot: $[1 \times number_of_subcarriers]$.

6 Calculation for a slot, for each RB of the relative phase errors based on the arithmetic mean of the subcarrier relative phase errors determined in previous step.

The output is a "slot relative phase error" vector for a slot: $[1 \times number_of_RBs]$.

7 Calculation for a slot of the difference of relative phase errors based on the "SRS relative phase error" (reference) determined in step 2 and the "slot relative phase error" determined in previous step.

The output is a "difference of relative phase error" vector for a slot: $[1 \times number_of_RBs]$.

8 Calculation for a slot of the arithmetic mean value of the "difference of relative phase error" vector determined in previous step, this value corresponds to an RB.

The output is a "difference of relative phase error" value for a slot: $[1 \times 1]$.

9 Perform for each slot of the 20ms time window, steps 3 to 8.

The output is a "difference of relative phase error" vector: $[1 \times number_of_slots]$.

10 Calculation of the maximum value of the "difference of relative phase error".

The output is the "difference of relative phase error" that should be verified as complying with the 40° maximum allowable difference of relative phase error requirement: $[1 \times 1]$.

Annex H (Normative): Modified MPR behavior

H.1 Indication of modified MPR behavior

This annex contains the definitions of the bits in the field *modifiedMPR-Behavior* indicated per supported NR band in the IE *RF-Parameters* [13] by a UE supporting an MPR or A-MPR modified in a given version of this specification. A modified MPR or A-MPR behaviour can apply to a supported NR band in stand-alone operation (including CA and NN-DC operation) or in non-standalone operation with the said NR band as part of an EN-DC or NE-DC band combination. Moreover, the bits in the field can explicitly indicate NS value(s) supported by a UE.

NOTE 1: In the present release, the *modifiedMPR-Behavior* is indicated [13] by an 8-bit bitmap per supported NR band.

NR Band	Index of field (bit number)	Definition (description of the supported functionality if indicator set to one)	Notes
n257	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n257
n258	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n258
	1	Void	
	2	- NS_203 as defined in clause 6.5.3.2.4 or both NS_203 and CA_NS_203 as defined in clause 6.5A.3.2.4 of 38.101-2 v15.11.0	 This bit shall be set to 1 by a UE supporting n258 or both n258 and CA_n258
n260	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n260
n261	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n261

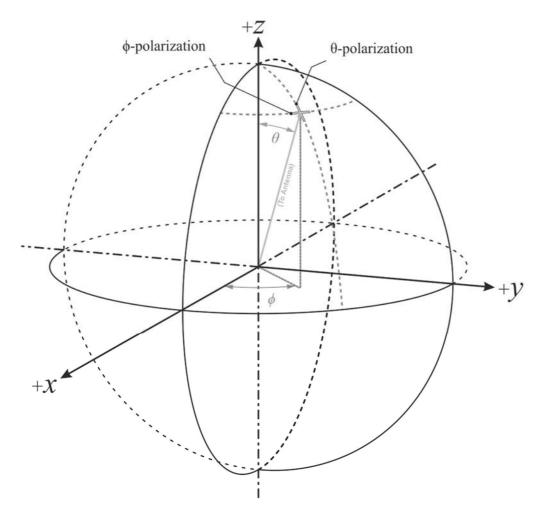
Table H.1-1: Definitions of the bits in the field modifiedMPRbehavior

Annex I (informative): Void

Annex J (normative): UE coordinate system

J.1 Reference coordinate system

This annex defines the measurement coordinate system for the NR UE. The reference coordinate system as defined in IEEE Std 149 [15] is provided in Figure J.1-1 below while Figure J.1.-2 shows the DUT in the default alignment, i.e., the DUT and the reference coordinate systems are aligned with $\alpha = 0^{\circ}$ and $\beta = 0^{\circ}$ and $\gamma = 0^{\circ}$ where α , β , and γ describe the relative angles between the two coordinate systems.





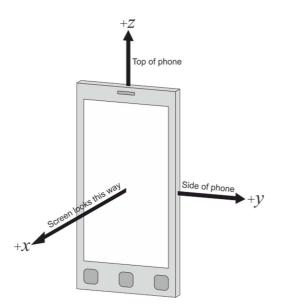


Figure J.1-2: DUT default alignment to coordinate system

The following aspects are necessary:

- A basic understanding of the top and bottom of the device is needed in order to define unambiguous DUT positioning requirements for the test, e.g., in the drawings used in this annex, the three buttons are on the bottom of the device (front) and the camera is on the top of the device (back).
- An understanding of the origin and alignment the coordinate system inside the test system i.e. the directions in which the x, y, z -axes points inside the test chamber is needed in order to define unambiguous DUT orientation, DUT beam, signal, interference, and measurement angles

J.2 Test conditions and angle definitions

Tables J.2-1 through J.2-3 below provides the test conditions and angle definitions for three permitted device alignment for the default test condition, DUT orientation 1, and two different options for each permitted device alignment to reposition the device for DUT Orientation 2 as outlined in Figures J.2-1 and J.2-3.

$ \begin{array}{c c} Free space \\ DUT \\ (default) \\ ($	Test condition	DUT orientation	Link angle	Measurement angle	Diagram
$\begin{array}{c c} DUT\\ Orientation 2\\ - Option 1\\ (based on re-positioning approach) \end{array} \left(\begin{array}{c} \beta = 0^\circ;\\ \gamma = 0^\circ \end{array} \right) \left(\begin{array}{c} \varphi \\ \psi \\ \psi \\ \varphi \\ \end{array} \right) \left(\begin{array}{c} \varphi \\ \varphi $	DUT Orientation 1	$\beta = 0^{\circ};$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or	Rotation Matrix $R_2(y)$ Rotation Matrix $R_x(\alpha)$ Rotation
Free space DUT Orientation 2 - Option 2 (based on re- positioning approach) $\alpha = 0^{\circ}$; $\beta = 180^{\circ}$; $\gamma = 0^{\circ}$ θ_{Link} ; φ_{Link} with polarization reference Pol_kink = 0 or ϕ θ_{Meas} ; ϕ_{Meas} with polarization reference Pol_Meas = 0 or ϕ θ_{Meas} ; φ θ_{Meas} ; φ θ_{Meas} ; φ Kotation Matrix $R_z(y)$ $\alpha = 0^{\circ}$; $\beta = 180^{\circ}$; $\gamma = 0^{\circ}$ θ_{Link} ; φ θ_{Meas} ; φ φ Vink $\beta = 180^{\circ}$; φ θ_{Meas} ; φ φ φ Vink φ φ φ φ Vink φ φ φ Vink φ φ φ Vink φ φ φ Vink φ	DUT Orientation 2 – Option 1 (based on re- positioning	$\beta = 0^{\circ};$	¢ _{Link} with polarization reference Pol _{Link} = θ or	φ _{Meas} with polarization reference Pol _{Meas} = θ or	Rotation
$\begin{array}{c c} DUT \\ Orientation 2 \\ - Option 2 \\ (based on repositioning approach) \end{array} \left(\begin{array}{c} \beta = 180^{\circ}; \\ \gamma = 0^{\circ} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Link}} \\ \text{with} \\ \text{polarization} \\ \text{reference} \\ \text{Pol}_{\text{Link}} = \theta \text{ or} \\ \varphi \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \text{with} \\ \text{polarization} \\ \text{reference} \\ \text{Pol}_{\text{Meas}} = \theta \text{ or} \\ \varphi \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} = \theta \text{ or} \\ \varphi \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} = \theta \text{ or} \\ \varphi \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Meas}} \\ \text{Pol}_{\text{Matrix} R_{x}(\alpha)} \\ \text{Rotation} \\ \text{Matrix} R_{x}(\alpha) \\ \text{Rotation} \\ \text{Matrix} R_{y}(\beta) \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Matrix}} \\ \text{Pol}_{\text{Matrix}} \\ \text{Pol}_{\text{Matrix} R_{y}(\beta)} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Matrix} R_{y}(\beta)} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Matrix}} \\ \varphi_{x}(\alpha) \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \text{Pol}_{\text{Matrix} R_{y}(\beta)} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \\ \varphi_{\text{Meas}} \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Matrix} R_{y}(\alpha) \\ \varphi_{\text{Matrix} R_{y}(\beta) \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Matrix} R_{y}(\alpha) \\ \varphi_{\text{Matrix} R_{y}(\beta) \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Matrix} R_{y}(\beta) \end{array} \right) \left(\begin{array}{c} \varphi_{\text{Matrix} R_{y}(\beta) \\ \varphi_{\text{Matrix} R_{y}(\beta) \end{array} \right) \left(\begin{array}{c} \varphi_$					Matrix $R_x(\alpha)$ + χ Rotation Matrix $R_y(\beta)$
Matrix $R_x(\alpha)$ + χ Rotation Matrix $R_y(\beta)$	DUT Orientation 2 – Option 2 (based on re- positioning	β = 180°;	¢ _{Link} with polarization reference Pol _{Link} = θ or	φ _{Meas} with polarization reference Pol _{Meas} = θ or	Rotation
NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for					Matrix $R_x(\alpha)$ + χ Rotation Matrix $R_y(\beta)$

 Table J.2-1: Test conditions and angle definitions for Alignment Option 1

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$ \begin{aligned} \alpha &= 0^{\circ}; \\ \beta &= -90^{\circ}; \\ \gamma &= 0^{\circ} \end{aligned} $	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(\gamma)$ +X Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha = 180^{\circ};$ $\beta = 90^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(\gamma)$ +X Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 2 (based on re- positioning approach)	$ \begin{aligned} \alpha &= 0^{\circ}; \\ \beta &= 90^{\circ}; \\ \gamma &= 0^{\circ} \end{aligned} $	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(y)$ +X Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
each	signal angle, link	or interferer angle	elation to the refere, and measureme by matrix $M=R_z(\gamma)$	

Table J.2-2: Test conditions and angle definitions for Alignment Option 2

Test	DUT	Link	Measurement	Diagram
condition Free space DUT Orientation 1 (default)		angle θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	angle θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(y)$ For the formula $x_{x}(\alpha)$ +x +x Rotation Matrix $R_{x}(\alpha)$ Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 1 (based on re- positioning approach)	$\alpha = -90^{\circ};$ $\beta = 0^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{z}(y)$ Rotation Matrix $R_{x}(\alpha)$ +X Rotation Matrix $R_{y}(\beta)$
Free space DUT Orientation 2 – Option 2 (based on re- positioning approach)	$\alpha = 90^{\circ};$ $\beta = 180^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} ¢ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	+Z Rotation Matrix $R_{2}(\gamma)$ Rotation Matrix $R_{x}(\alpha)$ +X Rotation Matrix $R_{y}(\beta)$
each	signal angle, link	or interferer angle	elation to the refere, and measuremed by matrix $M=R_z(\gamma)$	

 Table J.2-3: Test conditions and angle definitions for Alignment Option 3

For each UE requirement and test case, each of the parameters in Table J.2-1 through J.2-3 need to be recorded, such that DUT positioning, DUT beam direction, and angles of the signal, link/interferer, and measurement are specified in terms of the fixed coordinate system.

Due to the non-commutative nature of rotations, the order of rotations is important and needs to be defined when multiple DUT orientations are tested.

The rotations around the x, y, and z axes can be defined with the following rotation matrices

$$R_{x}(\alpha) = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos \alpha & -\sin \alpha & 0 \\ 0 & \sin \alpha & \cos \alpha & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

$$R_{y}(\beta) = \begin{bmatrix} \cos \beta & 0 & \sin \beta & 0 \\ 0 & 1 & 0 & 0 \\ -\sin \beta & 0 & \cos \beta & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

and

$$R_{z}(\gamma) = \begin{bmatrix} \cos \gamma & -\sin \gamma & 0 & 0 \\ \sin \gamma & \cos \gamma & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with the respective angles of rotation, α , β , γ , and

$$\begin{bmatrix} x'\\y'\\z'\\1 \end{bmatrix} = R \begin{bmatrix} x\\y\\z\\1 \end{bmatrix}$$

Additionally, any translation of the DUT can be defined with the translation matrix

$$T(t_x, t_y, t_z) = \begin{bmatrix} 1 & 0 & 0 & t_x \\ 0 & 1 & 0 & t_y \\ 0 & 0 & 1 & t_z \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with offsets t_x , t_y , t_z in x, y, and z, respectively and with

$$\begin{bmatrix} x' \\ y' \\ z' \\ 1 \end{bmatrix} = T \begin{bmatrix} x \\ y \\ z \\ 1 \end{bmatrix}$$

The combination of rotations and translation is captured by the multiplication of rotation and translation matrices.

For instance, the matrix M

$$M = T(t_x, t_y, t_z) \cdot R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$$

describes an initial rotation of the DUT around the x axis with angle α , a subsequent rotation around the y axis with angle β , and a final rotation around the z axis with angle γ . After those rotations, the DUT is translated by t_x , t_y , t_z in x, y, and z, respectively.

J.3 DUT positioning guidelines

The centre of the reference coordinate system shall be aligned with the geometric centre of the DUT in order to minimize the offset between antenna arrays integrated at any position of the UE and the centre of the quiet zone.

Near-field coupling effects between the antenna and the pedestals/positioners/fixtures generally cause increased signal ripples. Re-positioning the DUT by directing the beam peak away from those areas can reduce the effect of signal ripple on EIRP/EIS measurements. Figure J.3-1 and J.3-2 illustrate how to reposition the DUT in distributed axes and combined axes system, when the beam peak is directed to the DUTs upper hemisphere (DUT orientation 1) or the DUTs lower hemisphere (DUT orientation 2). While these figures are examples of different positioning systems and other implementations are not precluded, the relative orientation of the coordinate system with respect to the antennas/reflectors and the axes of rotation shall apply to any measurement setup.

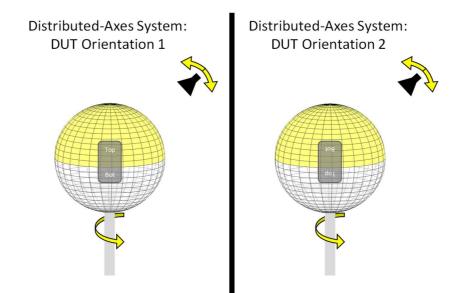


Figure J.3-1: DUT re-positioning for an example of distributed-axes system

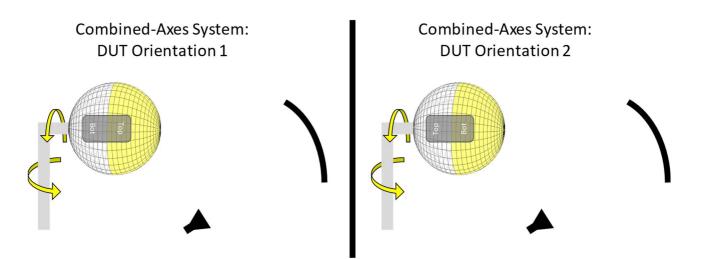


Figure J.3-2: DUT re-positioning for an example of combined-axes system

For EIRP/EIS measurements, re-positioning the DUT makes sure the pedestal is not obstructing the beam path and that the pedestal is not in closer proximity to the measurement antenna/reflector than the DUT. For TRP measurements, re-positioning the DUT makes sure that the beam peak direction is not obstructed by the pedestal and the pedestal is in the measurement path only when measuring the back-hemisphere. No re-positioning during the TRP measurement is required.

Annex K (informative): Void

Annex L (informative): Change history

						Change history	
Date	Meeting	TDoc	CR	Rev	Cat	Subject/Comment	New versio n
2017-08	RAN4#84					Initial Skeleton	0.0.1
2017-10	RAN4#84 Bis	R4- 1711979				TPs from R4#84Bis by editors	0.1.0
2017-12	RAN4#85	R4- 1713806				Approved TPs from R4#85 R4-1714537, TP for TS 38.101-2: Channel Bandwidth Definition, Qualcomm Incorporated R4-1714115, TP for TS 38.101-2: Channel Arrangement, : Qualcomm Incorporated (Note: this TP was further discussed and edited in the reflector) R4-1713205, TP on general parts for 38.101-2 NR FR, : Ericsson R4-1712884, TP to TS38.101-2 on environmental conditions, Intel Corporation R4-1714018, TP to TS 38.101-2 for definition of UE RF terminologies, Anritsu Corporation R4-1714477, TP on UE power class for FR2, Intel Corporation R4-1714370, TP to TS38.101-2 on EVM equalizer spectrum flatness requirements, Intel Corporation R4-1714330, TP to TR 38.101-2 v0.1.0: ON/OFF mask design for NR UE transmissions for FR2, Ericsson R4-1714364, TP to TR 38.101: NR UE transmit OFF power for FR2, CATT R4-1714364, TP to TS 38.101-2 on spurious emissions requirements for FR2, Intel Corporation (Note: this TP was further discussed and edited in the reflector) R4-1714364, TP to TS 38.101-2 ACS requirement for mmW (section 7.5), Qualcomm Incorporated R4-171438, TP to TS 38.101-2 ACS requirement for mmW (section 7.6.1), Qualcomm Incorporated R4-171438, TP to TS 38.101-2 NR spurious emissions for FR2, Intel Corporation Min power for EVM requirement according to R4-1711568, TP to TR 38.xxx - UE minimum transmit power for range 2, CATT Band list according to R4-1714542, List of bands and band combinations to be introduced into RAN4 NR core requirements by December 2017, RAN4 Chairmen	0.2.0
2017-12	RAN4#85	R4- 1714570				Further corrections and alignments with 38.104 after email review	0.3.0
2017-12		RP-172476				v1.0.0 submitted for plenary approval. Contents same as 0.3.0	1.0.0
2017-12 2018-03	RAN#78 RAN#79	RP-180264	0004		F	Approved by plenary – Rel-15 spec under change control Implementation of endorsed CR on to 38.101-2 Endorsed draft CRs in RAN4-NR-AH#1801 F: R4-1800918, Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801097, Modification for TS38.101-2, CATT F: R4-1801098 Draft CR for TS38.101-2: On requirement metrics. Sumitomo Elec. Industries, Ltd F: R4-1800401, Editorial corections to 38.101-2, Qualcomm F: R4-1800401, Editorial corections to 38.101-2, Qualcomm F: R4-1801122: Draft pCR for TS 38.101-2 version 15.0.0: Remaining ON/OFF masks for FR2 NR UE transmissions, Ericsson F: R4-1800418, Correction of NR SEM for FR2 table, vivo F: R4-1800316 Draft CR to 38.101-2: Tx spurious emission for NR FR2 (section 6.5.3), ZTE Corporation F: R4-1800918 Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801013, Draft CR to 38.101-2: Clarifications to UE spectrum utilization section 5.3, Ericsson F: R4-180129, Draft CR to 38.101-2: Channel spacing for CA for NR FR2(section 5.4.1.2), ZTE Corporation F: R4-1801232, Correction CR for channel spacing:38.101-2, Samsung	15.0.0

raster calculation in section 5.4.2, ZTE Corporation F: R4-1800860, Corrections of GSCN, Nokia Endorsed draft CRs in RAN4#86 R4-1803054, Draft CR for new spec structure of 38.101-2, Ericsson R4-1801466, Modification for NR UE time mask requirement for FR2, CATT R4-1801967, CR on EVM spectrum flatness for FR2, Huawei R4-1801967, CR on EVM spectrum flatness for FR2, Huawei R4-1802303, Draft CR to 38.101-2: Colrifications on peak directions and REFSENS, ROHDE & SCHWARZ R4-1802303, Draft CR to TS 38.101-2: Clarification of mixed numerology guardband size, Ericsson R4-1803365, Draft CR to 38.101-2: ACLR requirement clarification, Huawei R4-1803453, draft CR for TS 38.101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ R4-1803365, Draft CR for 37.865-01-01 into 38.101-2; Fricsson R4-1803453, draft CR for Timtroduction of completed band combinations from 37.865-01-01 into 38.101-2; Sync raster offset in refarming bands (5.4.3), Ericsson	·				 1		
2018-06 RAN#80 RP-181262 0010 F CR 1430054, Draft CR to TS 38, 101-2; Corrections to In-band blocking entities of the term of term of term of the term of te						F: R4-1801325, Draft CR to TS 38.101-2: Corrections on channel	
Endorsed draft CRs in RAN4#86 R4-1803364, Draft CR for new spec structure of 38.101-2, Ericsson R4-1801446, Modification for NR UE time mask requirement for FR2, CATT R4-1801729, Draft CR to 38.101-2; Corrections to In-band blocking requirements, R4-1801567, CR on EVM spectrum, Rations to FR2, Huaweil R4-1801567, CR on EVM spectrum, R4-1802567, Draft CR to TS 38.101-2; Clarification on pesk directions and R4 FESENS (FOHDE & SCHWARZ; R4-1802367, Draft CR to 38.101-2; Clarification on R4-1802368, Draft CR to 73.83.101-2; ACLR requirement clarification, Huaweil R4-1803365, Draft CR to 73.83.101-2; Lerisson R4-1803565, Draft CR to 75.38.101-2; Lerisson R4-1803566, Draft CR to 75.38.101-2; CR to 75.38.101-							
2018-06 RA-18016R, Draft CR for new spec structure of 38.101-2, Ericsson R4-180146, Modification for NR UE time mask requirement for FR2, CAT R4-1801729, Draft CR to 38.101-2: Corrections to In-band blocking requirements. Rohd & Schwarz R4-1801967, CR on EVM spectrum littiness for FR2, Huawei R4-180230, Draft CR to 38.101-2: Clarifications on peak directions and NEFSENS, ROHDE & SCHWARZ R4-1802030, Draft CR to 38.101-2: Clarifications on peak directions and NEFSENS, ROHDE & SCHWARZ R4-1802330, Draft CR to 38.101-2: Clarification on REFSENS Definition, Huawei R4-1803365, Draft CR to 78.38.101-2; Clarification on REFSENS Definition, NetWei R4-1803365, Draft CR to 78.38.101-2; Schwarz R4-1803566, Draft CR to 775 38.101-2; Sync raster offset in re- tarming bands (5.4.3), Ericsson R4-1803565, Draft CR to 75 38.101-2; Sync raster offset in re- tarming bands (5.4.3), Ericsson R4-180355, Draft CR to 75 38.101-2; Sync raster offset in re- tarming bands (5.4.3), Ericsson R4-180355, Draft CR to 75 38.101-2; Sync raster offset in re- tarming bands (5.4.3), Ericsson R4-180355, Draft CR to 78.101-2; Channe RAFT R2 CA BW Classes, Nokia R4-1804657, Introduction of UE to UE coexistence requirements requirements for FR2, Qualcomm Incorporated R4-1804657, Introduction of UE to UE coexistence requirements requirements for FR2, Qualcomm Incorporated R4-1804657, Introduction of UE to 33.101 T3.80.101-2; Nokia R4-1805650, Draft CR to 38.101-2; Channel alignment with different rumerologies (Section 5.3.4), ZTE Corporation R4-1804657, Update of CR to 38.101-2; Channel alignment with different rumerologies (Section 5.3.4), ZTE Corporation R4-1805650, Draft CR to 38.101-2; Channel alignment with different rumerologies (Section 5.3.4), ZTE Corporation R4-1805650, Draft CR to 38.101-2; Sync raster, Samsung R4-1805677, Update of CR to 38.101-2; Sync raster, Samsung R4-180569, Draft CR on 53.101-2, sync raster, Samsung R4-1805690, Draft CR on 53.101-2; Sync raster, Samsung R4-1805690, Draft CR on SSB c							
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R4-1801967. CR on EVM spectrum flamess for FR2, Huavei R4-1802330. Draft CR to 38.101-2: Clarifications on peak directions and REFSENS, ROHDE & SCHWARZ R4-1802330. Draft CR to 75 38.101-2: Clarification of mixed numerology quardband size, Ericsson R4-1802330. Draft CR to 75 38.101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ R4-1803365. Draft CR to 38.101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ R4-180356. Draft CR to 75 38.101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ R4-180356. Draft CR for T5 38.101-2: Inclusion of endorsed draft CRs from R4-180356. Draft CR for 75 38.101-2: Inclusion 2018-06 RAN#80 RP-181262 0010 F CR to 75 38.101-2: Indirection of completed band combinations from 37.865-01-01 into 38.101-2: Sync raster diffset in re- faming bands (5-43). Ericsson 2018-06 RAN#80 RP-181262 0010 F CR to 75 38.101-2: Notia R4-180450, Traft CRs from RAN4#87 Endorsed draft CRs from RAN4#860Bis R4-180455, Draft CR to 38.101-2: IBE Section Update, Qualcomm, Inc. R4-1804565, Draft CR to 153.31.01-2: Nokia R4-1804565, Draft CR to 153.31.01-2: Channel Raster to Resource Element Mapping (Sacction 5.4.2.2) and RB alignment with different numerologies (Section 5.4.2.4) and RB alignment with different numerologies (Section 5.4.2.4) and RB alignment with different numerologies (Section 5.4.2.4) an						R4-1801729, Draft CR to 38.101-2: Corrections to In-band blocking	
R4-1802339, Draft CR to 38, 101-2: Clarifications on peak directions and REFSENS, ROHDE & SCHWARZ R4-1802667, Draft CR to TS 38, 101-2: Clarification of mixed numerology quardband size, Ericsson R4-1803238, Draft CR to TS 38, 101-2: ACLR requirement clarification, Huawi R4-1803365, Draft CR to 38, 101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ R4-1803453, draft CR for instroduction of completed band combinations from 37, 865-01-01 into 38, 101-2; Ericsson R4-1803366, Draft CR for TS 38, 101-2: Sync raster offset in re- faming bands (54, 3), Ericsson 2018-06 RAN#80 RP-181262 0010 F CR to TS 38, 101-2; Implementation of endorsed draft CRs from R4-1803766, Draft CR on channel raster entry of band n258 for TS 38, 101-2; ZTE Wistion Telecorn AB R4-1804052, CR for modifications and clarifications for NR FR2 CA BW Classes, Nokia R4-1804055, Draft CR to 38, 101-2; IBE Section Update, Qualcomm, Inc. R4-1804055, Draft CR to 38, 101-2; ISE Section Update, Qualcomm, Inc. R4-1805641, Corrections of BCS for n257 intraband contiguous CA in 38, 101-2; Nokia R4-1805661, Corrections of BCS for n257 intraband contiguous CA in 38, 101-2; Nokia R4-1805657, Update of ACS requirements for FR2, Qualcomm Incorporated R4-1805705, Draft CR to 38, 101-2; Channel Raster to Resource Element Mapping (Section 5, 3.4), ZTE Corporation R4-1805705, Draft CR to 38, 101-2; Oran R4 alignment with different numerologies (Section 5, 3.4), ZTE Corporation R4-1805775, draft CR to 78, 101-2; suprater to FR2, Qualcomm Incorporated R4-1805775, draft CR to 78, 101-12; suprater to FR2, Qualcomm Incorporated							
R4-1802567, Draft CR to TS 38.101-2: Clarification of mixed Numerology quardband size, Ericsson R4-1803238, Draft CR for TS 38.101-2: ACLR requirement clarification, Huawei R4-1803458, Draft CR to 38.101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ, R4-1803463, draft CR for introduction of completed band combinitions from 37.865-01-01 into 38.101-2: Sync raster offset in re- faming bands (5.4.3). Encsson R4-1803768, Draft CR for TS 38.101-2: Sync raster offset in re- faming bands (5.4.3). Encsson 2018-06 RAN#80 RP-181262 0010 F CR to TS 38.101-2: Implementation of endorsed draft CRs from RAV4 #86bis and RAN4 #87 2018-06 RAN#80 RP-181262 0010 F CR to TS 38.101-2: Implementation of endorsed draft CRs from RAV4 #86bis and RAN4 #87 2018-06 RAV#80492, CR for modifications and clarifications for NR FR2 CA BW (Classes, Notia R4-1804657, Introduction of UE to UE coexistence requirements requirements for FR2, Qualcomm Incorporated R4-1804665, Draft CR to 38.101-2; Nokia R4-1804665, Draft CR to 38.101-2; Nokia R4-180564, Draft CR to TS 38.101-2; Nokia R4-180574, Update of UE emission requirements for FR2, Qualcomm Incorporated R4-180574, Update of UE emission requirements for FR2, Qualcomm Incorporated R4-1805756, draft CR to TS 38.101-2; Update of section 7.1, Rohde & Schwarz R4-1805775, Update of ACS requirement for FR2, Qualcomm Incorporated R4-1805775, draft CR in TG 38.10						R4-1802339, Draft CR to 38.101-2: Clarifications on peak directions	
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						R4-1813470, draftCR on applicability of TDD configuratiin for CA in	
						TS 38.101-2, Huawei	
						R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2,	
						R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2,	
						Huawei R4-1813527, Correction to FR2 spurious emission requirement,	
						Nokia	
						R4-1813585, Draft CR to Specify UL Power for FR2 REFSENS Test	
						Cases, Keysight	
						R4-1813815, Draft CR to 38.101-2: Corrections on configurations for	
						intra-band non-contiguous CA, ZTE Corporation	
						R4-1814149, Changes to FR2 UL MIMO, OPPO R4-1814180, Draft CR to TS 38.101-2 on channel arrangement	
						descriptions, LG Electronics Inc.	
						R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions	
						of UE channel bandwidth for CA, ZTE Corporation	
				2		R4-1814163, draft CR of operating band for Power Class 2 in FR2,	
						LG Electronics	
						R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde & Schwarz	
						R4-1814164, draftCR on MPR for TS 38.101-2, Huawei	
						R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA,	
						Qualcomm Incorporated	
						R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing,	
						Qualcomm Incorporated	
						Enderood droft CP's from DAN(4490	
						Endorsed draft CR's from RAN4#89 R4-1815951, dCR on TS38.101-2 merging draft CRs from	
						RAN4#89, Qualcomm Incorporated	
						R4-1814497, Correction on UL MIMO requirement for PC1 UE,	
						Samsung	
						R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2,	
						Intel Corporation	
						R4-1814698, Draft CR to TS38.101-2 updating references, Apple	
						Inc. R4-1815623, Draft CR to 38.101-2: FR2 Max. Input Power UL	
						Configuration, Qualcomm Incorporated	
						R4-1815801, draft CR editorial correction in 38.101-2, Ericsson	
						R4-1815810, draft Rel-15 CR to 38.101-2 to include n260 fallbacks	
						needed, Ericsson	
						R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated	
						R4-1815943, dCD Coherent UL MIMO parameters for FR2, Qualcomm Incorporated	
						R4-1816205, Draft CR to TS38.101-2 correcting the Pcmax	
						requirement, Apple Inc.	
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						R4-1816206, draft CR on Pcmax for ULCA and limitation on max	
						aggregated ULCA BW, Qualcomm Incorporated	
						R4-1816217, Draft CR to 38.101-2 on UE maximum output power	
						with additional requirements, ZTE Corporation	
						R4-1816218, Draft CR for Introducing missing requirement for power	
						class 4 in FR2 for TS 38.101-2, NTT DOCOMO, INC. R4-1816219, draft CR of MPR for Power Class 2 in FR2, LG	
						Electronics	
						R4-1816220, Draft CR to 38.101-2: On FR2 CA MPR v2, Qualcomm	
						Incorporated	
						R4-1816239, Draft CR to 38.101-2: On FR2 EESS A-MPR for n258,	
						Qualcomm Incorporated	
						R4-1816245, Draft CR to 38.101-2: FR2 EIS DL Signal Polarization	
						Clarification, Qualcomm Incorporated	
						R4-1816257, Draft CR to TS38.101-2 to correct UL CA scope for	
						FR2 in Rel-15, Apple Inc.	
						R4-1816605, TDD configuration for UE Tx test in FR2, Ericsson R4-1816664, Draft CR to 38.101-2 (5.3.4) RB alignment, Huawei	
						R4-1816064, Draft CR for RF exposure compliance in TS38.101-2,	
						LG Electronics France	
						R4-1816626, Draft CR to TS 38.101-2: Introducing multi-band	
						applicability for PC3, Apple Inc.	
						R4-1816634, Draft CR to 38.101-2: FR2 EIS Spherical Coverage	
						Requirement, Qualcomm Incorporated	
						R4-1816639, Verification of beam correspondence, Ericsson, Sony	
						R4-1816633, draft CR on UE type for Power Class 2 in FR2, LG	
						Electronics	
						R4-1816644, Draft CR to TS 38.101-2: Temperature Condition for testing EIRP Spherical Coverage requirement, Apple Inc.	
2019-03	RAN#83	RP-190747	0018		F	CR to TS 38.101-2: Implementation of endorsed draft CRs from	15.5.0
2010-00	11711#05	10110141	0010			RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW	10.0.0
						······································	
						Endorced draft CRs from RAN4#90	
						R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualcomm	
						Incorporated	
						R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Qualcomm	
						Incorporated	
						R4-1900131, draft CR to 38101-2 Correction to EVM equalizer spectrum flatness for Pi2 BPSK, Intel Corporation	
						R4-1900132, draft CR to 38101-2 FR2 transmit modulation guality	
						for CA, Intel Corporation	
						R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in	
						FR2, OPPO	
						R4-1900301, Draft CR: Introduction of Annex on Characteristics of	
						the Interfering Signal, Samsung	
						R4-1900386, CR to 38.101-2 on CA BW Classes fallback groups,	
						Intel Corporation R4-1900443, CR to chance Annex E2.1, Qualcomm Incorporated	
						R4-1900443, CK to Chance Africk L2. 1, Qualcomminicorporated R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intra-	
						band non-contiguous CA, ZTE Corporation	
						R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG	
						Electronics	
				1		R4-1900533, draft CR on maximum output power reduction for CA	
						for power class 2 in FR2, LG Electronics	
						R4-1900535, draft CR on A-MPR for CA for power class 2 in FR2,	
						LG Electronics R4-1900542, Draft CR on Measurement period of PRACH time	
						mask, Qualcomm Incorporated	
						R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output	
						power, Qualcomm Incorporated	
						R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA,	
						Qualcomm Incorporated	
						R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRACH,	
						Qualcomm Incorporated	
						R4-1900679,Draft CR to 38.101-2: IBB requirement update,	
						Qualcomm Incorporated R4-1900680, Draft CR to 38.101-2: Complete Pmin requirement for	
						CA, Qualcomm Incorporated	
						R4-1900728, Update to PRACH EVM window length for FR2, Rohde	
						& Schwarz	
						R4-1900736, Draft CR on editorial error of TS38.101-2, LG	
1						Electronics Inc.	
						R4-1900755, Draft CR on spurious emission limit in 38.101-2,	
						Qualcomm Incorporated	

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						ditorial corrections for 38.101-2, Qualcomm	
					Incorporated	of OD to 00,404.0, compating of the polation white	
						aft CR to 38.101-2: correction of the relationship um requirements and test requirements, Apple Inc.	
						aft_CR TS 38.101-2 FR1 frequency range extension,	
					Skyworks Soluti		
						raft CR to 38.101-2: correction of multi-band aspects	
						r PC3, Apple Inc.	
						aftCR on maximum output power for TS 38.101-2,	
					Huawei	aft CR for Multi-band relaxation to TS 38.101-2, NTT	
					DOCOMO, INC.		
						aft CR on max input power in FR2, OPPO	
						aft CR to TS 38.101-2: Introduction of the	
					requirement on	beam correspondence, Apple Inc	
					Further changes		
						tion 6.2.2.0 to modify the MPR=0dB waveform and	
						to modify the MPR tables to accommodate the OBW	
					requirements	,	
2019-06	RAN#84	RP-191240	0021	F		1-2: Implementation of endorsed draft CRs from	15.6.0
					RAN4#90bis an	d RAN4#91	
					Endorsed draft	CRs from RAN4#90Bis:	
						raft CR to TS 38.101-2 Correction to Pcmax,	
					1.4 1002002. D	Intel Corporation	
					R4-1902976	Draft CR on PRACH and PUCCH format	
						description for EVM in FR2Anritsu corporation	
					R4-1903121	Draft CR on DL power allocation for TS 38.101-2	
					R4-1903242	Intel Corporation Adding BCS definition in TS38.101-2 CATT	
					R4-1903474	draft CR of in-band emission for FR2 PC2 LG	
						Electronics	
					R4-1903888	Draft CR: Alignment of FR2 DL scheduling of DL	
					R4-1904001	RMC with UL RMCEricsson Draft CR for TS 38.101-2 – UE coordinate system	
					D 4 4 9 9 4 4 4 4	Rohde & Schwarz	
					R4-1904411	draft Rel-15 CR for editorial corrections in 38.101-2 Ericsson	
					R4-1904553	Draft CR to 38.101-2: FR2 power dynamics DTX removal Qualcomm Incorporated	
					R4-1904930	Draft CR to 38.101-2: Updating MPR wording in ULMIMO section Qualcomm Incorporated	
					R4-1904931	Draft CR to clarify frequency of carrier leakage in RBs for FR2 Anritsu corporation	
					R4-1904932	Draft CR on editorial error of TS38.101-2 LG	
					R4-1904933	Electronics France Draft CR on UE optional bandwidth for FR2	
					D4 400 4050	Huawei, HiSilicon	
					R4-1904956	Draft CR for TS 38.101-2: Corrections to configurations for intra-band non-contiguous CA	
						MediaTek Inc.	
					R4-1904961	Draft CR for TR38.101-2 – Update to EVM	
						averaging Rohde & Schwarz	
					R4-1904962	Draft CR to 38.101-2: FR2 ULMIMO EVM	
					R4-1904966	Qualcomm Incorporated Draft CR to TS 38.101-2 CA maximum input level	
					114 1004000	Intel Corporation	
					R4-1904986	Draft CR for TS 38.101-2: Corrections to EVM	
						equalizer spectrum flatness requirements	
					P4 1004004	MediaTek Inc.	
					R4-1904994	draft CR to 38.101-2 Correction to ACS and In-band Blocking notes Intel Corporation	
					R4-1905003	Draft CR to 38.101-2: FR2 PC3 and PC1 MPR	
						Qualcomm Incorporated	
					R4-1905005	Draft CR for 38.101-2 frequency separation class Huawei, HiSilicon	
						,	
						CRs from RAN4#91:	
					R4-1905504	Change description 4.2(d) in Applicability of	
					R4-1905685	minimum requirements for TS 38.101-2 vivo Draft CR to 38.101-2: FR2 Sensitivity Qualcomm	
						Incorporated	
					R4-1905764	draft CR to 38.101-2 UE maximum output power	
					D4 1005765	reduction for UL-MIMOIntel Corporation	
					R4-1905765	draft CR to 38.101-2 UE maximum output power for UL-MIMO Intel Corporation	
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2019-00 RA-1957/96 Correction to a description of PRB for in-Band mission in FR2 Antisus Corporation RA-1905798 Correction is power control in FR2 Antisus Correction is power control in FR2 Antisus RA-1905793 RA-1905798 Correction is power control in FR2 Antisus RA-1905793 RA-1905793 RA-1905793 RA-1905793 Correction is power control in FR2 Antisus RA-190703 Data CR to relational corrections of rs 28.01-2 Cocgle inc. Cocgle inc. RA-190703 Control CR to relational control in the con									
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2019-06 RAN464 RP-192040 Draft CR for editorial corrections in TS 38.101-2 Google Inc. R4-1907030 R4-1907030 Draft CR for editorial corrections in TS 38.101-2 Google Inc. R4-1907430 R4-1907430 R4-19070420 Draft CR for Signific PC3 same requirements LG Electronics Inc. R4-1907437 Draft CR for TS 38.101-2 Correction of channel bandwidth set for NR CA. Huawel, HSILicon, CMCC R4-1907447 Draft CR for TS 38.101-2 Complex FE2 MPR/A- MPR. Intel Corporation R4-1907444 R4-1907447 Draft CR for S3.8.101-2 Complex FE2 MPR/A- MPR. Intel Corporation R4-1907444 R4-1907447 Draft CR for S3.8.101-2 Complex FE2 MPR/A- MPR. Intel Corporation R4-1907465 R4-1907468 Draft CR for S3.8.101-2 Control R4-1907466 Draft CR for S3.8.101-2 Control R4-1907469 Draft CR for S3.8.101-2 Control Correction to Pores: and Purask tor CA Eresson R4-1907480 Draft CR for S3.8.101-2 Control CA Eresson Eresson R4-1907480 Draft CR for S3.8.101-2 Control CA Eresson Eresson R4-1907680 Correction to CA carrier spacing								Corporation	
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2019-06 RAH885 RP-192043 CR to REL_16 TS 38.101-2: Insert definitions Qualcomm Incorporated R4-190743 Draft CR to 38.101-2: Complete FR2 MPR/A- MPR Inite Corporation R4-190743 Draft CR to 38.101-2: Complete FR2 MPR/A- MPR Inite Corporation RA+1907443 Draft CR to 58.101-2: Complete FR2 MPR/A- MPR Inite Corporation R4-1907446 Draft CR to 38.101-2: CR CA EFEESNS Outcomm Incorporated R4-1907466 Draft CR to 38.101-2: FR2 CA MPR enhancement Outcomm Incorporated R4-1907466 Draft CR to 38.101-2: CR ZA MPR Wording Clean-Up Outcomm Incorporated R4-1907466 R4-1907466 Draft CR to 38.101-2: CR ZA MPR Wording Clean-Up Outcomm Incorporated R4-1907476 Draft CR to 38.101-2: CR ZA MPR wording Clean-Up Outcomm Incorporated R4-19074766 Draft CR to 78.401-2 To 78.401-2 2019-06 RAN#84 RP-191241 0020 B CR to REL-16 TS 38.101-2: Implementation of endorsed draft CRs on NR combinations and dual Connectivity combinations 16.0.0 2019-06 RAN#84 RP-191241 0022 1 B CR to REL-16 TS 38.101-2: Implementation of endorsed draft CRs on NR combinations and dual Connectivity combinations 16.1.0 2019-08 RAN#85 RP-192049 0028 A CR to TS 38.101-2: Implementation of endorsed draft CRs from RAH4902 (Rel-16) 16.1.0 2019-08									
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R4-1907468 Draft CR to 38.101-2: FR2 PR Wording CleanUp Qualcomm Incorporated R4-1907473 Draft CR to TS38.101-2: On Configurations for intra- band contiguous CA ZTE Corporation R4-1907611 Draft CR to TS38.101-2: on configurations for intra- band contiguous CA ZTE Corporation R4-1907688 Correction to Pemax and Pumax for CA Samsung, Apple, Verizon R4-1907688 16.0.0 2019-06 RAN#84 RP-191241 0020 B CR to REI-16 TS 38.101-2: Inplementation of endorsed draft CRs 16.0.0 2019-06 RAN#84 RP-191241 0022 1 B CR to REI-16 TS 38.101-2: Implementation of endorsed draft CRs for 38.101-2 16.0.0 2019-07 RAN#84 RP-191241 0022 1 B CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN#452 (ReI-16) 16.0.0 2019-07 RAN#85 RP-192049 0028 A CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN#452 (ReI-16) 16.1.0 2019-09 RAN#85 RP-192049 0028 A CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN#452 (ReI-16) 16.1.0 2019-09 RAN#85 RP-192049 0028 A CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN#452 (ReI-16) 16.1.0 2019-09 RAN#85 RP-192049 0028 <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td>R4-1907466</td> <td>Draft CR to 38.101-2: FR2 CA MPR enhancement</td> <td></td>							R4-1907466	Draft CR to 38.101-2: FR2 CA MPR enhancement	
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R4-1909117Draft CR for 38.101-2 applicability for intra-band CA HuaweiR4-1909316Draft CR to TS 38.101-2 on symbols correction ZTE CorporationR4-1910235Draft CR to TS38.101-2 for Rx RF requirementsLG Electronics FinlandR4-1910238CR for Handling of fallbacks for combined contiguous and non-contiguous CA in FR2 AppleR4-1910241Draft CR to TS 38.101-2 on NR CA configurations for FR2 ZTE CorporationR4-1910259dCR to 38.101-2: Reference signal clarifications Qualcomm IncorporatedR4-1910261dCR to 38.101-2: FR2 AMPR updates, including ERC 74-01 changesQualcomm Incorporated R4-1910287dCR to 38.101-2: FR2 CA MPR refinement							R4-1908708	Draft CR to TS38.101-2: corrections on the receiver	
Huawei R4-1909316 Draft CR to TS 38.101-2 on symbols correction ZTE Corporation R4-1910235 Draft CR to TS38.101-2 for Rx RF requirements LG Electronics Finland R4-1910238 CR for Handling of fallbacks for combined contiguous and non-contiguous CA in FR2 Apple R4-1910241 Draft CR to TS 38.101-2 on NR CA configurations for FR2 ZTE Corporation R4-1910259 dCR to 38.101-2: Reference signal clarifications Qualcomm Incorporated R4-1910261 dCR to 38.101-2: FR2 AMPR updates, including ERC 74-01 changes Qualcomm Incorporated R4-1910287 dCR to 38.101-2: FR2 CA MPR refinement									
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R4-1910238CR for Handling of fallbacks for combined contiguous and non-contiguous CA in FR2 Apple R4-1910241Apple R4-1910241R4-1910241Draft CR to TS 38.101-2 on NR CA configurations for FR2 ZTE Corporation R4-1910259CR to 38.101-2: Reference signal clarifications Qualcomm Incorporated R4-1910261R4-1910261dCR to 38.101-2: FR2 AMPR updates, including ERC 74-01 changesQualcomm Incorporated R4-1910287							R4-1910235		
contiguous and non-contiguous CA in FR2 Apple R4-1910241 Draft CR to TS 38.101-2 on NR CA configurations for FR2 ZTE Corporation R4-1910259 dCR to 38.101-2: Reference signal clarifications Qualcomm Incorporated R4-1910261 dCR to 38.101-2: FR2 AMPR updates, including ERC 74-01 changes Qualcomm Incorporated R4-1910287 dCR to 38.101-2: FR2 CA MPR refinement									
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R4-1910287 dCR to 38.101-2: FR2 CA MPR refinement							R4-1910261 c	dCR to 38.101-2: FR2 AMPR updates, including	

						R4-1910328 Draft CR to TS 38.101-2: Corrections for UL and DL	
						RMC for FR2 tests Intel Corporation	
						R4-1910333 Draft CR for 38.101-2 reference measurement	
						channel for beam correspondence Huawei	
						R4-1910334 Draft CR for TS38.101-2, Editorial corrections	
						CATT R4-1910412 Draft CR for 38.101-2 correction for channel raster	
						Huawei	
						R4-1910614 Draft CR for TS 38.101-2: Channel spacing for	
						adjacent NR carriers ZTE	
						Conditional agreements for BC for PC1/2/4 from R4-1902252	
2019-09	RAN#85	RP-192027	0025		F	Minor corrections of intra-band non-contiguous CA operating bands	16.1.0
2013 03	10/11/00	102021	0023	1		in TS 38.101-2	10.1.0
2019-09	RAN#85	RP-192027	0026		D	Rel-16 CR for further simplification of 38.101-2 Table 5.5A.2-2	16.1.0
2019-12	RAN#86				A	CR to 38.101-2: DMRS exceptions	16.2.0
2019-12	RAN#86	RP-193030			A	Sync raster to SSB resource element mapping	16.2.0
2019-12	RAN#86	RP-193030			A	CR to 38.101-2 (Rel-16) to clarify measurement interval and	16.2.0
2019-12	IXAN#00	11-195050	0033		~	observation window on frequency error	10.2.0
2019-12	RAN#86	RP-193031	0041		А	CR to TS 38.101-2 on beam correspondence side condition	16.2.0
2019-12	INAIN#00	KF-193031	0041		A	applicability	10.2.0
2019-12	RAN#86	RP-193031	0044		А	CR to TS 38.101-2: Correctin on FInterferer (offset) for CA ACS	16.2.0
2019-12	RAN#86	RP-193030			A	CR for TS 38.101-2: Editorial correction on MPR for contiguous CA	16.2.0
2019-12	INAIN#00	KF-193030	0040		A	notation	10.2.0
2019-12	RAN#86	RP-193031	0050		А	CR for TS 38.101-2: CA bandwidth class definition amendment	16.2.0
2019-12	RAN#86 RAN#86	RP-193031 RP-193030			A	CR to TS 38.101-2: CA bandwidth class definition amendment CR to TS 38.101-2 on corrections to channel raster entries for NR	16.2.0
2019-12	KAN#86	RP-193030	0052		А	band (Rel-16)	10.2.0
2010 12		DD 102020	0056		۸		16.2.0
2019-12	RAN#86	RP-193030			A	CR to transmit modulation quality in FR2	16.2.0 16.2.0
2019-12	RAN#86	RP-193030			A	Frequency separation class clarification REL-16	
2019-12	RAN#86	RP-193012	0064		В	CR introduction completed band combinations 38.716-01-01 ->	16.2.0
0040.40	DANI//00	DD 400044	0005		_	38.101-2	40.0.0
2019-12	RAN#86	RP-193011	0065	1	F	CR to 38.101-2-g10 Corrections to maximum output power reduction	16.2.0
0040.40	DANI//00	DD 400000	0007		^	for power class 3	40.0.0
2019-12	RAN#86				A	CR for TS 38.101-2: power classes and maxUplinkDutyCycle-FR2	16.2.0
2019-12	RAN#86	RP-193031			A	CR for agreed MPR CA for FR2 intra-band contiguous	16.2.0
2019-12	RAN#86	RP-193031		1	A	CR for 38.101-2 on NS_202 band definition	16.2.0
2019-12	RAN#86	RP-193031			Α	CR to TS 38.101-2: Correctin on CA NRACLR	16.2.0
2020-03	RAN#87	RP-200395			Α	Correction of the FR2 RMC slot patterns for MOP test cases	16.3.0
2020-03	RAN#87	RP-200395			Α	CR to 38.101-2 (Rel-16) MPR for CA	16.3.0
2020-03	RAN#87	RP-200395			F	CR FR2 CA tables REL16	16.3.0
2020-03	RAN#87	RP-200395	0108		А	CR to TS 38.101-2 on corrections to intra-band contiguous CA for	16.3.0
						FR2 bands (Rel-16)	
2020-03	RAN#87	RP-200395	0110		А	CR to 38.101-2: Align Rx CA requirements structure with TS38.101-	16.3.0
-						1	
2020-03	RAN#87	RP-200395	0114		А	CR for TS 38.101-2: Editorial addition of CBW and CABW definitions	16.3.0
						in Abbreviations section	
2020-03	RAN#87	RP-200395			Α	CR to TS 38.101-2: Correction on FRC table for FR2 DL 64QAM	16.3.0
2020-03	RAN#87	RP-200469		2	Α	CR for 38.101-2 side condition for BC_Rel16	16.3.0
2020-03	RAN#87	RP-200380			F	Editorial corrections	16.3.0
2020-03	RAN#87		0122		F	Opened the set for a fille set the Definition for Developed as a	
2020-03		RP-200378				Correction of Inner Allocation Definition for Powerclass 3	16.3.0
2020 00	RAN#87	RP-200378 RP-200395			A	R16 CR to 38.101-2: TRS and SSB configurations in FR2	16.3.0 16.3.0
2020-04		RP-200395	0136 0147			R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected	16.3.0 16.3.1
	RAN#87 RAN#88		0136 0147		A	R16 CR to 38.101-2: TRS and SSB configurations in FR2	16.3.0
2020-04		RP-200395	0136 0147 0148		A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected	16.3.0 16.3.1
2020-04 2020-06	RAN#88	RP-200395 RP-200985	0136 0147 0148 0151		A A F	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2	16.3.0 16.3.1 16.4.0
2020-04 2020-06 2020-06	RAN#88 RAN#88	RP-200395 RP-200985 RP-201046	0136 0147 0148 0151		A A F A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16	16.3.0 16.3.1 16.4.0 16.4.0
2020-04 2020-06 2020-06	RAN#88 RAN#88	RP-200395 RP-200985 RP-201046	0136 0147 0148 0151 0164		A A F A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam	16.3.0 16.3.1 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985	0136 0147 0148 0151 0164 0168		A A F A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170		A A F A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170		A A F A A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172		A A F A A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172		A A F A A A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174		A A F A A A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: no correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174		A A F A A A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174		A A F A A A A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175		A A A A A A A F	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181		A A A A A A A F	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: no correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181 0183		A F A A A A A A F A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2 on correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200959 RP-200959	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181 0183 0184		A F A A A A A F A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: no correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs	16.3.0 16.3.1 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181 0183 0184 0188		A F A A A A A A F F A F	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: no correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs	$\begin{array}{c} 16.3.0\\ 16.3.1\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ \end{array}$
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181 0183 0184 0188 0193		A A A A A A A A A A A F A F B B F	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: no correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM	$\begin{array}{c} 16.3.0\\ 16.3.1\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ \end{array}$
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-201046 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181 0183 0184 0188 0193 0198		A A F A A A A A F A F A A	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: ncorrection of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM	$\begin{array}{c} 16.3.0\\ 16.3.1\\ 16.4.0\\$
2020-04 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200395 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985 RP-200985	0136 0147 0148 0151 0164 0168 0170 0172 0174 0175 0181 0183 0184 0188 0193 0198 0200		A A A A A A A A A A A F A F B B F	R16 CR to 38.101-2: TRS and SSB configurations in FR2 Change history corrected CR on ACLR MBW definition in FR2 CR to 38.101-2: Revision to Multiband Relaxations CR to 38.101-2: no correction of reference point for beam correspondence side conditions R16 CR to 38.101-2 to correct Link and Meas Angles CR to 38.101-2: NS_202 update after changes to EU regulations CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications CR for TS 38.101-2: Correction for configured transmitted power for CA CR for TS 38.101-2: Clarifications on transmitter power for receiver requirements CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM	$\begin{array}{c} 16.3.0\\ 16.3.1\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ 16.4.0\\ \end{array}$

2020-06	RAN#88	RP-200959	0209		Α	CR to 38.101-2: Introduce mmWave intra-band uplink CA	16.4.0
2020-0n i		DD 200005	0161	4	Р	Configurations	16.4.0
	RAN#88	RP-200985		1	B	CR to K1 value in Annex A.3.3 of 38.101-2	16.4.0
	RAN#88 RAN#88	RP-201046 RP-200985		2	A B	CR to 38.101-2 on FR2 frequency separation class enhancement CR on Pcmax correction for CA	16.4.0 16.4.0
	RAN#88	RP-200965 RP-200978		2	B	CR to 38.101-2 for Introduction of band n259	16.4.0
	RAN#88	RP-200978 RP-201046			A	FR2 new MPR and modifiedmpr	16.4.0
	RAN#89	RP-201040		1	B	Introduction of MPE related P-MPR operation in sub-clause 6.2.4	16.5.0
2020-09	RAN#89	RP-201430			A	CR on Minimum output power and Off power MBW definition in FR2	16.5.0
	RAN#89	RP-201496		1	B	CR to 38.101-2 (Rel-16) intra-band non-cont. DL CA	16.5.0
	RAN#89	RP-201430		-	A	CR for R16 38.101-2; Correction of in-band emission tables	16.5.0
2020-09	RAN#89	RP-201512		1	F	Correction for REL16 FR2 contiguous intra-band CA configuration	16.5.0
2020 00	10,11,00	101201012	0220			table	10.0.0
2020-09	RAN#89	RP-201512	0230	1	F	modifiedMPR correction for FR2 REL16	16.5.0
	RAN#89	RP-201496		2	В	Beam correspondence enhancement	16.5.0
2020-09	RAN#89	RP-201512	0234		Α	CR to TS 38.101-2 on corrections to operating bands for intra-band	16.5.0
						CA (Rel-16)	
2020-09	RAN#89	RP-201506	0235		F	Correction of ACS requiremet for n259	16.5.0
2020-09	RAN#89	RP-201496	0237	2	F	Introduction of FR2 inter-band DL CA	16.5.0
2020-09	RAN#89	RP-201512	0239		Α	CR for introduction of EESS protection for n257 into general	16.5.0
						spurious emission	
2020-09	RAN#89	RP-201512	0241		Α	CR to TS 38.101-2: Correction on the Aggregated Channel	16.5.0
						Bandwidth	
	RAN#89	RP-201512			Α	CR to TS 38.101-2: Correction on the PC3 MPR description	16.5.0
	RAN#89	RP-201512			Α	FR2 Minimum output power measurement period definition	16.5.0
2020-09	RAN#89	RP-201488	0249	2	F	CR to TS38.101-2 on ULFPTx and UE SRS port configuration	16.5.0
	DANIMOR	<u></u>			_	clarification	
	RAN#89	RP-201496		1	F	CR to 38.101-2: DL CA BW Enhancement and CA REFSENS	16.5.0
	RAN#89	RP-201496		1	В	CR to 38.101-2: FR2 UE EIRP increase with IBE relaxation	16.5.0
	RAN#89	RP-201496		1	В	FR2 intra-band non-contiguous UL CA feature	16.5.0
	RAN#89	RP-201507			F	Correction of corrupted table	16.5.0
	RAN#90	RP-202485			A	EESS protection related requirements for FR2 bands	16.6.0
	RAN#90	RP-202485			A	CR to 38.101-2: ULCA clarifications	16.6.0
2020-12 2020-12	RAN#90	RP-202485 RP-202443		1	A	CR for TS38.101-2 Rel-16, Correction for definition of P-MPR	16.6.0
	RAN#90 RAN#90	RP-202443 RP-202443		1	F	REL16 eBC capability alingment with 38.306	16.6.0
	RAN#90 RAN#90	RP-202443 RP-202443		1	F	CR to 38.101-2 (Rel-16) inter-band DL CA Clarification of EIS spherical coverage for inter-band CA	16.6.0 16.6.0
	RAN#90	RP-202443 RP-202485			A		16.6.0
	RAN#90	RP-202465			A	Transmission gap for relative power tolerance in FR2 CR to TS38.101-2 on DC location correction	16.6.0
2020-12	RAN#90	RP-202485			A	CR for TS 38.101-2: Clarification for NS_202	16.6.0
2020-12	RAN#90		0280	1	F	CR to TS 38.101-2 on fallback group for intra-band contiguous CA	16.6.0
2020 12		111-202000	0202			(Rel-16)	10.0.0
2020-12	RAN#90	RP-202509	0283	1	F	CR to TS 38.101-2 on simplification for inter-band CA configuration	16.6.0
2020-12	RAN#90	RP-202485			A	Correction to Pcmax: total radiated power	16.6.0
2020-12	RAN#90	RP-202485			A	Correction to EIS definition	16.6.0
		RP-202428		1	F	CR for editorial corrections 38.101-2	16.6.0
	RAN#90	RP-202485			A	Mirror CR for 38.101-2: IBB and ACS corrections	16.6.0
	RAN#90	RP-202485			Α	CR to DMRS position in UL RMC for FR2	16.6.0
2021-03	RAN#91	RP-210116			Α	CR for 38.141-2: BS demodulation synchronization in test setup	16.7.0
2021-03	RAN#91	RP-210091			F	CR to TS 38.101-2 on correction to intra-band non-contiguous CA	16.7.0
						configurations (Rel-16)	
2021-03	RAN#91	RP-210083	0323	1	F	P_cmax P_IBE wording refinement and terminology improvement	16.7.0
	RAN#91	RP-210117			F	CR to 38.101-2: correction on UL MIMO	16.7.0
2021-03	RAN#91	RP-210117	0336		Α	CR to 38.101-2 on beam correspondence	16.7.0
2021-03	RAN#91	RP-210191		2	F	CR on FR2 inter-band DL CA CBM and IBM	16.7.0
	RAN#91	RP-210117	0345		Α	CR on FR2 intra-band UL CA	16.7.0
2021-06	RAN#92	RP-211083			Α	P_cmax fix for the CA applicability	16.8.0
	RAN#92	RP-211084			Α	Update of FR2 UL RMC tables	16.8.0
	RAN#92	RP-211104			F	Removal of CA_n260(*) notation and IE fix R16 CATF	16.8.0
2021-06	RAN#92	RP-211117		1	F	Correction of the channel raster of n259 for TS 38.101-2	16.8.0
2021-06	RAN#92	RP-211117	0383		F	CR to 38.101-2 on side conditions for beam correspondence based	16.8.0
				.		on SSB and CSI-RS for n259 (Rel-16)	45.5
2021-06	RAN#92	RP-211080		1	F	CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2	16.8.0
	RAN#92	RP-211107			F	CR to TS38.101-2: Some Corrections on for CA_n260-n261	16.8.0
2021-06	RAN#92	RP-211091		I	A	CR to 38.101-2: CABW definition addition	16.8.0
2021-06 2021-06	RAN#92	RP-211091	0407		F	CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3	16.8.0
2021-06	10,01,02			1	I	MPR	
2021-06 2021-06 2021-06		DD 044004	0040	_	۸		40.00
2021-06 2021-06 2021-06 2021-09	RAN#93	RP-211921		3	A	CR to 38.101-2 on handling of fallbacks for FR2 CA	16.9.0
2021-06 2021-06 2021-06 2021-09 2021-09	RAN#93 RAN#93	RP-211923	0422	3	F	CR to 38.101-2 on handling of fallbacks for FR2 CA Big CR for TS 38.101-2 Maintenance part1 (Rel-16)	16.9.0
2021-06 2021-06 2021-06 2021-09 2021-09 2021-12	RAN#93		0422 0435	3		CR to 38.101-2 on handling of fallbacks for FR2 CA	

2022-06	RAN#96	RP-221661	0465	F	CR for TS 38.101-2: update of simultaneous RxTx capability for band combinations	16.12.0
2022-06	RAN#96	RP-221655	0467	F	Big CR for TS 38.101-2 Maintenance (Rel-16)	16.12.0
2022-09	RAN#97	RP-222026	0495	F	Big CR for 38.101-2 maintenance (Rel-16)	16.13.0
2022-12	RAN#98-e	RP-223296	0507	F	CR R16 ModifiedMPR	16.14.0
2022-12	RAN#98-e	RP-223290	0509	A	Annex G Clarifications on diagram related to measurement point for difference of relative phase/power error for UL coherent MIMO (Rel- 16)	16.14.0
2022-12	RAN#98-e	RP-223290	0519	F	CR for Rel-16 38.101-2 to correct the side condition for SSB and CSI-RS based	16.14.0
2022-12	RAN#98-e	RP-223290	0520	F	CR for Rel-16 38.101-2 to correct the side condition for CSI-RS based	16.14.0
2022-12	RAN#98-e	RP-223296	0523	F	CR to 38.101-2 on removing ambiguity in CA MPR definition	16.14.0
2022-12	RAN#98-e	RP-223291	0527	F	Correction to DL RMC (Rel-16)	16.14.0

Document history						
V16.4.0	July 2020	Publication				
V16.5.0	November 2020	Publication				
V16.6.0	January 2021	Publication				
V16.7.0	April 2021	Publication				
V16.8.0	September 2021	Publication				
V16.9.0	October 2021	Publication				
V16.10.1	April 2022	Publication				
V16.11.0	April 2022	Publication				
V16.12.0	August 2022	Publication				
V16.13.0	October 2022	Publication				
V16.14.0	January 2023	Publication				

History